TEXAS INSTRUMENTS
MSP430F6736, MSP430F6735, MSP430F6734, MSP430F6733, MSP430F6731, MSP430F6730
MSP430F6726, MSP430F6725, MSP430F6724, MSP430F6723, MSP430F6721, MSP430F6720
ZHCS707D – DECEMBER 2011 – REVISED SEPTEMBER 2018

MSP430F673x、MSP430F672x 混合信号微控制器

1 器件概述

1.1 特性

- 低电源电压范围：
  3.6V 到低至 1.8V
- 超低功耗
  - 激活模式 (AM)：
    所有系统时钟激活
    在 8MHz、3.0V 且闪存程序执行时为 265µA/MHz（典型值）
    在 8MHz、3.0V 且 RAM 程序执行时为 140µA/MHz（典型值）
  - 待机模式 (LPM3)：
    实时时钟（采用晶振）、看门狗和电源监控器工作，完全 RAM 保持，快速唤醒：
    3.0V 时为 1.7µA，3.0V 时为 2.5µA（典型值）
  - 关闭模式 (LPM4)：
    完全 RAM 保持，电源监控器可用，快速唤醒：
    3.0V 时为 1.6µA（典型值）
  - 关断 RTC 模式 (LPM3.5)：
    关断模式，带有晶振的有源实时时钟 (RTC)：
    3.0V 时为 1.24µA（典型值）
  - 关断模式 (LPM4.5)：
    3.0V 时为 0.78µA（典型值）
- 在 3µs（典型值）内从待机模式唤醒
- 16 位精简指令集 (RISC) 架构、扩展内存、高达 25MHz 系统时钟
- 灵活的电源管理系统
  - 可设定经稳压内核电源电压的完全集成低压降稳压器 (LDO)
  - 电源电压监视、监控、和临时限电
  - 由多达 2 个辅助电源供电的系统运行
- 单一时钟系统
  - 针对频率稳定的锁相环 (FLL) 控制环路
  - 低功耗低频内部时钟源 (VLO)
  - 低频修整内部基准源 (REFO)
  - 32kHz 晶体 (XT1)
- 一个具有 3 个捕捉/比较寄存器的 16 位定时器
- 3 个 16 位定时器，每个定时器具有 2 个捕捉/比较寄存器
- 增强型通用串行通信接口
  - eUSCI_A0、eUSCI_A1 和 eUSCI_A2
    - 增强型通用异步收发器 (UART) 支持自动波特率检测
    - IrDA 编码和解码
    - 同步串行外设接口 (SPI)
  - eUSCI_B0
    - 支持多个从器件寻址的 I^2C
    - 同步串行外设接口 (SPI)
- 具有晶振偏移校准和温度补偿功能的受密码保护的 RTC
- 用于备用子系统的独立电压电源
  - 32kHz 低频振荡器 (XT1)
  - 实时时钟
  - 备用存储器（4 × 16 位）
- 三个具有差分可编程增益放大器 (PGA) 输入的 24 位 Σ-Δ 模数转换器 (ADC)
- 具有 8 路复用模式下高达 320 段对比度控制 的集成 LCD 驱动器
- 硬件乘法器支持 32 位运算
- 10位 200ksps ADC
  - 内部基准
  - 采样和保持、自动扫描特性
  - 多达 6 个外部通道和 2 个内部通道，包括温度传感器
- 3 通道内部 DMA
- 串行板上编程，无需外部编程电压
- 单相电子电表开发工具（另请参阅 工具与软件）
  - EVM430-F6736 - 用于计量的 MSP430F6736 EVM
  - 适用于 MSP430™ MCU 的电能测量设计中心
- 器件比较 汇总了可用的产品系列成员
- 采用 100 引脚和 80 引脚 LQFP 封装

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。 有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。 TI 不保证翻译的准确性和有效性。 在实际设计之前，请务必参考最新版本的英文版本。

1.2 应用

- 两线制单相计量
- 三线制单相计量
- 防篡改仪表

1.3 说明

TI MSP 系列超低功耗微控制器种类繁多，各成员器件配备不同的外设集以满足各类应用的 需求。此架构与多种低功耗模式配合使用，是延长便携式测量应用电池寿命的最优 选择。该器件 具有 一个强大的 16 位精简指令集 (RISC) 中央处理器 (CPU)，使用 16 位寄存器以及常数发生器，以便获得最高编码效率。该数控振荡器 (DCO) 可在 3µs（典型值）内从低功率模式唤醒至激活模式。

MSP430F673x 和 MSP430F672x 具有多达 3 个高性能 24 位 Σ-Δ ADC，1 个 10 位 ADC、4 个增强型通用串行通信接口（3 个 eUSCI_A 模块和 1 个 eUSCI_B 模块）、4 个 16 位计时器、1 个硬件乘法器、1 个 DMA 模块、1 个具有报警功能的 RTC 模块、1 个具有集成对比度控制功能的 LCD 驱动器以及 1 个辅助电源系统；100 引脚器件的 I/O 引脚多达 72 个，而 80 引脚器件的 I/O 引脚多达 52 个。

有关完整的模块说明，请参阅 *《MSP430F5xx 和 MSP430F6xx 系列用户指南》*

器件信息(1)

器件型号	封装	封装尺寸(2)
MSP430F6736IPZ	LQFP (100)	14mm x 14mm
MSP430F6736IPN	LQFP (80)	12mm x 12mm

(1) 要获得最新的产品、封装和订购信息，请参见*封装选项附录*（节 8），或者访问德州仪器 (TI) 网站 www.ti.com.cn。
(2) 这里显示的尺寸为近似值。要获得包含误差值的封装尺寸，请参见*机械数据*（节 8）。

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1.4 功能方框图

图 1-1 给出了所有采用 PZ 封装的器件型号的功能方框图。

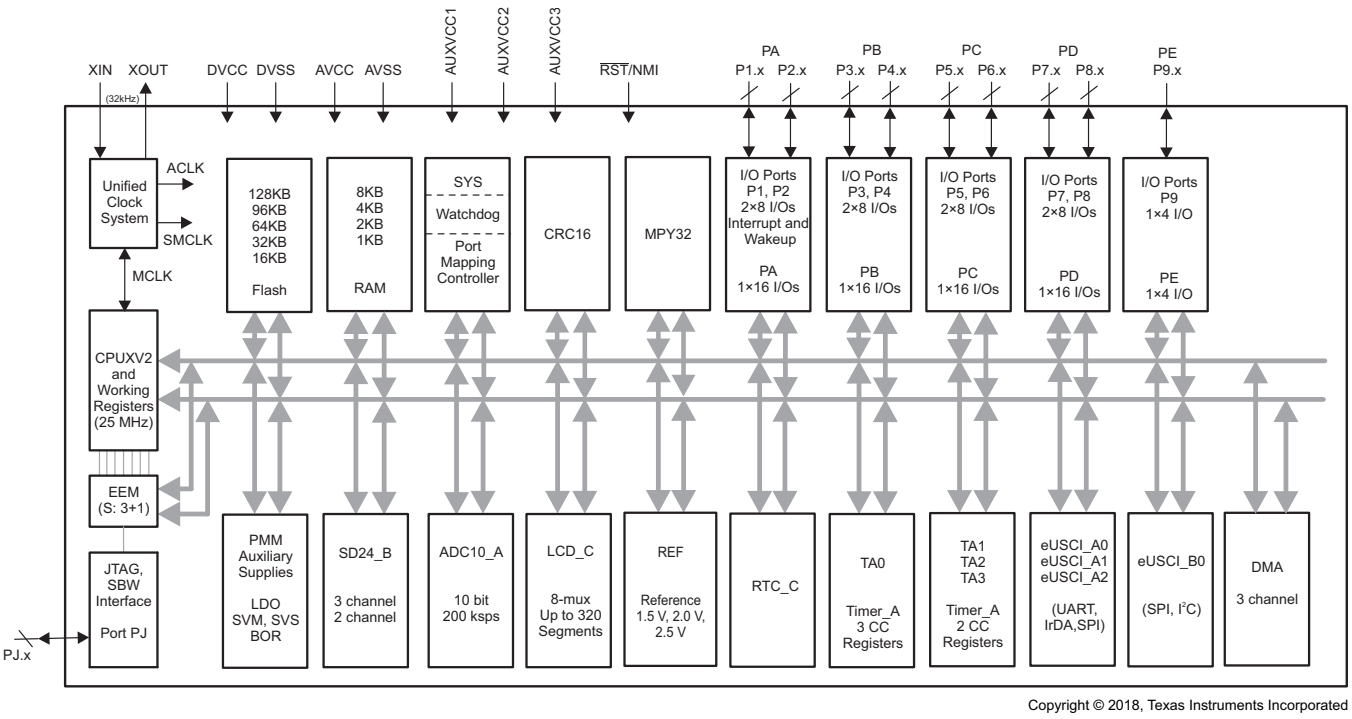


图 1-1. 功能方框图 - MSP430F673xIPZ 和 MSP430F672xIPZ

图 1-2 显示了所有采用 PN 封装的器件型号的功能方框图。

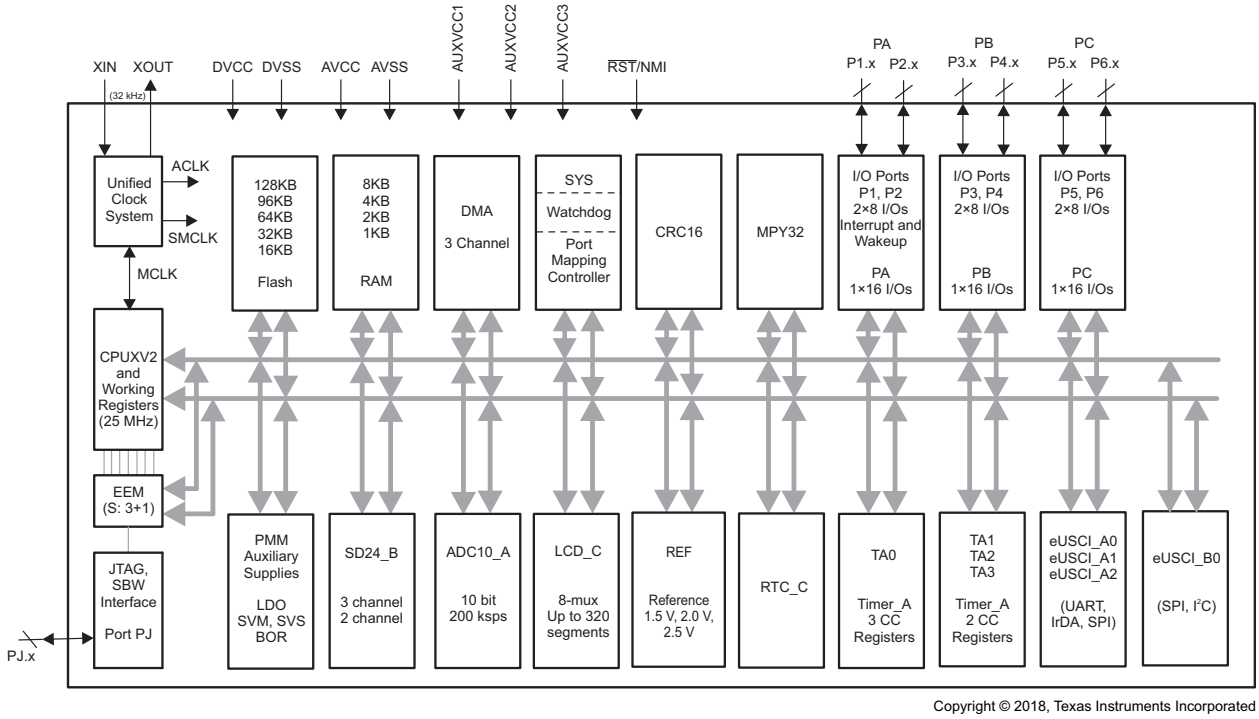


图 1-2. 功能方框图 - MSP430F673xIPN 和 MSP430F672xIPN

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2 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from February 28, 2013 to September 28, 2018 **Page**

- 通篇更改了格式和结构，其中包括添加章节编号 1
- 在 中添加了指向开发工具和设计中心的链接*特性* 1
- 添加了*器件信息* 表 2
- 更正了节 1.4*功能方框图* 中 AUXVCC1、AUXVCC2 和 AUXVCC3 引脚的名称 3
- Added Section 3 and moved Table 3-1 to it 6
- Added Section 3.1, *Related Products* 7
- Added note to $\overline{\text{RST}}$/NMI/SBWTDIO pin in Table 4-3, *Terminal Functions, PZ Package* 17
- Added note to $\overline{\text{RST}}$/NMI/SBWTDIO pin in Table 4-4, *Terminal Functions, PN Package* 22
- Added typical conditions statements at the beginning of Section 5, *Specifications* 24
- Moved all electrical specifications to Section 5, *Specifications* 24
- Added SD24_B input pins and AUXVCCx pins to exception list on "Voltage applied to pins" parameter, and added SD24_B input pin limits in "Diode current at pins" parameter in Section 5.1, *Absolute Maximum Ratings* 24
- Added Section 5.2, *ESD Ratings* 24
- Added note on C_{VCORE} in Section 5.3, *Recommended Operating Conditions* 24
- Added Section 5.7, *Thermal Resistance Characteristics* 29
- Added note to R_{Pull} in Table 5-1, *Schmitt-Trigger Inputs – General-Purpose I/O* 30
- Changed TYP value of $C_{L,eff}$ with Test Conditions of "XTS = 0, XCAPx = 0" from 2 pF to 1 pF in Table 5-7, *Crystal Oscillator, XT1, Low-Frequency Mode* 35
- Corrected the formula in note (1) [added "/ (85ºC – (–40ºC)"] in Table 5-8, *Internal Very-Low-Power Low-Frequency Oscillator (VLO)* 36
- Corrected the formula in note (1) [added "/ (85ºC – (–40ºC)"] in Table 5-9, *Internal Reference, Low-Frequency Oscillator (REFO)* 36
- Changed the MIN value of the $V_{(DVCC_BOR_hys)}$ parameter from 60 mV to 50 mV in Table 5-11, *PMM, Brownout Reset (BOR)* 38
- Updated notes (1) and (2) and added note (3) in Table 5-17, *Wake-up Times From Low-Power Modes and Reset* 40
- Corrected the names of the AUXVCC1, AUXVCC2, and AUXVCC3 pins in Auxiliary Supplies section 41
- Corrected the name of the AUXCHCx bit in the Test Conditions of Table 5-25, *Auxiliary Supplies, Charge Limiting Resistor* 43
- Replaced f_{Frame} parameter with f_{LCD}, $f_{FRAME,4mux}$, and $f_{FRAME,8mux}$ parameters in Table 5-33, *LCD_C Recommended Operating Conditions* 50
- Removed ADC10DIV from the formula for the TYP value in the second row of the $t_{CONVERT}$ parameter in Table 5-44, *10-Bit ADC, Timing Parameters*, because ADC10CLK is after division 59
- Updated Test Conditions for all parameters in Table 5-45, *10-Bit ADC, Linearity Parameters*: Changed from "C_{VREF+} = 20 pF" to "C_{VeREF+} = 20 pF"; Changed from "$(V_{eREF+} – V_{eREF–})$min ≤ $(V_{eREF+} – V_{eREF–})$" to "1.4 V ≤ $(V_{eREF+} – V_{eREF–})$"; Added "C_{VeREF+} = 20 pF" to E_I Test Conditions 60
- Added "ADC10SREFx = 11b" to Test Conditions for E_G and E_T in Table 5-45 60
- Throughout document, changed all instances of "bootstrap loader" to "bootloader" 69
- Corrected spelling of NMIIFG in 表 6-11, *System Module Interrupt Vector Registers* 75
- Removed mention of real-time clock mode (also called counter mode) in 节 6.11.21, *Real-Time Clock (RTC_C)* (feature is not supported in this device) 80
- Removed SD24BTRGCTL, SD24BTRGOSR, and SD24BTRGPRE registers (not supported) in 表 6-55, *SD24_B Registers* 93
- 添加了节 7*器件和文档支持*并将*器件和开发工具命名规则* 和*商标* 部分移到这里 129
- 将先前的*开发工具支持* 部分替换成了节 7.3*工具与软件* 131
- 添加了节 8*机械、封装和可订购信息* 136

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3 Device Comparison

Table 3-1 summarizes the available family members.

Table 3-1. Family Members(1)(2)

DEVICE	FLASH (KB)	SRAM (KB)	SD24_B CONVERTERS	ADC10_A CHANNELS	Timer_A(3)	eUSCI_A: UART, IrDA, SPI	eUSCI_B: SPI, I²C	I/Os	PACKAGE
MSP430F6736IPZ	128	8	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6735IPZ	128	4	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6734IPZ	96	4	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6733IPZ	64	4	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6731IPZ	32	2	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6730IPZ	16	1	3	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6726IPZ	128	8	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6725IPZ	128	4	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6724IPZ	96	4	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6723IPZ	64	4	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6721IPZ	32	2	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6720IPZ	16	1	2	6 ext, 2 int	3, 2, 2, 2	3	1	72	100 PZ
MSP430F6736IPN	128	8	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6735IPN	128	4	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6734IPN	96	4	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6733IPN	64	4	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6731IPN	32	2	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6730IPN	16	1	3	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6726IPN	128	8	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6725IPN	128	4	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6724IPN	96	4	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6723IPN	64	4	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6721IPN	32	2	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN
MSP430F6720IPN	16	1	2	3 ext, 2 int	3, 2, 2, 2	3	1	52	80 PN

(1) For the most current package and ordering information, see the *Package Option Addendum* in 节 8, or see the TI website at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(3) Each number in the sequence represents an instantiation of Timer_A with its associated number of capture compare registers and PWM output generators available. For example, a number sequence of 3, 5 would represent two instantiations of Timer_A, the first instantiation having 3 and the second instantiation having 5 capture compare registers and PWM output generators, respectively.

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3.1 Related Products

For information about other devices in this family of products or related products, see the following links.

Products for TI Microcontrollers TI's low-power and high-performance MCUs, with wired and wireless connectivity options, are optimized for a broad range of applications.

Products for MSP430 Ultra-Low-Power Microcontrollers One platform. One ecosystem. Endless possibilities. Enabling the connected world with innovations in ultra-low-power microcontrollers with advanced peripherals for precise sensing and measurement.

Companion Products for MSP430F6736 Review products that are frequently purchased or used with this product.

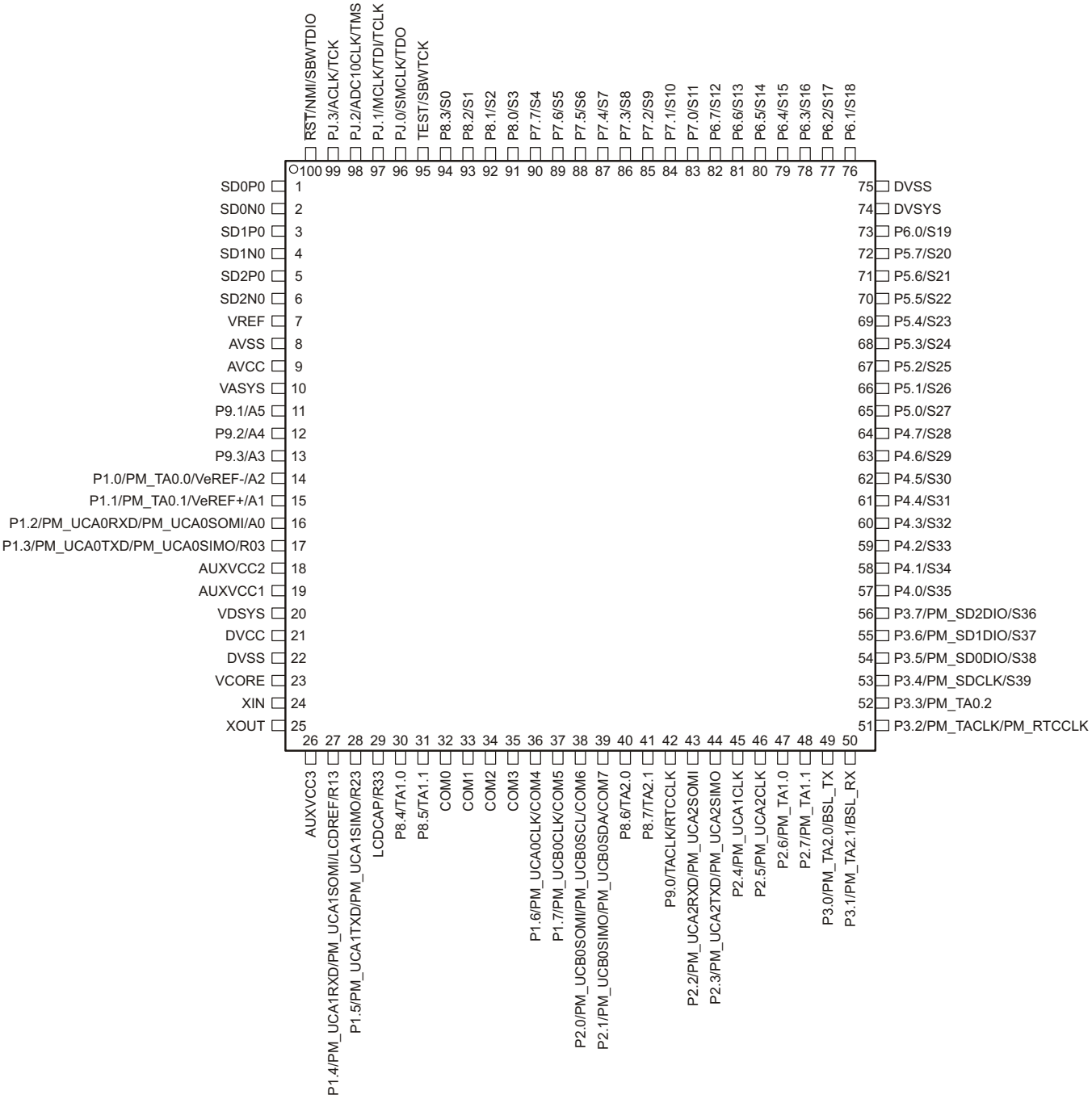
Reference Designs for MSP430F6736 The TI Designs Reference Design Library is a robust reference design library that spans analog, embedded processor, and connectivity. Created by TI experts to help you jump start your system design, all TI Designs include schematic or block diagrams, BOMs, and design files to speed your time to market. Search and download designs at ti.com/tidesigns.

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4 Terminal Configuration and Functions

4.1 Pin Diagrams

Figure 4-1 shows the pinout for the 100-pin PZ package. See Table 4-1 for differences between the MSP430F673x and MSP430F672x devices in this package.



NOTE: The secondary digital functions on Ports P1, P2, and P3 are fully mappable. This pinout shows the default mapping. See 表 6-9 for details.

NOTE: The pins VDSYS and DVSYS must be connected externally on board for proper device operation.

CAUTION: The LCDCAP/R33 pin must be connected to DVSS if not used.

Figure 4-1. 100-Pin PZ Package (Top View)

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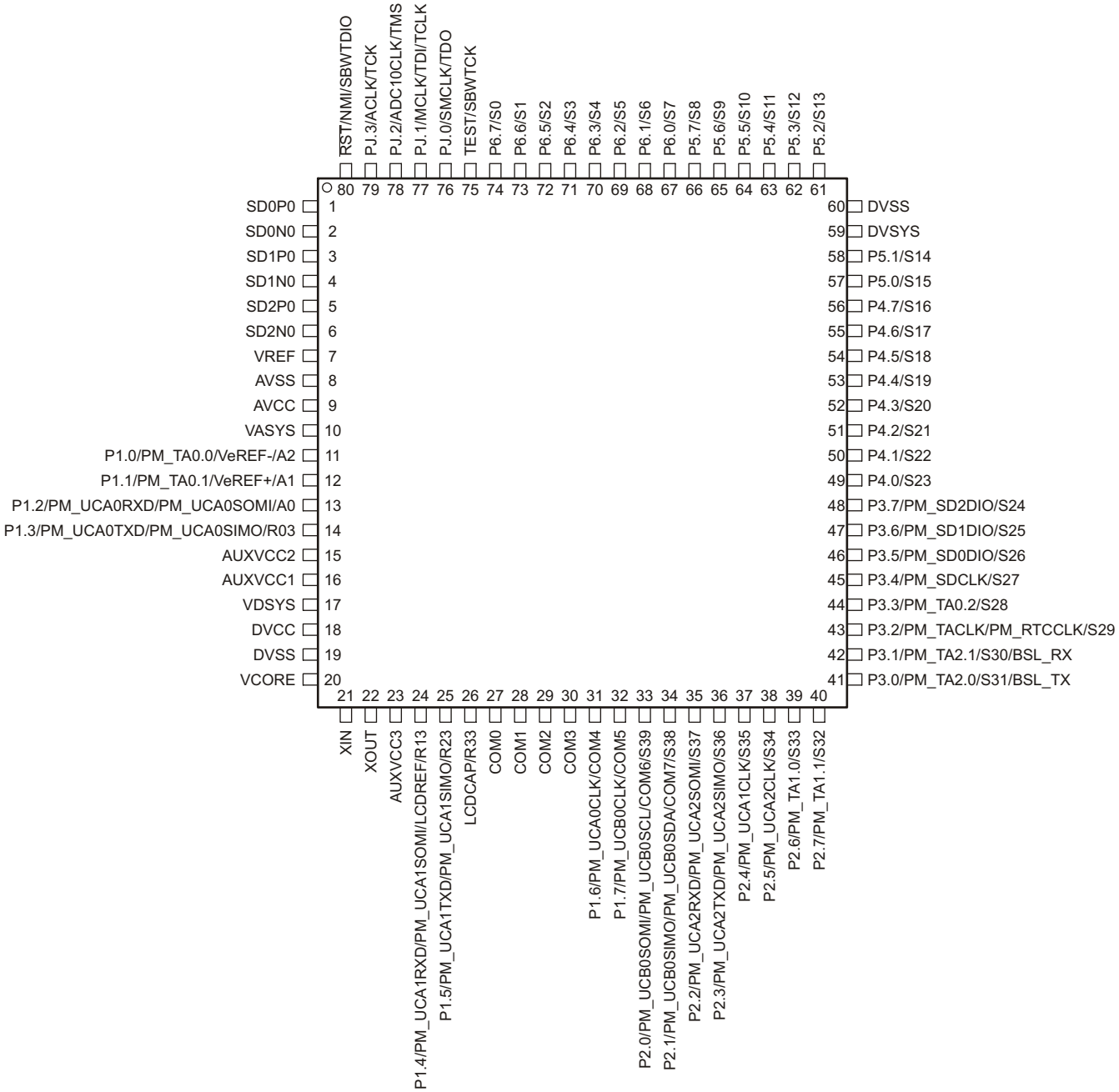
Table 4-1. Pinout Differences Between MSP430F673xIPZ and MSP430F672xIPZ(1)

PIN NUMBER	PIN NAME	
	MSP430F673xIPZ	MSP430F672xIPZ
1	SD0P0	SD0P0
2	SD0N0	SD0N0
3	SD1P0	SD1P0
4	SD1N0	SD1N0
5	*SD2P0*	*NC*
6	*SD2N0*	*NC*
7	VREF	VREF
53	P3.4/PM_SDCLK/S39	P3.4/PM_SDCLK/S39
54	P3.5/PM_SD0DIO/S38	P3.5/PM_SD0DIO/S38
55	P3.6/PM_SD1DIO/S37	P3.6/PM_SD1DIO/S37
56	P3.7/*PM_SD2DIO*/S36	P3.7/*PM_NONE*/S36

(1) Signal names that differ between devices are indicated by *italic* typeface.

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Figure 4-2 shows the pinout for the 80-pin PN package. See Table 4-2 for differences between the MSP430F673x and MSP430F672x devices in this package.



NOTE: The secondary digital functions on Ports P1, P2, and P3 are fully mappable. This pinout shows the default mapping. See 表 6-9 for details.

NOTE: The pins VDSYS and DVSYS must be connected externally on board for proper device operation.

CAUTION: The LCDCAP/R33 pin must be connected to DVSS if not used.

Figure 4-2. 80-Pin PN Package (Top View)

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Table 4-2. Pinout Differences Between MSP430F673xIPN and MSP430F672xIPN(1)

PIN NUMBER	PIN NAME	
	MSP430F673xIPN	MSP430F672xIPN
1	SD0P0	SD0P0
2	SD0N0	SD0N0
3	SD1P0	SD1P0
4	SD1N0	SD1N0
5	*SD2P0*	*NC*
6	*SD2N0*	*NC*
7	VREF	VREF
45	P3.4/PM_SDCLK/S27	P3.4/PM_SDCLK/S27
46	P3.5/PM_SD0DIO/S26	P3.5/PM_SD0DIO/S26
47	P3.6/PM_SD1DIO/S25	P3.6/PM_SD1DIO/S25
48	P3.7/*PM_SD2DIO*/S24	P3.7/*PM_NONE*/S24

(1) Signal names that differ between devices are indicated by *italic* typeface.

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4.2 Signal Descriptions

Table 4-3 describes the signals for all device variants in the PZ package. See Table 4-4 for signal descriptions in the PN package.

Table 4-3. Terminal Functions, PZ Package

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO.		
	PZ		
SD0P0	1	I	SD24_B positive analog input for converter 0(2)
SD0N0	2	I	SD24_B negative analog input for converter 0(2)
SD1P0	3	I	SD24_B positive analog input for converter 1(2)
SD1N0	4	I	SD24_B negative analog input for converter 1(2)
SD2P0	5	I	SD24_B positive analog input for converter 2(2) (not available on F672x devices)
SD2N0	6	I	SD24_B negative analog input for converter 2(2) (not available on F672x devices)
VREF	7	I	SD24_B external reference voltage
AVSS	8		Analog ground supply
AVCC	9		Analog power supply
VASYS	10		Analog power supply selected between AVCC, AUXVCC1, AUXVCC2. Connect recommended capacitor value of C_{VSYS} (see Table 5-18).
P9.1/A5	11	I/O	General-purpose digital I/O Analog input A5 for 10-bit ADC
P9.2/A4	12	I/O	General-purpose digital I/O Analog input A4 for 10-bit ADC
P9.3/A3	13	I/O	General-purpose digital I/O Analog input A3 for 10-bit ADC
P1.0/PM_TA0.0/VeREF-/A2	14	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA0 CCR0 capture: CCI0A input, compare: Out0 output Negative terminal for the ADC reference voltage for an external applied reference voltage Analog input A2 for 10-bit ADC
P1.1/PM_TA0.1/VeREF+/A1	15	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA0 CCR1 capture: CCI1A input, compare: Out1 output Positive terminal for the ADC reference voltage for an external applied reference voltage Analog input A1 for 10-bit ADC
P1.2/PM_UCA0RXD/ PM_UCA0SOMI/A0	16	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 UART receive data; eUSCI_A0 SPI slave out/master in Analog input A0 for 10-bit ADC
P1.3/PM_UCA0TXD/ PM_UCA0SIMO/R03	17	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 UART transmit data; eUSCI_A0 SPI slave in/master out Input/output port of lowest analog LCD voltage (V5)
AUXVCC2	18		Auxiliary power supply AUXVCC2
AUXVCC1	19		Auxiliary power supply AUXVCC1

(1) I = input, O = output
(2) Short unused analog input pairs and connect them to analog ground.

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Table 4-3. Terminal Functions, PZ Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO.		
	PZ		
VDSYS(3)	20		Digital power supply selected between DVCC, AUXVCC1, AUXVCC2. Connect recommended capacitor value of C_{VSYS} (see Table 5-18).
DVCC	21		Digital power supply
DVSS	22		Digital ground supply
VCORE(4)	23		Regulated core power supply (internal use only, no external current loading)
XIN	24	I	Input terminal for crystal oscillator
XOUT	25	O	Output terminal for crystal oscillator
AUXVCC3	26		Auxiliary power supply AUXVCC3 for back up subsystem
P1.4/PM_UCA1RXD/ PM_UCA1SOMI/LCDREF/R13	27	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 UART receive data; eUSCI_A1 SPI slave out/master in External reference voltage input for regulated LCD voltage Input/output port of third most positive analog LCD voltage (V3 or V4)
P1.5/PM_UCA1TXD/ PM_UCA1SIMO/R23	28	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 UART transmit data; eUSCI_A1 SPI slave in/master out Input/output port of second most positive analog LCD voltage (V2)
LCDCAP/R33	29	I/O	LCD capacitor connection Input/output port of most positive analog LCD voltage (V1) **CAUTION**: This pin must be connected to DVSS if not used.
P8.4/TA1.0	30	I/O	General-purpose digital I/O Timer TA1 CCR0 capture: CCI0A input, compare: Out0 output
P8.5/TA1.1	31	I/O	General-purpose digital I/O Timer TA1 CCR1 capture: CCI1A input, compare: Out1 output
COM0	32	O	LCD common output COM0 for LCD backplane
COM1	33	O	LCD common output COM1 for LCD backplane
COM2	34	O	LCD common output COM2 for LCD backplane
COM3	35	O	LCD common output COM3 for LCD backplane
P1.6/PM_UCA0CLK/COM4	36	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 clock input/output LCD common output COM4 for LCD backplane
P1.7/PM_UCB0CLK/COM5	37	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 clock input/output LCD common output COM5 for LCD backplane
P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6	38	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 SPI slave out/master in; eUSCI_B0 I^2C clock LCD common output COM6 for LCD backplane

(3) The pins VDSYS and DVSYS must be connected externally on the board for proper device operation.
(4) VCORE is for internal use only. No external current loading is possible. VCORE should only be connected to the recommended capacitor value, C_{VCORE}.

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Table 4-3. Terminal Functions, PZ Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO.		
	PZ		
P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7	39	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 SPI slave in/master out; eUSCI_B0 I^2C data LCD common output COM7 for LCD backplane
P8.6/TA2.0	40	I/O	General-purpose digital I/O Timer TA2 CCR0 capture: CCI0A input, compare: Out0 output
P8.7/TA2.1	41	I/O	General-purpose digital I/O Timer TA2 CCR1 capture: CCI1A input, compare: Out1 output
P9.0/TACLK/RTCCLK	42	I/O	General-purpose digital I/O Timer clock input TACLK for TA0, TA1, TA2, TA3 RTCCLK clock output
P2.2/PM_UCA2RXD/ PM_UCA2SOMI	43	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 UART receive data; eUSCI_A2 SPI slave out/master in
P2.3/PM_UCA2TXD/ PM_UCA2SIMO	44	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 UART transmit data; eUSCI_A2 SPI slave in/master out
P2.4/PM_UCA1CLK	45	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 clock input/output
P2.5/PM_UCA2CLK	46	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 clock input/output
P2.6/PM_TA1.0	47	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA1 capture CCR0: CCI0A input, compare: Out0 output
P2.7/PM_TA1.1	48	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA1 capture CCR1: CCI1A input, compare: Out1 output
P3.0/PM_TA2.0/BSL_TX	49	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA2 capture CCR0: CCI0A input, compare: Out0 output Bootloader: Data transmit
P3.1/PM_TA2.1/BSL_RX	50	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA2 capture CCR1: CCI1A input, compare: Out1 output Bootloader: Data receive
P3.2/PM_TACLK/PM_RTCCLK	51	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer clock input TACLK for TA0, TA1, TA2, TA3; RTCCLK clock output
P3.3/PM_TA0.2	52	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA0 capture CCR2: CCI2A input, compare: Out2 output
P3.4/PM_SDCLK/S39	53	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B bitstream clock input/output LCD segment output S39

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Table 4-3. Terminal Functions, PZ Package (continued)

TERMINAL		I/O[1]	DESCRIPTION
NAME	NO. PZ		
P3.5/PM_SD0DIO/S38	54	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-0 bitstream data input/output LCD segment output S38
P3.6/PM_SD1DIO/S37	55	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-1 bitstream data input/output LCD segment output S37
P3.7/PM_SD2DIO/S36	56	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-2 bitstream data input/output (not available on F672x devices) LCD segment output S36
P4.0/S35	57	I/O	General-purpose digital I/O LCD segment output S35
P4.1/S34	58	I/O	General-purpose digital I/O LCD segment output S34
P4.2/S33	59	I/O	General-purpose digital I/O LCD segment output S33
P4.3/S32	60	I/O	General-purpose digital I/O LCD segment output S32
P4.4/S31	61	I/O	General-purpose digital I/O LCD segment output S31
P4.5/S30	62	I/O	General-purpose digital I/O LCD segment output S30
P4.6/S29	63	I/O	General-purpose digital I/O LCD segment output S29
P4.7/S28	64	I/O	General-purpose digital I/O LCD segment output S28
P5.0/S27	65	I/O	General-purpose digital I/O LCD segment output S27
P5.1/S26	66	I/O	General-purpose digital I/O LCD segment output S26
P5.2/S25	67	I/O	General-purpose digital I/O LCD segment output S25
P5.3/S24	68	I/O	General-purpose digital I/O LCD segment output S24
P5.4/S23	69	I/O	General-purpose digital I/O LCD segment output S23

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Table 4-3. Terminal Functions, PZ Package (continued)

TERMINAL		I/O[1]	DESCRIPTION
NAME	NO. PZ		
P5.5/S22	70	I/O	General-purpose digital I/O LCD segment output S22
P5.6/S21	71	I/O	General-purpose digital I/O LCD segment output S21
P5.7/S20	72	I/O	General-purpose digital I/O LCD segment output S20
P6.0/S19	73	I/O	General-purpose digital I/O LCD segment output S19
DVSYS[3]	74		Digital power supply for I/Os
DVSS	75		Digital ground supply
P6.1/S18	76	I/O	General-purpose digital I/O LCD segment output S18
P6.2/S17	77	I/O	General-purpose digital I/O LCD segment output S17
P6.3/S16	78	I/O	General-purpose digital I/O LCD segment output S16
P6.4/S15	79	I/O	General-purpose digital I/O LCD segment output S15
P6.5/S14	80	I/O	General-purpose digital I/O LCD segment output S14
P6.6/S13	81	I/O	General-purpose digital I/O LCD segment output S13
P6.7/S12	82	I/O	General-purpose digital I/O LCD segment output S12
P7.0/S11	83	I/O	General-purpose digital I/O LCD segment output S11
P7.1/S10	84	I/O	General-purpose digital I/O LCD segment output S10
P7.2/S9	85	I/O	General-purpose digital I/O LCD segment output S9
P7.3/S8	86	I/O	General-purpose digital I/O LCD segment output S8
P7.4/S7	87	I/O	General-purpose digital I/O LCD segment output S7

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Table 4-3. Terminal Functions, PZ Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO. PZ		
P7.5/S6	88	I/O	General-purpose digital I/O LCD segment output S6
P7.6/S5	89	I/O	General-purpose digital I/O LCD segment output S5
P7.7/S4	90	I/O	General-purpose digital I/O LCD segment output S4
P8.0/S3	91	I/O	General-purpose digital I/O LCD segment output S3
P8.1/S2	92	I/O	General-purpose digital I/O LCD segment output S2
P8.2/S1	93	I/O	General-purpose digital I/O LCD segment output S1
P8.3/S0	94	I/O	General-purpose digital I/O LCD segment output S0
TEST/SBWTCK	95	I	Test mode pin – select digital I/O on JTAG pins Spy-Bi-Wire input clock
PJ.0/SMCLK/TDO	96	I/O	General-purpose digital I/O SMCLK clock output Test data output
PJ.1/MCLK/TDI/TCLK	97	I/O	General-purpose digital I/O MCLK clock output Test data input or Test clock input
PJ.2/ADC10CLK/TMS	98	I/O	General-purpose digital I/O ADC10_A clock output Test mode select
PJ.3/ACLK/TCK	99	I/O	General-purpose digital I/O ACLK clock output Test clock
$\overline{\text{RST}}$/NMI/SBWTDIO	100	I/O	Reset input active low(5) Nonmaskable interrupt input Spy-Bi-Wire data input/output

(5) When this pin is configured as reset, the internal pullup resistor is enabled by default.

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Table 4-4 describes the signals for all device variants in the PN package. See Table 4-3 for signal descriptions in the PZ package.

Table 4-4. Terminal Functions, PN Package

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO.		
	PN		
SD0P0	1	I	SD24_B positive analog input for converter 0(2)
SD0N0	2	I	SD24_B negative analog input for converter 0(2)
SD1P0	3	I	SD24_B positive analog input for converter 1(2)
SD1N0	4	I	SD24_B negative analog input for converter 1(2)
SD2P0	5	I	SD24_B positive analog input for converter 2(2) (not available on F672x devices)
SD2N0	6	I	SD24_B negative analog input for converter 2(2) (not available on F672x devices)
VREF	7	I	SD24_B external reference voltage
AVSS	8		Analog ground supply
AVCC	9		Analog power supply
VASYS	10		Analog power supply selected between AVCC, AUXVCC1, AUXVCC2. Connect recommended capacitor value of C_{VSYS} (see Table 5-18).
P1.0/PM_TA0.0/VeREF-/A2	11	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA0 CCR0 capture: CCI0A input, compare: Out0 output Negative terminal for the ADC reference voltage for an external applied reference voltage Analog input A2 for 10-bit ADC
P1.1/PM_TA0.1/VeREF+/A1	12	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA0 CCR1 capture: CCI1A input, compare: Out1 output Positive terminal for the ADC reference voltage for an external applied reference voltage Analog input A1 for 10-bit ADC
P1.2/PM_UCA0RXD/ PM_UCA0SOMI/A0	13	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 UART receive data; eUSCI_A0 SPI slave out/master in Analog input A0 for 10-bit ADC
P1.3/PM_UCA0TXD/ PM_UCA0SIMO/R03	14	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 UART transmit data; eUSCI_A0 SPI slave in/master out Input/output port of lowest analog LCD voltage (V5)
AUXVCC2	15		Auxiliary power supply AUXVCC2
AUXVCC1	16		Auxiliary power supply AUXVCC1
VDSYS(3)	17		Digital power supply selected between DVCC, AUXVCC1, AUXVCC2. Connect recommended capacitor value of C_{VSYS} (see Table 5-18).
DVCC	18		Digital power supply
DVSS	19		Digital ground supply
VCORE(4)	20		Regulated core power supply (internal use only, no external current loading)
XIN	21	I	Input terminal for crystal oscillator
XOUT	22	O	Output terminal for crystal oscillator
AUXVCC3	23		Auxiliary power supply AUXVCC3 for back up subsystem

(1) I = input, O = output
(2) Short unused analog input pairs and connect them to analog ground.
(3) The pins VDSYS and DVSYS must be connected externally on the board for proper device operation.
(4) VCORE is for internal use only. No external current loading is possible. VCORE should only be connected to the recommended capacitor value, C_{VCORE}.

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Table 4-4. Terminal Functions, PN Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO. PN		
P1.4/PM_UCA1RXD/ PM_UCA1SOMI/LCDREF/R13	24	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 UART receive data; eUSCI_A1 SPI slave out/master in External reference voltage input for regulated LCD voltage Input/output port of third most positive analog LCD voltage (V3 or V4)
P1.5/PM_UCA1TXD/ PM_UCA1SIMO/R23	25	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 UART transmit data; eUSCI_A1 SPI slave in/master out Input/output port of second most positive analog LCD voltage (V2)
LCDCAP/R33	26	I/O	LCD capacitor connection Input/output port of most positive analog LCD voltage (V1) **CAUTION**: This pin must be connected to DVSS if not used.
COM0	27	O	LCD common output COM0 for LCD backplane
COM1	28	O	LCD common output COM1 for LCD backplane
COM2	29	O	LCD common output COM2 for LCD backplane
COM3	30	O	LCD common output COM3 for LCD backplane
P1.6/PM_UCA0CLK/COM4	31	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A0 clock input/output LCD common output COM4 for LCD backplane
P1.7/PM_UCB0CLK/COM5	32	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 clock input/output LCD common output COM5 for LCD backplane
P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6/S39	33	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 SPI slave out/master in; eUSCI_B0 I^2C clock LCD common output COM6 for LCD backplane LCD segment output S39
P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7/S38	34	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_B0 SPI slave in/master out; eUSCI_B0 I^2C data LCD common output COM7 for LCD backplane LCD segment output S38
P2.2/PM_UCA2RXD/ PM_UCA2SOMI/S37	35	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 UART receive data; eUSCI_A2 SPI slave out/master in LCD segment output S37
P2.3/PM_UCA2TXD/ PM_UCA2SIMO/S36	36	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 UART transmit data; eUSCI_A2 SPI slave in/master out LCD segment output S36
P2.4/PM_UCA1CLK/S35	37	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A1 clock input/output LCD segment output S35

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Table 4-4. Terminal Functions, PN Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO. PN		
P2.5/PM_UCA2CLK/S34	38	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: eUSCI_A2 clock input/output LCD segment output S34
P2.6/PM_TA1.0/S33	39	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA1 capture CCR0: CCI0A input, compare: Out0 output LCD segment output S33
P2.7/PM_TA1.1/S32	40	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Timer TA1 capture CCR1: CCI1A input, compare: Out1 output LCD segment output S32
P3.0/PM_TA2.0/S31/BSL_TX	41	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA2 capture CCR0: CCI0A input, compare: Out0 output LCD segment output S31 Bootloader: Data transmit
P3.1/PM_TA2.1/S30/BSL_RX	42	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA2 capture CCR1: CCI1A input, compare: Out1 output LCD segment output S30 Bootloader: Data receive
P3.2/PM_TACLK/PM_RTCCLK/ S29	43	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer clock input TACLK for TA0, TA1, TA2, TA3; RTCCLK clock output LCD segment output S29
P3.3/PM_TA0.2/S28	44	I/O	General-purpose digital I/O with mappable secondary function Default mapping: Timer TA0 capture CCR2: CCI2A input, compare: Out2 output LCD segment output S28
P3.4/PM_SDCLK/S27	45	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B bitstream clock input/output LCD segment output S27
P3.5/PM_SD0DIO/S26	46	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-0 bitstream data input/output LCD segment output S26
P3.6/PM_SD1DIO/S25	47	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-1 bitstream data input/output LCD segment output S25
P3.7/PM_SD2DIO/S24	48	I/O	General-purpose digital I/O with mappable secondary function Default mapping: SD24_B converter-2 bitstream data input/output (not available on F672x devices) LCD segment output S24

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Table 4-4. Terminal Functions, PN Package (continued)

TERMINAL		I/O[1]	DESCRIPTION
NAME	NO. PN		
P4.0/S23	49	I/O	General-purpose digital I/O LCD segment output S23
P4.1/S22	50	I/O	General-purpose digital I/O LCD segment output S22
P4.2/S21	51	I/O	General-purpose digital I/O LCD segment output S21
P4.3/S20	52	I/O	General-purpose digital I/O LCD segment output S20
P4.4/S19	53	I/O	General-purpose digital I/O LCD segment output S19
P4.5/S18	54	I/O	General-purpose digital I/O LCD segment output S18
P4.6/S17	55	I/O	General-purpose digital I/O LCD segment output S17
P4.7/S16	56	I/O	General-purpose digital I/O LCD segment output S16
P5.0/S15	57	I/O	General-purpose digital I/O LCD segment output S15
P5.1/S14	58	I/O	General-purpose digital I/O LCD segment output S14
DVSYS[3]	59		Digital power supply for I/Os
DVSS	60		Digital ground supply
P5.2/S13	61	I/O	General-purpose digital I/O LCD segment output S13
P5.3/S12	62	I/O	General-purpose digital I/O LCD segment output S12
P5.4/S11	63	I/O	General-purpose digital I/O LCD segment output S11
P5.5/S10	64	I/O	General-purpose digital I/O LCD segment output S10
P5.6/S9	65	I/O	General-purpose digital I/O LCD segment output S9
P5.7/S8	66	I/O	General-purpose digital I/O LCD segment output S8

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Table 4-4. Terminal Functions, PN Package (continued)

TERMINAL		I/O(1)	DESCRIPTION
NAME	NO. PN		
P6.0/S7	67	I/O	General-purpose digital I/O LCD segment output S7
P6.1/S6	68	I/O	General-purpose digital I/O LCD segment output S6
P6.2/S5	69	I/O	General-purpose digital I/O LCD segment output S5
P6.3/S4	70	I/O	General-purpose digital I/O LCD segment output S4
P6.4/S3	71	I/O	General-purpose digital I/O LCD segment output S3
P6.5/S2	72	I/O	General-purpose digital I/O LCD segment output S2
P6.6/S1	73	I/O	General-purpose digital I/O LCD segment output S1
P6.7/S0	74	I/O	General-purpose digital I/O LCD segment output S0
TEST/SBWTCK	75	I	Test mode pin – select digital I/O on JTAG pins Spy-Bi-Wire input clock
PJ.0/SMCLK/TDO	76	I/O	General-purpose digital I/O SMCLK clock output Test data output
PJ.1/MCLK/TDI/TCLK	77	I/O	General-purpose digital I/O MCLK clock output Test data input or Test clock input
PJ.2/ADC10CLK/TMS	78	I/O	General-purpose digital I/O ADC10_A clock output Test mode select
PJ.3/ACLK/TCK	79	I/O	General-purpose digital I/O ACLK clock output Test clock
$\overline{\text{RST}}$/NMI/SBWTDIO	80	I/O	Reset input active low(5) Nonmaskable interrupt input Spy-Bi-Wire data input/output

(5) When this pin is configured as reset, the internal pullup resistor is enabled by default.

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5 Specifications

All graphs in this section are for typical conditions, unless otherwise noted.

Typical (TYP) values are specified at V_{CC} = 3.3 V and T_A = 25°C, unless otherwise noted.

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage applied at DVCC to DVSS		–0.3	4.1	V
Voltage applied to pins(2)	All pins except VCORE(3), SD24_B input pins (SD0N0, SD0P0, SD1N0, SD1P0, SD2N0, SD2P0)(4), AUXVCC1, AUXVCC2, and AUXVCC3(5)	–0.3	V_{CC} + 0.3	V
Diode current at pins	All pins except SD24_B input pins (SD0N0, SD0P0, SD1N0, SD1P0, SD2N0, SD2P0)		±2	mA
	SD0N0, SD0P0, SD1N0, SD1P0, SD2N0, SD2P0(6)		2	
Maximum junction temperature, T_J			95	°C
Storage temperature, T_{stg}(7)		–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages referenced to V_{SS} = $V_{(DVSS)}$ = $V_{(AVSS)}$.
(3) VCORE is for internal device use only. Do not apply external DC loading or voltage.
(4) See Table 5-35 for SD24_B specifications.
(5) See Table 5-18 for AUX specifications.
(6) A protection diode is connected to V_{CC} for the SD24_B input pins. No protection diode is connected to V_{SS}.
(7) Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±250	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±1000 V may actually have higher performance.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±250 V may actually have higher performance.

5.3 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage during program execution and flash programming, $V_{(AVCC)}$ = $V_{(DVCC)}$ = V_{CC} (1)(2)	PMMCOREVx = 0	1.8		3.6	V
		PMMCOREVx = 0, 1	2.0		3.6	
		PMMCOREVx = 0, 1, 2	2.2		3.6	
		PMMCOREVx = 0, 1, 2, 3	2.4		3.6	
V_{SS}	Supply voltage $V_{(AVSS)}$ = $V_{(DVSS)}$ = V_{SS}			0		V
T_A	Operating free-air temperature		–40		85	°C
T_J	Operating junction temperature		–40		85	°C
C_{VCORE}	Recommended capacitor at VCORE(3)			470		nF
C_{DVCC}/C_{VCORE}	Capacitor ratio of DVCC to VCORE		10			

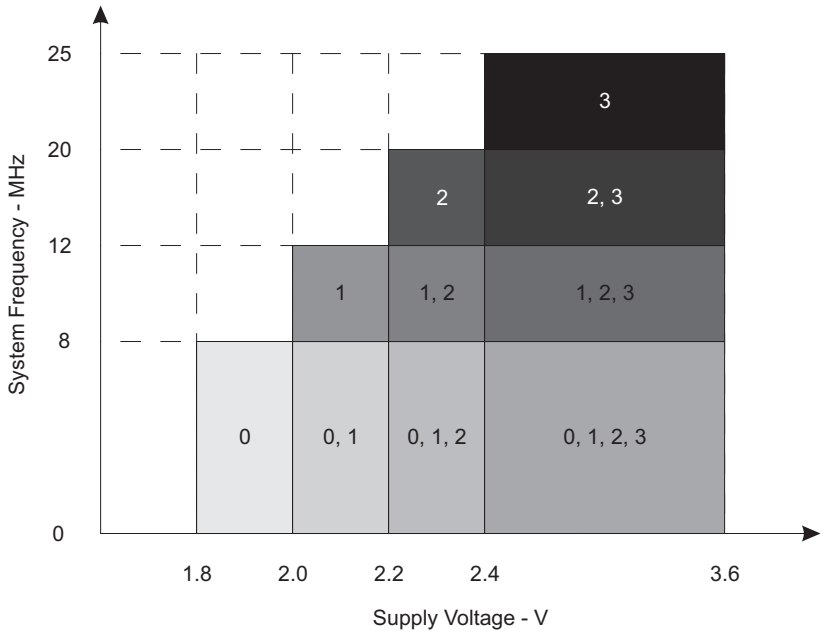
(1) TI recommends powering AVCC and DVCC from the same source. A maximum difference of 0.3 V between $V_{(AVCC)}$ and $V_{(DVCC)}$ can be tolerated during power up and operation.
(2) The minimum supply voltage is defined by the supervisor SVS levels when it is enabled. See the Table 5-13 threshold parameters for the exact values and further details.
(3) A capacitor tolerance of ±20% or better is required.

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Recommended Operating Conditions *(continued)*

			MIN	NOM	MAX	UNIT
f_{SYSTEM}	Processor frequency (maximum MCLK frequency)(4)(5) (see Figure 5-1)	PMMCOREVx = 0, 1.8 V ≤ V_{CC} ≤ 3.6 V (default condition)	0		8.0	MHz
		PMMCOREVx = 1, 2.0 V ≤ V_{CC} ≤ 3.6 V	0		12.0	
		PMMCOREVx = 2, 2.2 V ≤ V_{CC} ≤ 3.6 V	0		20.0	
		PMMCOREVx = 3, 2.4 V ≤ V_{CC} ≤ 3.6 V	0		25.0	
$I_{LOAD, DVCCD}$	Maximum load current that can be drawn from DVCC for core and IO ($I_{LOAD} = I_{CORE} + I_{IO}$)				20	mA
$I_{LOAD, AUX1D}$	Maximum load current that can be drawn from AUXVCC1 for core and IO ($I_{LOAD} = I_{CORE} + I_{IO}$)				20	mA
$I_{LOAD, AUX2D}$	Maximum load current that can be drawn from AUXVCC2 for core and IO ($I_{LOAD} = I_{CORE} + I_{IO}$)				20	mA
$I_{LOAD, AVCCA}$	Maximum load current that can be drawn from AVCC for analog modules ($I_{LOAD} = I_{Modules}$)				10	mA
$I_{LOAD, AUX1A}$	Maximum load current that can be drawn from AUXVCC1 for analog modules ($I_{LOAD} = I_{Modules}$)				5	mA
$I_{LOAD, AUX2A}$	Maximum load current that can be drawn from AUXVCC2 for analog modules ($I_{LOAD} = I_{Modules}$)				5	mA

(4) The MSP430 CPU is clocked directly with MCLK. Both the high and low phases of MCLK must not exceed the pulse duration of the specified maximum frequency.
(5) Modules may have a different maximum input clock specification. See the specification of the respective module in this data sheet.



The numbers within the fields denote the supported PMMCOREVx settings.

Figure 5-1. Maximum System Frequency

5.4 Active Mode Supply Current Into V_{CC} Excluding External Current

over recommended operating free-air temperature (unless otherwise noted)(1) (2) (3)

PARAMETER	EXECUTION MEMORY	V_{CC}	PMMCOREVx	FREQUENCY ($f_{DCO} = f_{MCLK} = f_{SMCLK}$)										UNIT
				1 MHz		8 MHz		12 MHz		20 MHz		25 MHz		
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
$I_{AM, Flash}$ (4)	Flash	3.0 V	0	0.32	0.36	2.10	2.30							mA
			1	0.36		2.39		3.54	3.90					
			2	0.39		2.65		3.94		6.54	7.23			
			3	0.42		2.82		4.20		6.96		8.65	9.54	
$I_{AM, RAM}$ (5)	RAM	3.0 V	0	0.20	0.22	1.10	1.22							mA
			1	0.22		1.30		1.90	2.10					
			2	0.24		1.45		2.15		3.55	4.0			
			3	0.26		1.55		2.30		3.80		4.70	5.30	

(1) All inputs are tied to 0 or to V_{CC}. Outputs do not source or sink any current.
(2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.
(3) Characterized with program executing typical data processing.
f_{ACLK} = 32786 Hz, $f_{DCO} = f_{MCLK} = f_{SMCLK}$ at specified frequency.
XTS = CPUOFF = SCG0 = SCG1 = OSCOFF = SMCLKOFF = 0.
(4) Active mode supply current when program executes in flash at a nominal supply voltage of 3 V.
(5) Active mode supply current when program executes in RAM at a nominal supply voltage of 3 V.

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5.5 Low-Power Mode Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)(2)

PARAMETER		V_{CC}	PMMCOREVx	TEMPERATURE (T_A)								UNIT
				–40°C		25°C		60°C		85°C		
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
$I_{LPM0,1MHz}$	Low-power mode 0(3)(4)	2.2 V	0	75		78	87	81		84	96	µA
		3.0 V	3	85		89	99	93		98	110	
I_{LPM2}	Low-power mode 2(5)(4)	2.2 V	0	5.9		6.2	9	6.9		9.4	17	µA
		3.0 V	3	6.9		7.4	10	8.4		11	19	
$I_{LPM3,XT1LF}$	Low-power mode 3, crystal mode(6)(4)	2.2 V	0	1.4		1.7		2.5		4.9		µA
			1	1.5		1.9		2.7		5.2		
			2	1.7		2.0		2.9		5.5		
$I_{LPM3,XT1LF}$	Low-power mode 3, crystal mode(6)(4)	3.0 V	0	2.2		2.5	3.1	3.3		5.5	12.7	µA
			1	2.3		2.7		3.5		5.8		
			2	2.5		2.9		3.7		6.1		
			3	2.5		2.9	3.5	3.7		6.1	14.0	
$I_{LPM3,VLO}$	Low-power mode 3, VLO mode(7)(4)	3.0 V	0	1.4		1.7	2.2	2.4		4.5	11.5	µA
			1	1.5		1.8		2.5		4.7		
			2	1.6		1.9		2.7		4.9		
			3	1.6		1.9	2.4	2.7		5.0	12.7	
I_{LPM4}	Low-power mode 4(8)(4)	3.0 V	0	1.3		1.6	2.0	2.3		4.4	11.1	µA
			1	1.4		1.6		2.4		4.5		
			2	1.4		1.7		2.5		4.8		
			3	1.4		1.7	2.2	2.5		4.8	12.2	
$I_{LPM3.5}$	Low-power mode 3.5, RTC active on AUXVCC3(9)	2.2 V		0.65		0.80		0.90		1.30		µA
		3.0 V		1.16		1.24	2.05	1.43		1.87	2.71	
$I_{LPM4.5}$	Low-power mode 4.5(10)	3.0 V		0.70		0.78	1.05	0.90		1.20	1.85	µA

(1) All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.
(2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.
(3) Current for watchdog timer clocked by SMCLK included. ACLK = low-frequency crystal operation (XTS = 0, XT1DRIVEx = 0).
CPUOFF = 1, SCG0 = 0, SCG1 = 0, OSCOFF = 0 (LPM0), f_{ACLK} = 32768 Hz, f_{MCLK} = 0 MHz, f_{SMCLK} = f_{DCO} = 1 MHz
(4) Current for brownout, high-side supervisor (SVS_H) normal mode included. Low-side supervisor (SVS_L) and low-side monitor (SVM_L) disabled. High-side monitor (SVM_H) disabled. RAM retention enabled.
(5) Current for watchdog timer clocked by ACLK and RTC clocked by XT1 included. ACLK = low-frequency crystal operation (XTS = 0, XT1DRIVEx = 0).
CPUOFF = 1, SCG0 = 0, SCG1 = 1, OSCOFF = 0 (LPM2), f_{ACLK} = 32768 Hz, f_{MCLK} = 0 MHz, f_{SMCLK} = f_{DCO} = 0 MHz, DCO setting = 1-MHz operation, DCO bias generator enabled.
(6) Current for watchdog timer clocked by ACLK and RTC clocked by XT1 included. ACLK = low-frequency crystal operation (XTS = 0, XT1DRIVEx = 0).
CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 0 (LPM3), f_{ACLK} = 32768 Hz, f_{MCLK} = f_{SMCLK} = f_{DCO} = 0 MHz
(7) Current for watchdog timer clocked by ACLK included. RTC is disabled (RTCHOLD = 1). ACLK = VLO.
CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 0 (LPM3), f_{ACLK} = f_{VLO}, f_{MCLK} = f_{SMCLK} = f_{DCO} = 0 MHz
(8) CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 1 (LPM4), f_{DCO} = f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz
(9) f_{DCO} = f_{MCLK} = f_{SMCLK} = 0 MHz, f_{ACLK} = 32768 Hz, PMMREGOFF = 1, RTC active on AUXVCC3 supply
(10) f_{DCO} = f_{MCLK} = f_{SMCLK} = 0 MHz, f_{ACLK} = 0 Hz, PMMREGOFF = 1

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5.6 Low-Power Mode With LCD Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)(2)

PARAMETER		V_{CC}	PMMCOREVx	TEMPERATURE (T_A)								UNIT
				–40°C		25°C		60°C		85°C		
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
I_{LPM3} LCD, int. bias	Low-power mode 3 (LPM3) current, LCD 4-mux mode, internal biasing, charge pump disabled(3)(4)	2.2 V	0	2.4		2.9	3.6	3.8		5.8	12.2	µA
			1	2.5		3.1		4.0		6.0		
			2	2.6		3.3	3.9	4.2		6.3	13.4	
I_{LPM3} LCD, int. bias	Low-power mode 3 (LPM3) current, LCD 4-mux mode, internal biasing, charge pump disabled(3)(4)	3.0 V	0	2.8		3.2	3.9	4.1		6.4	13.3	µA
			1	2.9		3.4		4.3		6.7		
			2	3.1		3.6		4.5		7.0		
			3	3.1		3.6	4.5	4.5		7.0	14.7	
I_{LPM3} LCD,CP	Low-power mode 3 (LPM3) current, LCD 4-mux mode, internal biasing, charge pump enabled(3)(5)	2.2 V	0			3.8						µA
			1			3.9						
			2			4.0						
		3.0 V	0			4.0						
			1			4.1						
			2			4.2						
			3			4.2						

(1) All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.
(2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.
(3) Current for watchdog timer clocked by ACLK and RTC clocked by XT1 included. ACLK = low-frequency crystal operation (XTS = 0, XT1DRIVEx = 0).
CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 0 (LPM3), f_{ACLK} = 32768 Hz, $f_{MCLK} = f_{SMCLK} = f_{DCO}$ = 0 MHz
Current for brownout, high-side supervisor (SVS_H) normal mode included. Low-side supervisor (SVS_L) and low-side monitor (SVM_L) disabled. High-side monitor (SVM_H) disabled. RAM retention enabled.
(4) LCDMx = 11 (4-mux mode), LCDREXT = 0, LCDEXTBIAS = 0 (internal biasing), LCD2B = 0 (1/3 bias), LCDCPEN = 0 (charge pump disabled), LCDSSEL = 0, LCDPREx = 101, LCDDIVx = 00011 (f_{LCD} = 32768 Hz / 32 / 4 = 256 Hz)
Even segments S0, S2, ... = 0 and odd segments S1, S3, ... = 1. No LCD panel load.
(5) LCDMx = 11 (4-mux mode), LCDREXT = 0, LCDEXTBIAS = 0 (internal biasing), LCD2B = 0 (1/3 bias), LCDCPEN = 1 (charge pump enabled), VLCDx = 1000 (V_{LCD} = 3 V, typical), LCDSSEL = 0, LCDPREx = 101, LCDDIVx = 00011 (f_{LCD} = 32768 Hz / 32 / 4 = 256 Hz)
Even segments S0, S2, ... = 0 and odd segments S1, S3, ... = 1. No LCD panel load.

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5.7 Thermal Resistance Characteristics

THERMAL METRIC(1) (2)			VALUE	UNIT
$R\theta_{JA}$	Junction-to-ambient thermal resistance, still air	LQFP 80 (PN)	46.3	°C/W
		LQFP 100 (PZ)	45.6	
$R\theta_{JC(TOP)}$	Junction-to-case (top) thermal resistance	LQFP 80 (PN)	11.5	°C/W
		LQFP 100 (PZ)	11.0	
$R\theta_{JC(BOTTOM)}$	Junction-to-case (bottom) thermal resistance	LQFP 80 (PN)	N/A(3)	°C/W
		LQFP 100 (PZ)	N/A	
$R\theta_{JB}$	Junction-to-board thermal resistance	LQFP 80 (PN)	21.9	°C/W
		LQFP 100 (PZ)	23.4	
Ψ_{JT}	Junction-to-package-top thermal characterization parameter	LQFP 80 (PN)	0.5	°C/W
		LQFP 100 (PZ)	0.4	
Ψ_{JB}	Junction-to-board thermal characterization parameter	LQFP 80 (PN)	21.6	°C/W
		LQFP 100 (PZ)	23.0	

(1) For more information about traditional and new thermal metrics, see *Semiconductor and IC Package Thermal Metrics*.
(2) These values are based on a JEDEC-defined 2S2P system (with the exception of the Theta JC [$R\theta_{JC}$] value, which is based on a JEDEC-defined 1S0P system) and will change based on environment as well as application. For more information, see these EIA/JEDEC standards:
- JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions - Natural Convection (Still Air)*
- JESD51-3, *Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*
- JESD51-7, *High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*
- JESD51-9, *Test Boards for Area Array Surface Mount Package Thermal Measurements*

(3) N/A = not applicable

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5.8 Digital I/O Ports

Table 5-1 lists the characteristics of the schmitt-trigger Inputs.

Table 5-1. Schmitt-Trigger Inputs – General-Purpose I/O

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage		1.8 V	0.80		1.40	V
			3 V	1.50		2.10	
V_{IT-}	Negative-going input threshold voltage		1.8 V	0.45		1.00	V
			3 V	0.75		1.65	
V_{hys}	Input voltage hysteresis ($V_{IT+} – V_{IT-}$)		1.8 V	0.3		0.85	V
			3 V	0.4		1.0	
R_{Pull}	Pullup or pulldown resistor(1)	For pullup: $V_{IN} = V_{SS}$ For pulldown: $V_{IN} = V_{CC}$		20	35	50	kΩ
C_I	Input capacitance	$V_{IN} = V_{SS}$ or V_{CC}			5		pF

(1) Also applies to $\overline{RST}$ pin when pullup or pulldown resistor is enabled.

Table 5-2 lists the characteristics of the P1 and P2 inputs.

Table 5-2. Inputs – Ports P1 and P2(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
$t_{(int)}$	External interrupt timing(2)	Port P1, P2: P1.x to P2.x, External trigger pulse duration to set interrupt flag	2.2 V, 3 V	20		ns

(1) Some devices may contain additional ports with interrupts. See the block diagram and terminal function descriptions.
(2) An external signal sets the interrupt flag every time the minimum interrupt pulse duration $t_{(int)}$ is met. It might be set by trigger signals shorter than $t_{(int)}$.

Table 5-3 lists the characteristics of the GPIO leakage current.

Table 5-3. Leakage Current – General-Purpose I/O

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
$I_{lkg(Px.y)}$	High-impedance leakage current	See (1)(2)	1.8 V, 3 V		±50	nA

(1) The leakage current is measured with V_{SS} or V_{CC} applied to the corresponding pins, unless otherwise noted.
(2) The leakage of the digital port pins is measured individually. The port pin is selected for input and the pullup or pulldown resistor is disabled.

Table 5-4 lists the characteristics of the full drive strength GPIO output.

Table 5-4. Outputs – General-Purpose I/O (Full Drive Strength)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
V_{OH}	High-level output voltage	$I_{(OHmax)} = –3$ mA(1)	1.8 V	$V_{CC} – 0.25$	V_{CC}	V
		$I_{(OHmax)} = –10$ mA(1)		$V_{CC} – 0.60$	V_{CC}	
		$I_{(OHmax)} = –5$ mA(1)	3 V	$V_{CC} – 0.25$	V_{CC}	
		$I_{(OHmax)} = –15$ mA(1)		$V_{CC} – 0.60$	V_{CC}	
V_{OL}	Low-level output voltage	$I_{(OLmax)} = 3$ mA(2)	1.8 V	V_{SS}	$V_{SS} + 0.25$	V
		$I_{(OLmax)} = 10$ mA(3)		V_{SS}	$V_{SS} + 0.60$	
		$I_{(OLmax)} = 5$ mA(2)	3 V	V_{SS}	$V_{SS} + 0.25$	
		$I_{(OLmax)} = 15$ mA(3)		V_{SS}	$V_{SS} + 0.60$	

(1) The maximum total current, $I_{(OHmax)}$, for all outputs combined should not exceed ±20 mA to hold the maximum voltage drop specified. See Section 5.3 for more details.
(2) The maximum total current, $I_{(OLmax)}$, for all outputs combined should not exceed ±48 mA to hold the maximum voltage drop specified.
(3) The maximum total current, $I_{(OLmax)}$, for all outputs combined should not exceed ±100 mA to hold the maximum voltage drop specified.

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5.8.1 Typical Characteristics – General-Purpose I/O (Full Drive Strength)

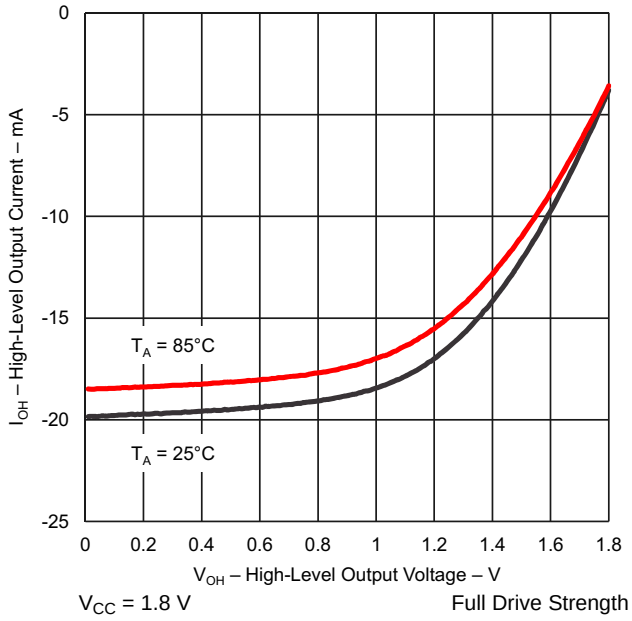


Figure 5-2. High-Level Output Current vs High-Level Output Voltage

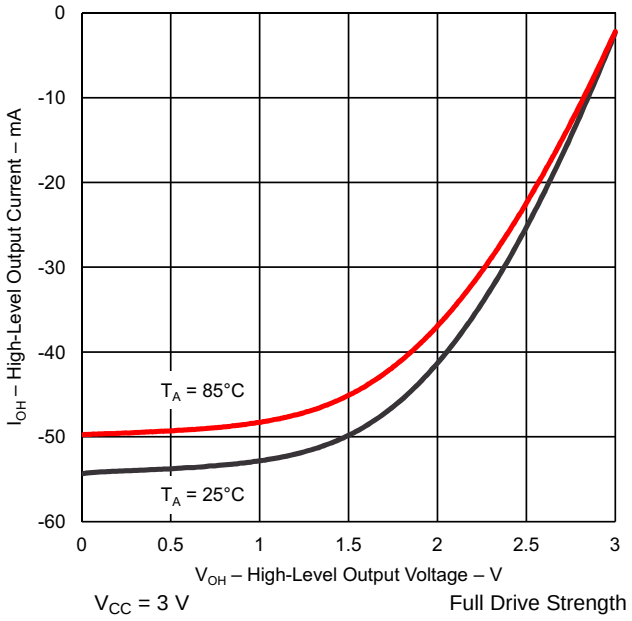


Figure 5-3. High-Level Output Current vs High-Level Output Voltage

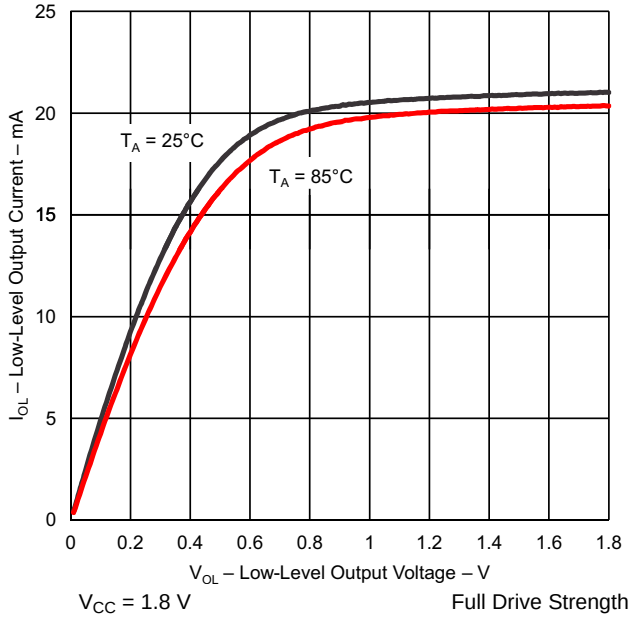


Figure 5-4. Low-Level Output Current vs Low-Level Output Voltage

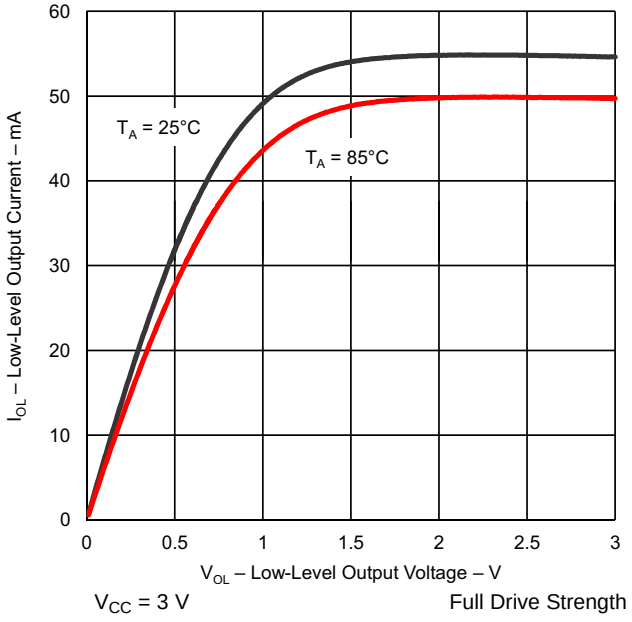


Figure 5-5. Low-Level Output Current vs Low-Level Output Voltage

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Table 5-5 lists the characteristics of the reduced drive strength GPIO output.

Table 5-5. Outputs – General-Purpose I/O (Reduced Drive Strength)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
V_{OH}	High-level output voltage	$I_{(OHmax)}$ = –1 mA(2)	1.8 V	V_{CC} – 0.25	V_{CC}	V
		$I_{(OHmax)}$ = –3 mA(2)		V_{CC} – 0.60	V_{CC}	
		$I_{(OHmax)}$ = –2 mA(2)	3.0 V	V_{CC} – 0.25	V_{CC}	
		$I_{(OHmax)}$ = –6 mA(2)		V_{CC} – 0.60	V_{CC}	
V_{OL}	Low-level output voltage	$I_{(OLmax)}$ = 1 mA(3)	1.8 V	V_{SS}	V_{SS} + 0.25	V
		$I_{(OLmax)}$ = 3 mA(4)		V_{SS}	V_{SS} + 0.60	
		$I_{(OLmax)}$ = 2 mA(3)	3.0 V	V_{SS}	V_{SS} + 0.25	
		$I_{(OLmax)}$ = 6 mA(4)		V_{SS}	V_{SS} + 0.60	

(1) Selecting reduced drive strength may reduce EMI.
(2) The maximum total current, $I_{(OHmax)}$, for all outputs combined should not exceed ±20 mA to hold the maximum voltage drop specified. See Section 5.3 for more details.
(3) The maximum total current, $I_{(OLmax)}$, for all outputs combined, should not exceed ±48 mA to hold the maximum voltage drop specified.
(4) The maximum total current, $I_{(OLmax)}$, for all outputs combined, should not exceed ±100 mA to hold the maximum voltage drop specified.

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5.8.2 Typical Characteristics – General-Purpose I/O (Reduced Drive Strength)

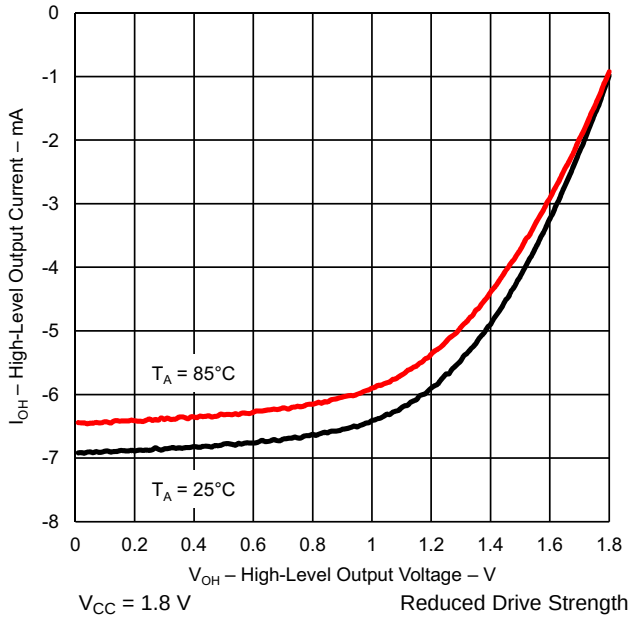


Figure 5-6. High-Level Output Current vs High-Level Output Voltage

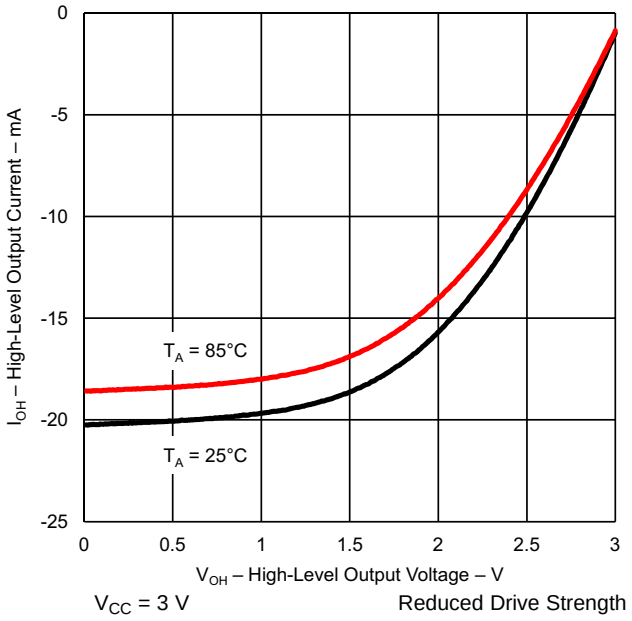


Figure 5-7. High-Level Output Current vs High-Level Output Voltage

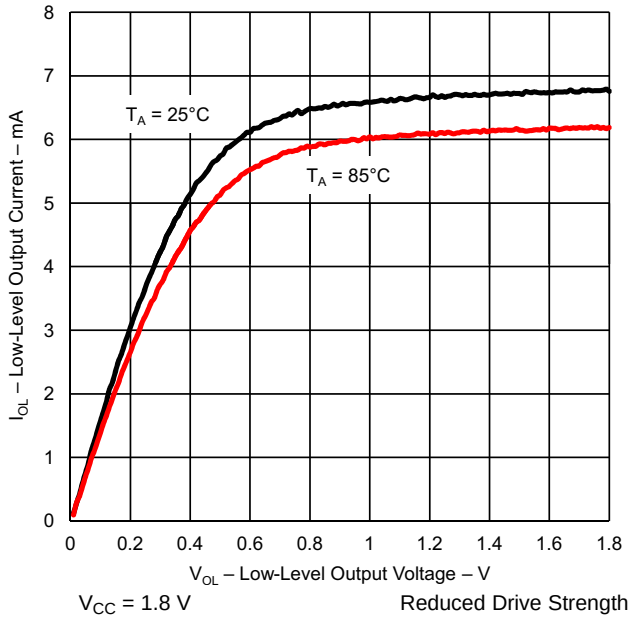


Figure 5-8. Low-Level Output Current vs Low-Level Output Voltage

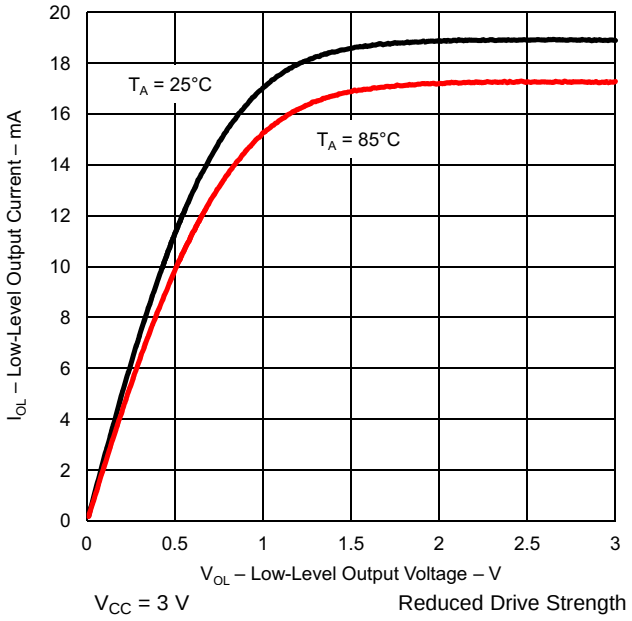


Figure 5-9. Low-Level Output Current vs Low-Level Output Voltage

Table 5-6 lists the characteristics of the GPIO output frequency.

Table 5-6. Output Frequency – General-Purpose I/O

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	MAX	UNIT
$f_{Px.y}$	Port output frequency (with load)	See (1)(2)	V_{CC} = 1.8 V, PMMCOREVx = 0		16	MHz
			V_{CC} = 3 V, PMMCOREVx = 3		25	
f_{Port_CLK}	Clock output frequency	ACLK, SMCLK, MCLK, C_L = 20 pF(2)	V_{CC} = 1.8 V, PMMCOREVx = 0		16	MHz
			V_{CC} = 3 V, PMMCOREVx = 3		25	

(1) A resistive divider with 2 × R1 between V_{CC} and V_{SS} is used as load. The output is connected to the center tap of the divider. For full drive strength, R1 = 550 Ω. For reduced drive strength, R1 = 1.6 kΩ. C_L = 20 pF is connected to the output to V_{SS}.
(2) The output voltage reaches at least 10% and 90% V_{CC} at the specified toggle frequency.

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5.9 Clock Specifications

Table 5-7 lists the characteristics of the XT1 oscillator in low-frequency mode.

Table 5-7. Crystal Oscillator, XT1, Low-Frequency Mode(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
$\Delta I_{DVCC.LF}$	Differential XT1 oscillator crystal current consumption from lowest drive setting, LF mode	f_{OSC} = 32768 Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 1, T_A = 25°C	3.0 V		0.075		µA
		f_{OSC} = 32768 Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 2, T_A = 25°C			0.170		
		f_{OSC} = 32768 Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 3, T_A = 25°C			0.290		
$f_{XT1,LF0}$	XT1 oscillator crystal frequency, LF mode	XTS = 0, XT1BYPASS = 0			32768		Hz
$f_{XT1,LF,SW}$	XT1 oscillator logic-level square-wave input frequency, LF mode	XTS = 0, XT1BYPASS = 1(2) (3)		10	32.768	50	kHz
OA_{LF}	Oscillation allowance for LF crystals(4)	XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 0, $f_{XT1,LF}$ = 32768 Hz, $C_{L,eff}$ = 6 pF			210		kΩ
		XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 1, $f_{XT1,LF}$ = 32768 Hz, $C_{L,eff}$ = 12 pF			300		
$C_{L,eff}$	Integrated effective load capacitance, LF mode(5)	XTS = 0, XCAPx = 0(6)			1		pF
		XTS = 0, XCAPx = 1			5.5		
		XTS = 0, XCAPx = 2			8.5		
		XTS = 0, XCAPx = 3			12.0		
	Duty cycle, LF mode	XTS = 0, Measured at ACLK, $f_{XT1,LF}$ = 32768 Hz		30%		70%	
$f_{Fault,LF}$	Oscillator fault frequency, LF mode(7)	XTS = 0(8)		10		10000	Hz
$t_{START,LF}$	Start-up time, LF mode	f_{OSC} = 32768 Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 0, T_A = 25°C, $C_{L,eff}$ = 6 pF	3.0 V		1000		ms
		f_{OSC} = 32768 Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVEx = 3, T_A = 25°C, $C_{L,eff}$ = 12 pF			500		

(1) To improve EMI on the XT1 oscillator, the following guidelines should be observed.
- Keep the trace between the device and the crystal as short as possible.
- Design a good ground plane around the oscillator pins.
- Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
- Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
- Use assembly materials and processes that avoid any parasitic load on the oscillator XIN and XOUT pins.
- If conformal coating is used, make sure that it does not induce capacitive or resistive leakage between the oscillator pins.

(2) When XT1BYPASS is set, XT1 circuits are automatically powered down. Input signal is a digital square wave with parametrics defined in the Schmitt-trigger inputs section of this data sheet.

(3) Maximum frequency of operation of the entire device cannot be exceeded.

(4) Oscillation allowance is based on a safety factor of 5 for recommended crystals. The oscillation allowance is a function of the XT1DRIVEx settings and the effective load. In general, comparable oscillator allowance can be achieved based on the following guidelines, but should be evaluated based on the actual crystal selected for the application:
- For XT1DRIVEx = 0, $C_{L,eff} \le 6$ pF.
- For XT1DRIVEx = 1, 6 pF $\le C_{L,eff} \le 9$ pF.
- For XT1DRIVEx = 2, 6 pF $\le C_{L,eff} \le 10$ pF.
- For XT1DRIVEx = 3, $C_{L,eff} \ge 6$ pF.

(5) Includes parasitic bond and package capacitance (approximately 2 pF per pin).
Because the PCB adds additional capacitance, TI recommends verifying the correct load by measuring the ACLK frequency. For a correct setup, the effective load capacitance should always match the specification of the used crystal.

(6) Requires external capacitors at both terminals. Values are specified by crystal manufacturers.

(7) Frequencies below the MIN specification set the fault flag. Frequencies above the MAX specification do not set the fault flag. Frequencies between the MIN and MAX specifications might set the flag.

(8) Measured with logic-level input frequency but also applies to operation with crystals.

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Table 5-8 lists the characteristics of the VLO.

Table 5-8. Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
f_{VLO}	VLO frequency	Measured at ACLK	1.8 V to 3.6 V	6	9.4	15	kHz
df_{VLO}/d_T	VLO frequency temperature drift	Measured at ACLK(1)	1.8 V to 3.6 V		0.5		%/°C
df_{VLO}/dV_{CC}	VLO frequency supply voltage drift	Measured at ACLK(2)	1.8 V to 3.6 V		4		%/V
	Duty cycle	Measured at ACLK	1.8 V to 3.6 V	30%		70%	

(1) Calculated using the box method: (MAX(–40°C to 85ºC) – MIN(–40°C to 85ºC)) / MIN(–40°C to 85ºC) / (85ºC – (–40ºC))
(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

Table 5-9 lists the characteristics of the REFO.

Table 5-9. Internal Reference, Low-Frequency Oscillator (REFO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
I_{REFO}	REFO oscillator current consumption	T_A = 25°C	1.8 V to 3.6 V		3		µA
f_{REFO}	REFO frequency calibrated	Measured at ACLK	1.8 V to 3.6 V		32768		Hz
	REFO absolute tolerance calibrated	Full temperature range	1.8 V to 3.6 V			±3.5%	
		T_A = 25°C	3 V			±1.5%	
df_{REFO}/d_T	REFO frequency temperature drift	Measured at ACLK(1)	1.8 V to 3.6 V		0.01		%/°C
df_{REFO}/dV_{CC}	REFO frequency supply voltage drift	Measured at ACLK(2)	1.8 V to 3.6 V		1.0		%/V
	Duty cycle	Measured at ACLK	1.8 V to 3.6 V	40%	50%	60%	
t_{START}	REFO start-up time	40%/60% duty cycle	1.8 V to 3.6 V		25		µs

(1) Calculated using the box method: (MAX(–40°C to 85ºC) – MIN(–40°C to 85ºC)) / MIN(–40°C to 85ºC) / (85ºC – (–40ºC))
(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

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Table 5-10 lists the frequency characteristics of the DCO.

Table 5-10. DCO Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{DCO(0,0)}$	DCO frequency (0, 0)(1)	DCORSELx = 0, DCOx = 0, MODx = 0	0.07		0.20	MHz
$f_{DCO(0,31)}$	DCO frequency (0, 31)(1)	DCORSELx = 0, DCOx = 31, MODx = 0	0.70		1.70	MHz
$f_{DCO(1,0)}$	DCO frequency (1, 0)(1)	DCORSELx = 1, DCOx = 0, MODx = 0	0.15		0.36	MHz
$f_{DCO(1,31)}$	DCO frequency (1, 31)(1)	DCORSELx = 1, DCOx = 31, MODx = 0	1.47		3.45	MHz
$f_{DCO(2,0)}$	DCO frequency (2, 0)(1)	DCORSELx = 2, DCOx = 0, MODx = 0	0.32		0.75	MHz
$f_{DCO(2,31)}$	DCO frequency (2, 31)(1)	DCORSELx = 2, DCOx = 31, MODx = 0	3.17		7.38	MHz
$f_{DCO(3,0)}$	DCO frequency (3, 0)(1)	DCORSELx = 3, DCOx = 0, MODx = 0	0.64		1.51	MHz
$f_{DCO(3,31)}$	DCO frequency (3, 31)(1)	DCORSELx = 3, DCOx = 31, MODx = 0	6.07		14.0	MHz
$f_{DCO(4,0)}$	DCO frequency (4, 0)(1)	DCORSELx = 4, DCOx = 0, MODx = 0	1.3		3.2	MHz
$f_{DCO(4,31)}$	DCO frequency (4, 31)(1)	DCORSELx = 4, DCOx = 31, MODx = 0	12.3		28.2	MHz
$f_{DCO(5,0)}$	DCO frequency (5, 0)(1)	DCORSELx = 5, DCOx = 0, MODx = 0	2.5		6.0	MHz
$f_{DCO(5,31)}$	DCO frequency (5, 31)(1)	DCORSELx = 5, DCOx = 31, MODx = 0	23.7		54.1	MHz
$f_{DCO(6,0)}$	DCO frequency (6, 0)(1)	DCORSELx = 6, DCOx = 0, MODx = 0	4.6		10.7	MHz
$f_{DCO(6,31)}$	DCO frequency (6, 31)(1)	DCORSELx = 6, DCOx = 31, MODx = 0	39.0		88.0	MHz
$f_{DCO(7,0)}$	DCO frequency (7, 0)(1)	DCORSELx = 7, DCOx = 0, MODx = 0	8.5		19.6	MHz
$f_{DCO(7,31)}$	DCO frequency (7, 31)(1)	DCORSELx = 7, DCOx = 31, MODx = 0	60		135	MHz
$S_{DCORSEL}$	Frequency step between range DCORSEL and DCORSEL + 1	$S_{RSEL} = f_{DCO(DCORSEL+1,DCO)}/f_{DCO(DCORSEL,DCO)}$	1.2		2.3	ratio
S_{DCO}	Frequency step between tap DCO and DCO + 1	$S_{DCO} = f_{DCO(DCORSEL,DCO+1)}/f_{DCO(DCORSEL,DCO)}$	1.02		1.12	ratio
	Duty cycle	Measured at SMCLK	40%	50%	60%	
df_{DCO}/dT	DCO frequency temperature drift	f_{DCO} = 1 MHz		0.1		%/°C
df_{DCO}/dV_{CORE}	DCO frequency voltage drift	f_{DCO} = 1 MHz		1.9		%/V

(1) When selecting the proper DCO frequency range (DCORSELx), the target DCO frequency, f_{DCO}, should be set to reside within the range of $f_{DCO(n,\ 0),MAX} \le f_{DCO} \le f_{DCO(n,\ 31),MIN}$, where $f_{DCO(n,\ 0),MAX}$ represents the maximum frequency specified for the DCO frequency, range n, tap 0 (DCOx = 0) and $f_{DCO(n,31),MIN}$ represents the minimum frequency specified for the DCO frequency, range n, tap 31 (DCOx = 31). This ensures that the target DCO frequency resides within the range selected. If the actual f_{DCO} frequency for the selected range causes the FLL or the application to select tap 0 or 31, the DCO fault flag is set to report that the selected range is at its minimum or maximum tap setting.



Figure 5-10. Typical DCO Frequency

5.10 Power-Management Module (PMM)

Table 5-11 lists the brownout characteristics of the PMM.

Table 5-11. PMM, Brownout Reset (BOR)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(DVCC_BOR_IT-)}$	BOR_H on voltage, DV_{CC} falling level	$\lvert dDV_{CC}/d_t \rvert$ < 3 V/s			1.45	V
$V_{(DVCC_BOR_IT+)}$	BOR_H off voltage, DV_{CC} rising level	$\lvert dDV_{CC}/d_t \rvert$ < 3 V/s	0.80	1.30	1.50	V
$V_{(DVCC_BOR_hys)}$	BOR_H hysteresis		50		250	mV
t_{RESET} (1)	Pulse duration required at $\overline{RST}$/NMI pin to accept a reset		2			µs

(1) Pulse much shorter than 2 µs might trigger reset.

Table 5-12 lists the core voltage characteristics of the PMM.

Table 5-12. PMM, Core Voltage

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CORE3}(AM)	Core voltage, active mode, PMMCOREV = 3	2.4 V ≤ DV_{CC} ≤ 3.6 V		1.93		V
V_{CORE2}(AM)	Core voltage, active mode, PMMCOREV = 2	2.2 V ≤ DV_{CC} ≤ 3.6 V		1.83		V
V_{CORE1}(AM)	Core voltage, active mode, PMMCOREV = 1	2.0 V ≤ DV_{CC} ≤ 3.6 V		1.62		V
V_{CORE0}(AM)	Core voltage, active mode, PMMCOREV = 0	1.8 V ≤ DV_{CC} ≤ 3.6 V		1.42		V
V_{CORE3}(LPM)	Core voltage, low-current mode, PMMCOREV = 3	2.4 V ≤ DV_{CC} ≤ 3.6 V		1.96		V
V_{CORE2}(LPM)	Core voltage, low-current mode, PMMCOREV = 2	2.2 V ≤ DV_{CC} ≤ 3.6 V		1.94		V
V_{CORE1}(LPM)	Core voltage, low-current mode, PMMCOREV = 1	2.0 V ≤ DV_{CC} ≤ 3.6 V		1.74		V
V_{CORE0}(LPM)	Core voltage, low-current mode, PMMCOREV = 0	1.8 V ≤ DV_{CC} ≤ 3.6 V		1.54		V

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Table 5-13 lists the characteristics of the high-side SVS.

Table 5-13. PMM, SVS High Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVSH)}$	SVS current consumption	SVSHE = 0, DV_{CC} = 3.6 V		0		nA
		SVSHE = 1, DV_{CC} = 3.6 V, SVSHFP = 0		200		
		SVSHE = 1, DV_{CC} = 3.6 V, SVSHFP = 1		1.5		µA
$V_{(SVSH_IT-)}$	SVS_H on voltage level(1)	SVSHE = 1, SVSHRVL = 0	1.60	1.65	1.70	V
		SVSHE = 1, SVSHRVL = 1	1.77	1.84	1.90	
		SVSHE = 1, SVSHRVL = 2	1.97	2.04	2.10	
		SVSHE = 1, SVSHRVL = 3	2.09	2.16	2.23	
$V_{(SVSH_IT+)}$	SVS_H off voltage level(1)	SVSHE = 1, SVSMHRRL = 0	1.68	1.74	1.80	V
		SVSHE = 1, SVSMHRRL = 1	1.89	1.95	2.01	
		SVSHE = 1, SVSMHRRL = 2	2.08	2.14	2.21	
		SVSHE = 1, SVSMHRRL = 3	2.21	2.27	2.34	
		SVSHE = 1, SVSMHRRL = 4	2.35	2.41	2.49	
		SVSHE = 1, SVSMHRRL = 5	2.65	2.72	2.80	
		SVSHE = 1, SVSMHRRL = 6	2.96	3.04	3.13	
		SVSHE = 1, SVSMHRRL = 7	2.96	3.04	3.13	
$t_{pd(SVSH)}$	SVS_H propagation delay	SVSHE = 1, dV_{DVCC}/dt = 10 mV/µs, SVSHFP = 1		2.5		µs
		SVSHE = 1, dV_{DVCC}/dt = 1 mV/µs, SVSHFP = 0		20		
$t_{(SVSH)}$	SVS_H on or off delay time	SVSHE = 0 → 1, SVSHFP = 1		12.5		µs
		SVSHE = 0 → 1, SVSHFP = 0		100		
dV_{DVCC}/dt	DV_{CC} rise time		0		1000	V/s

(1) The SVS_H settings available depend on the VCORE (PMMCOREVx) setting. Refer to the *Power Management Module and Supply Voltage Supervisor* chapter in the *MSP430x5xx and MSP430x6xx Family User's Guide* on recommended settings and usage.

Table 5-14 lists the characteristics of the high-side SVM.

Table 5-14. PMM, SVM High Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVMH)}$	SVM_H current consumption	SVMHE = 0, DV_{CC} = 3.6 V		0		nA
		SVMHE = 1, DV_{CC} = 3.6 V, SVMHFP = 0		200		
		SVMHE = 1, DV_{CC} = 3.6 V, SVMHFP = 1		1.5		µA
$V_{(SVMH)}$	SVM_H on or off voltage level(1)	SVMHE = 1, SVSMHRRL = 0	1.68	1.74	1.80	V
		SVMHE = 1, SVSMHRRL = 1	1.89	1.95	2.01	
		SVMHE = 1, SVSMHRRL = 2	2.08	2.14	2.21	
		SVMHE = 1, SVSMHRRL = 3	2.21	2.27	2.34	
		SVMHE = 1, SVSMHRRL = 4	2.35	2.41	2.49	
		SVMHE = 1, SVSMHRRL = 5	2.65	2.72	2.80	
		SVMHE = 1, SVSMHRRL = 6	2.96	3.04	3.13	
		SVMHE = 1, SVSMHRRL = 7	2.96	3.04	3.13	
		SVMHE = 1, SVMHOVPE = 1		3.79		
$t_{pd(SVMH)}$	SVM_H propagation delay	SVMHE = 1, dV_{DVCC}/dt = 10 mV/µs, SVMHFP = 1		2.5		µs
		SVMHE = 1, dV_{DVCC}/dt = 1 mV/µs, SVMHFP = 0		20		
$t_{(SVMH)}$	SVM_H on or off delay time	SVMHE = 0 → 1, SVMHFP = 1		12.5		µs
		SVMHE = 0 → 1, SVMHFP = 0		100		

(1) The SVM_H settings available depend on the VCORE (PMMCOREVx) setting. Refer to the *Power Management Module and Supply Voltage Supervisor* chapter in the *MSP430x5xx and MSP430x6xx Family User's Guide* on recommended settings and usage.

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Table 5-15 lists the characteristics of the low-side SVS.

Table 5-15. PMM, SVS Low Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVSL)}$	SVS_L current consumption	SVSLE = 0, PMMCOREV = 2		0		nA
		SVSLE = 1, PMMCOREV = 2, SVSLFP = 0		200		
		SVSLE = 1, PMMCOREV = 2, SVSLFP = 1		1.5		µA
$t_{pd(SVSL)}$	SVS_L propagation delay	SVSLE = 1, dV_{CORE}/dt = 10 mV/µs, SVSLFP = 1		2.5		µs
		SVSLE = 1, dV_{CORE}/dt = 1 mV/µs, SVSLFP = 0		20		
$t_{(SVSL)}$	SVS_L on or off delay time	SVSLE = 0 → 1, SVSLFP = 1		12.5		µs
		SVSLE = 0 → 1, SVSLFP = 0		100		

Table 5-16 lists the characteristics of the low-side SVM.

Table 5-16. PMM, SVM Low Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVML)}$	SVM_L current consumption	SVMLE = 0, PMMCOREV = 2		0		nA
		SVMLE = 1, PMMCOREV = 2, SVMLFP = 0		200		
		SVMLE = 1, PMMCOREV = 2, SVMLFP = 1		1.5		µA
$t_{pd(SVML)}$	SVM_L propagation delay	SVMLE = 1, dV_{CORE}/dt = 10 mV/µs, SVMLFP = 1		2.5		µs
		SVMLE = 1, dV_{CORE}/dt = 1 mV/µs, SVMLFP = 0		20		
$t_{(SVML)}$	SVM_L on or off delay time	SVMLE = 0 → 1, SVMLFP = 1		12.5		µs
		SVMLE = 0 → 1, SVMLFP = 0		100		

Table 5-17 lists the wake-up times.

Table 5-17. Wake-up Times From Low-Power Modes and Reset

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$t_{WAKE-UP-FAST}$	Wake-up time from LPM2, LPM3, or LPM4 to active mode(1)	PMMCOREV = SVSMLRRL = n (where n = 0, 1, 2, or 3), SVSLFP = 1	f_{MCLK} ≥ 4 MHz		3	5	µs
			1 MHz < f_{MCLK} < 4 MHz		4	6	
$t_{WAKE-UP-SLOW}$	Wake-up time from LPM2, LPM3, or LPM4 to active mode(2)(3)	PMMCOREV = SVSMLRRL = n (where n = 0, 1, 2, or 3), SVSLFP = 0			150	160	µs
$t_{WAKE-UP-LPM4.5}$	Wake-up time from LPM4.5 to active mode(4)				2	3	ms
$t_{WAKE-UP-RESET}$	Wake-up time from $\overline{RST}$ or BOR event to active mode(4)				2	3	ms

(1) This value represents the time from the wake-up event to the first active edge of MCLK. The wake-up time depends on the performance mode of the low-side supervisor (SVS_L) and low-side monitor (SVM_L). $t_{WAKE-UP-FAST}$ is possible with SVS_L and SVM_L in full performance mode or disabled. For specific register settings, see the *Low-Side SVS and SVM Control and Performance Mode Selection* section in the *Power Management Module and Supply Voltage Supervisor* chapter of the *MSP430x5xx and MSP430x6xx Family User's Guide*.

(2) This value represents the time from the wake-up event to the first active edge of MCLK. The wake-up time depends on the performance mode of the low-side supervisor (SVS_L) and low-side monitor (SVM_L). $t_{WAKE-UP-SLOW}$ is set with SVS_L and SVM_L in normal mode (low current mode). For specific register settings, see the *Low-Side SVS and SVM Control and Performance Mode Selection* section in the *Power Management Module and Supply Voltage Supervisor* chapter of the *MSP430x5xx and MSP430x6xx Family User's Guide*.

(3) The wake-up times from LPM0 and LPM1 to AM are not specified. They are proportional to MCLK cycle time but are not affected by the performance mode settings as for LPM2, LPM3, and LPM4.

(4) This value represents the time from the wake-up event to the reset vector execution.

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5.11 Auxiliary Supplies

Table 5-18 lists the operating conditions of the auxiliary supplies.

Table 5-18. Auxiliary Supplies, Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage range for all supplies at pins DVCC, AVCC, AUXVCC1, AUXVCC2, AUXVCC3		1.8		3.6	V
V_{DSYS}	Digital system supply voltage range, $V_{DSYS} = V_{CC} – R_{ON} \times I_{LOAD}$	PMMCOREVx = 0	1.8		3.6	V
		PMMCOREVx = 1	2.0		3.6	
		PMMCOREVx = 2	2.2		3.6	
		PMMCOREVx = 3	2.4		3.6	
V_{ASYS}	Analog system supply voltage range, $V_{ASYS} = V_{CC} – R_{ON} \times I_{LOAD}$		See module specifications			V
C_{VCC}, $C_{AUX1/2}$	Recommended capacitor at pins DVCC, AVCC, AUXVCC1, AUXVCC2			4.7		µF
C_{VSYS}	Recommended capacitor at pins VDSYS and VASYS			4.7		µF
C_{VCORE}	Recommended capacitance at VCORE pin			0.47		µF
C_{AUX3}	Recommended capacitor at pin AUXVCC3			0.47		µF

Table 5-19 lists the current consumption of AUX3.

Table 5-19. Auxiliary Supplies, AUXVCC3 (Backup Subsystem) Currents

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	T_A	MIN	TYP	MAX	UNIT
$I_{AUX3,RTCon}$	AUXVCC3 current with RTC enabled	RTC and 32-kHz oscillator in backup subsystem enabled	3 V	25°C			0.83	µA
				85°C			0.95	
$I_{AUX3,RTCoff}$	AUXVCC3 current with RTC disabled	RTC and 32-kHz oscillator in backup subsystem disabled	3 V	25°C			110	nA
				85°C			165	

Table 5-20 lists the characteristics of the auxiliary supply monitor.

Table 5-20. Auxiliary Supplies, Auxiliary Supply Monitor

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
$I_{CC,Monitor}$	Average supply current for monitoring circuitry drawn from VDSYS	LOCKAUX = 0, AUXMRx = 0, AUX0MD = 0, AUX1MD = 0, AUX2MD = 1, VDSYS = DVCC, VASYS = AVCC, Current measured at VDSYS pin (also see Figure 5-11)	3 V			0.70	µA
$I_{Meas,Monitor}$	Average current drawn from monitored supply during measurement cycle	LOCKAUX = 0, AUXMRx = 0, AUX0MD = 0, AUX1MD = 0, AUX2MD = 1, VDSYS = DVCC, VASYS = AVCC, AUXVCC1 = 3 V, Current measured at AUXVCC1 pin (also see Figure 5-12)				0.11	µA
$V_{Monitor}$	Auxiliary supply threshold level	AUXLVLx = 0		1.67	1.74	1.80	V
		AUXLVLx = 1		1.87	1.95	2.01	
		AUXLVLx = 2		2.06	2.14	2.21	
		AUXLVLx = 3		2.19	2.27	2.33	
		AUXLVLx = 4		2.33	2.41	2.48	
		AUXLVLx = 5		2.63	2.72	2.79	
		AUXLVLx = 6		2.91	3.02	3.10	
		AUXLVLx = 7		2.91	3.02	3.10	

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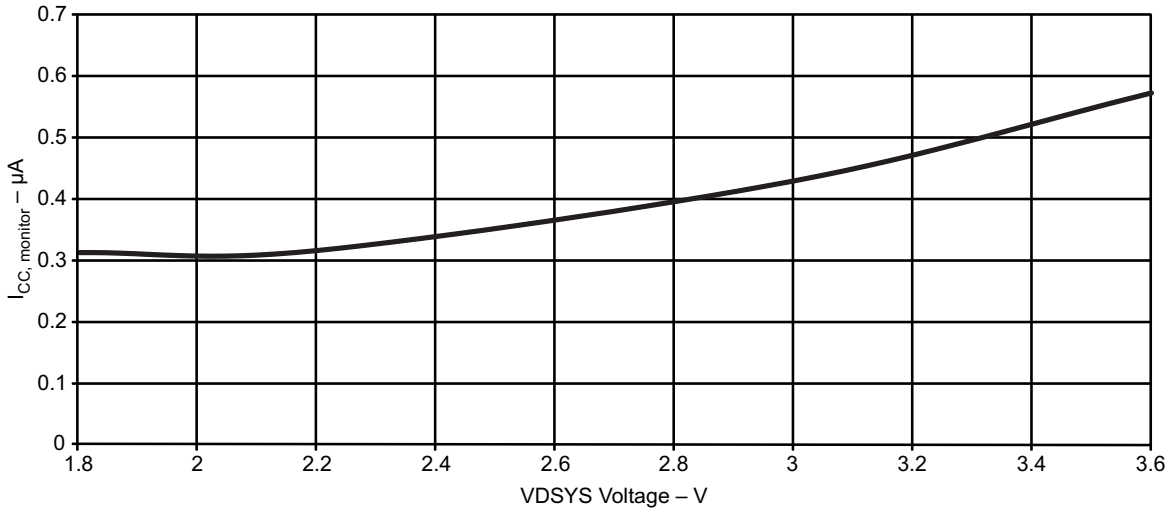


Figure 5-11. VDSYS Voltage vs $I_{CC,Monitor}$

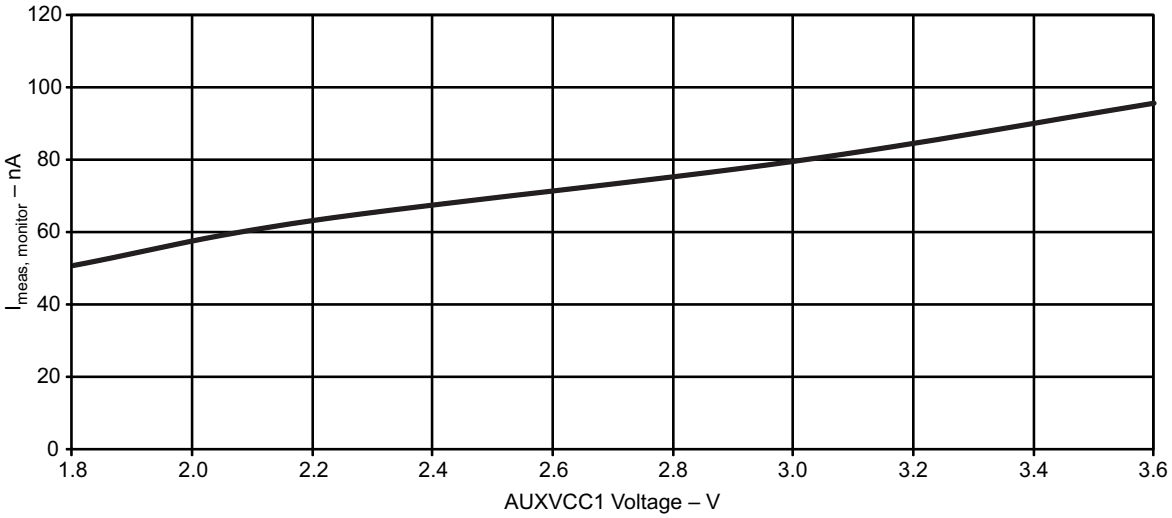


Figure 5-12. AUXVCC1 Voltage vs $I_{Meas,Monitor}$

Table 5-21 lists the ON-resistance characteristics of the auxiliary supplies.

Table 5-21. Auxiliary Supplies, Switch ON-Resistance

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{ON,DVCC}$	ON-resistance of switch between DVCC and VDSYS	$I_{LOAD} = I_{CORE} + I_{IO}$ = 10 mA + 10 mA = 20 mA			5	Ω
$R_{ON,DAUX1}$	ON-resistance of switch between AUXVCC1 and VDSYS	$I_{LOAD} = I_{CORE} + I_{IO}$ = 10 mA + 10 mA = 20 mA			5	Ω
$R_{ON,DAUX2}$	ON-resistance of switch between AUXVCC2 and VDSYS	$I_{LOAD} = I_{CORE} + I_{IO}$ = 10 mA + 10 mA = 20 mA			5	Ω
$R_{ON,AVCC}$	ON-resistance of switch between AVCC and V_{ASYS}	$I_{LOAD} = I_{Modules}$ = 10 mA			5	Ω
$R_{ON,AAUX1}$	ON-resistance of switch between AUXVCC1 and V_{ASYS}	$I_{LOAD} = I_{Modules}$ = 5 mA			20	Ω
$R_{ON,AAUX2}$	ON-resistance of switch between AUXVCC2 and V_{ASYS}	$I_{LOAD} = I_{Modules}$ = 5 mA			20	Ω

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Table 5-22 lists the switching times of the auxiliary supplies.

Table 5-22. Auxiliary Supplies, Switching Time

over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	MAX	UNIT
t_{Switch}	Time from occurence of trigger (SVM or software) to "new" supply connected to system supplies		100	ns
$t_{Recover}$	"Recovery time" after a switch over took place; during this time, no further switching takes place	200	450	µs

Table 5-23 lists the switch leakage of the auxiliary supplies.

Table 5-23. Auxiliary Supplies, Switch Leakage

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{SW,Lkg}$	Current into DVCC, AVCC, AUXVCC1, or AUXVCC2 if not selected	Per supply (but not the highest supply)		50	100	nA
I_{Vmax}	Current drawn from highest supply			450	730	nA

Table 5-24 lists the characteristics of the auxiliary supplies to ADC10_A.

Table 5-24. Auxiliary Supplies, Auxiliary Supplies to ADC10_A

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
V_3	Supply voltage divider $V_3 = V_{Supply}/3$			1.8 V	0.58	0.60	0.62	V
				3.0 V	0.98	1.00	1.02	
				3.6 V	1.18	1.20	1.22	
R_{V3}	Load resistance	AUXADCRx = 0					18	kΩ
		AUXADCRx = 1					1.5	
		AUXADCRx = 2					0.6	
$t_{Sample,V3}$	Sampling time required if V_3 selected	AUXADC = 1, ADC10ON = 1, INCH = 0Ch, Error of conversion result ≤ 1 LSB	AUXADCRx = 0		1000			ns
			AUXADCRx = 1		1000			
			AUXADCRx = 2		1000			

Table 5-25 lists the charge limiting resistor characteristics of the auxiliary supplies.

Table 5-25. Auxiliary Supplies, Charge Limiting Resistor

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
R_{CHARGE}	Charge limiting resistor	AUXCHCx = 1	3 V			5	kΩ
		AUXCHCx = 2	3 V			10	
		AUXCHCx = 3	3 V			20	

5.12 Timer_A

Table 5-26 lists the characteristics of the Timer_A.

Table 5-26. Timer_A

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
f_{TA}	Timer_A input clock frequency	Internal: SMCLK or ACLK, External: TACLK, Duty cycle = 50% ±10%	1.8 V, 3 V		25	MHz
$t_{TA,cap}$	Timer_A capture timing	All capture inputs, minimum pulse duration required for capture	1.8 V, 3 V	20		ns

5.13 eUSCI

Table 5-27. eUSCI (UART Mode) Clock Frequency

PARAMETER		CONDITIONS	V_{CC}	MIN	MAX	UNIT
f_{eUSCI}	eUSCI input clock frequency	Internal: SMCLK or ACLK, External: UCLK, Duty cycle = 50% ±10%			f_{SYSTEM}	MHz
f_{BITCLK}	BITCLK clock frequency (equals baud rate in MBaud)				5	MHz

Table 5-28 lists the switching characteristics of the eUSCI in UART mode.

Table 5-28. eUSCI (UART Mode) Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
t_t	UART receive deglitch time(1)	UCGLITx = 0	2 V, 3 V	10	15	25	ns
		UCGLITx = 1		30	50	85	
		UCGLITx = 2		50	80	150	
		UCGLITx = 3		70	120	200	

(1) Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized their duration should exceed the maximum specification of the deglitch time.

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Table 5-29 lists the supported clock frequencies of the eUSCI in SPI master mode.

Table 5-29. eUSCI (SPI Master Mode) Clock Frequency

PARAMETER		CONDITIONS	V_{CC}	MIN	MAX	UNIT
f_{eUSCI}	eUSCI input clock frequency	Internal: SMCLK or ACLK, Duty cycle = 50% ±10%			f_{SYSTEM}	MHz

Table 5-30 lists the switching characteristics of the eUSCI in SPI master mode.

Table 5-30. eUSCI (SPI Master Mode) Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	MAX	UNIT
$t_{STE,LEAD}$	STE lead time, STE active to clock	UCSTEM = 0, UCMODEx = 01 or 10	2 V, 3 V	150		ns
		UCSTEM = 1, UCMODEx = 01 or 10	2 V, 3 V	150		
$t_{STE,LAG}$	STE lag time, Last clock to STE inactive	UCSTEM = 0, UCMODEx = 01 or 10	2 V, 3 V	200		ns
		UCSTEM = 1, UCMODEx = 01 or 10	2 V, 3 V	200		
$t_{STE,ACC}$	STE access time, STE active to SIMO data out	UCSTEM = 0, UCMODEx = 01 or 10	2 V		50	ns
			3 V		30	
		UCSTEM = 1, UCMODEx = 01 or 10	2 V		50	
			3 V		30	
$t_{STE,DIS}$	STE disable time, STE inactive to SIMO high impedance	UCSTEM = 0, UCMODEx = 01 or 10	2 V		40	ns
			3 V		25	
		UCSTEM = 1, UCMODEx = 01 or 10	2 V		40	
			3 V		25	
$t_{SU,MI}$	SOMI input data setup time		2 V	50		ns
			3 V	30		
$t_{HD,MI}$	SOMI input data hold time		2 V	0		ns
			3 V	0		
$t_{VALID,MO}$	SIMO output data valid time(2)	UCLK edge to SIMO valid, C_L = 20 pF	2 V		9	ns
			3 V		5	
$t_{HD,MO}$	SIMO output data hold time(3)	C_L = 20 pF	2 V	0		ns
			3 V	0		

(1) $f_{UCxCLK} = 1/2t_{LO/HI}$ with $tL_{O/HI} = \max(t_{VALID,MO(eUSCI)} + t_{SU,SI(Slave)}, t_{SU,MI(eUSCI)} + t_{VALID,SO(Slave)})$
For the slave parameters $t_{SU,SI(Slave)}$ and $t_{VALID,SO(Slave)}$, see the SPI parameters of the attached slave.
(2) Specifies the time to drive the next valid data to the SIMO output after the output changing UCLK clock edge. See the timing diagrams in Figure 5-13 and Figure 5-14.
(3) Specifies how long data on the SIMO output is valid after the output changing UCLK clock edge. Negative values indicate that the data on the SIMO output can become invalid before the output changing clock edge observed on UCLK. See the timing diagrams in Figure 5-13 and Figure 5-14.

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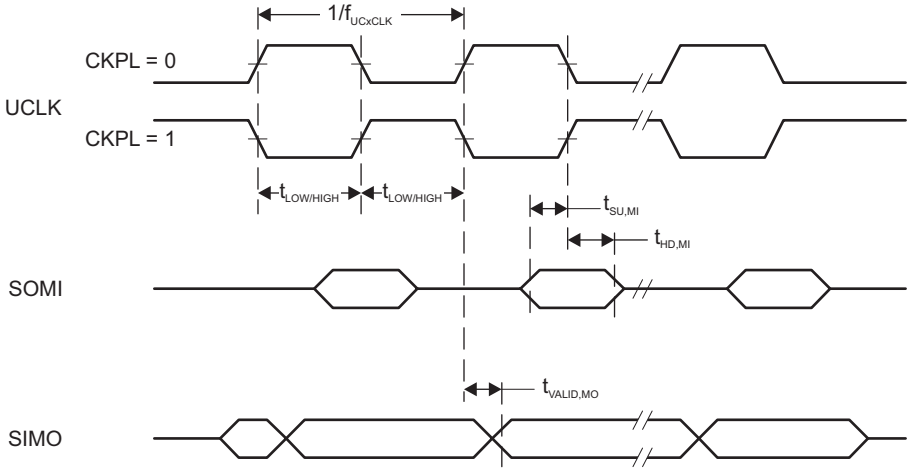


Figure 5-13. SPI Master Mode, CKPH = 0

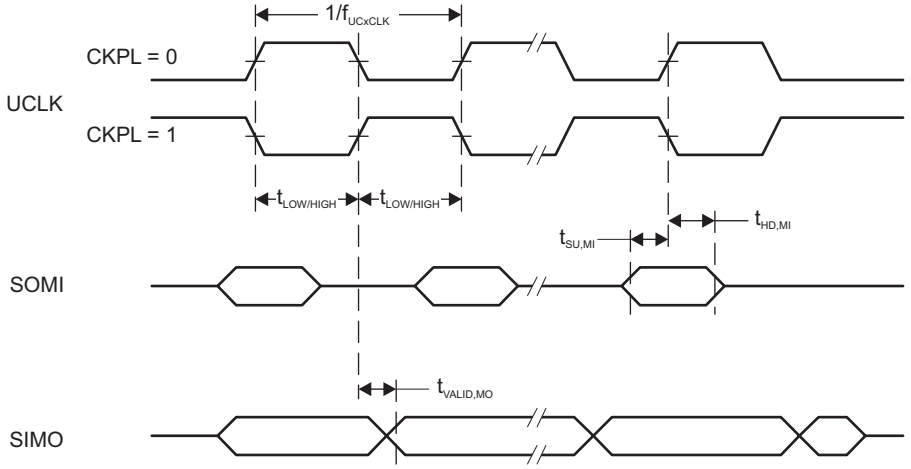


Figure 5-14. SPI Master Mode, CKPH = 1

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Table 5-31 lists the switching characteristics of the eUSCI in SPI slave mode.

Table 5-31. eUSCI (SPI Slave Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
$t_{STE,LEAD}$	STE lead time, STE active to clock		2.0 V	4			ns
			3.0 V	3			
$t_{STE,LAG}$	STE lag time, Last clock to STE inactive		2.0 V	0			ns
			3.0 V	0			
$t_{STE,ACC}$	STE access time, STE active to SOMI data out		2.0 V			46	ns
			3.0 V			24	
$t_{STE,DIS}$	STE disable time, STE inactive to SOMI high impedance		2.0 V			38	ns
			3.0 V			25	
$t_{SU,SI}$	SIMO input data setup time		2.0 V	2			ns
			3.0 V	1			
$t_{HD,SI}$	SIMO input data hold time		2.0 V	2			ns
			3.0 V	2			
$t_{VALID,SO}$	SOMI output data valid time(2)	UCLK edge to SOMI valid, C_L = 20 pF	2.0 V			55	ns
			3.0 V			32	
$t_{HD,SO}$	SOMI output data hold time(3)	C_L = 20 pF	2.0 V	24			ns
			3.0 V	16			

(1) $f_{UCxCLK} = 1/2t_{LO/HI}$ with $tL_{O/HI} = \max(t_{VALID,MO(Master)} + t_{SU,SI(eUSCI)}, t_{SU,MI(Master)} + t_{VALID,SO(eUSCI)})$
For the master parameters $t_{SU,MI(Master)}$ and $t_{VALID,MO(Master)}$, see the SPI parameters of the attached master.
(2) Specifies the time to drive the next valid data to the SOMI output after the output changing UCLK clock edge. See the timing diagrams in Figure 5-15 and Figure 5-16.
(3) Specifies how long data on the SOMI output is valid after the output changing UCLK clock edge. See the timing diagrams inFigure 5-15 and Figure 5-16.

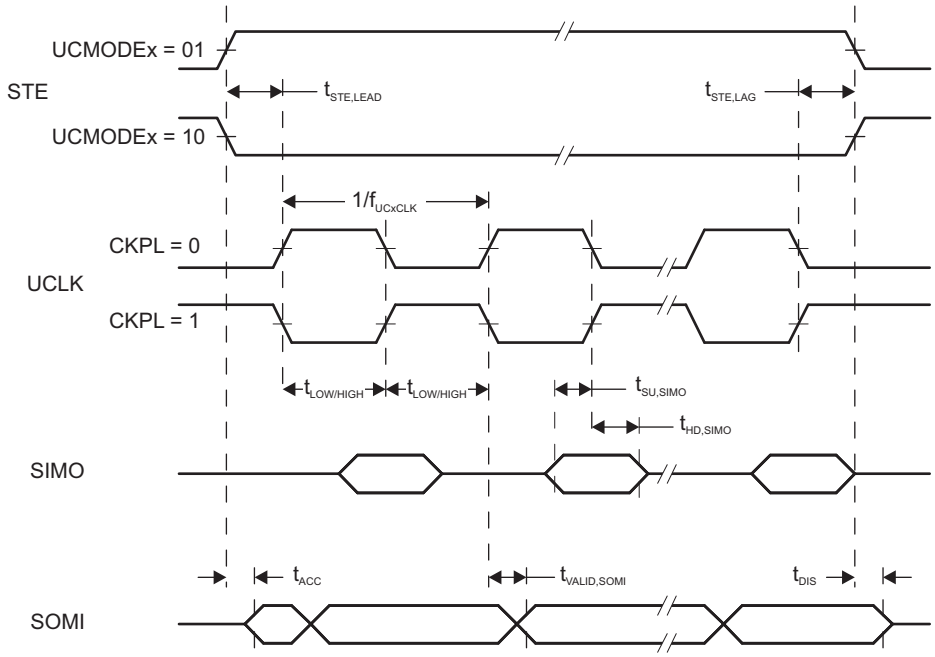


Figure 5-15. SPI Slave Mode, CKPH = 0

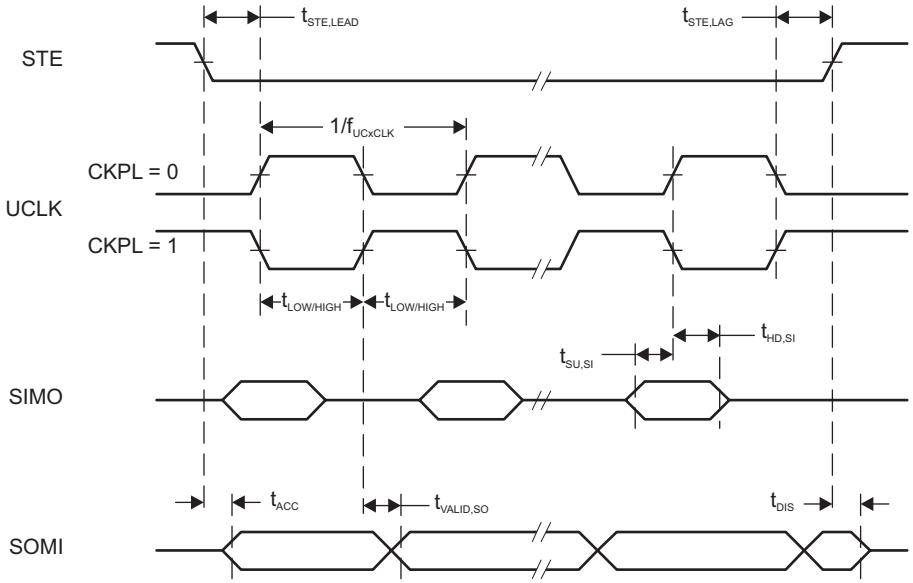


Figure 5-16. SPI Slave Mode, CKPH = 1

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Table 5-32 lists the switching characteristics of the eUSCI in I²C mode.

Table 5-32. eUSCI (I²C Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-17)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
f_{eUSCI}	eUSCI input clock frequency	Internal: SMCLK, ACLK External: UCLK Duty cycle = 50% ±10%				f_{SYSTEM}	MHz
f_{SCL}	SCL clock frequency		2 V, 3 V	0		400	kHz
$t_{HD,STA}$	Hold time (repeated) START	f_{SCL} = 100 kHz	2 V, 3 V	5.1			µs
		f_{SCL} > 100 kHz		1.5			
$t_{SU,STA}$	Setup time for a repeated START	f_{SCL} = 100 kHz	2 V, 3 V	5.1			µs
		f_{SCL} > 100 kHz		1.4			
$t_{HD,DAT}$	Data hold time		2 V, 3 V	0.4			µs
$t_{SU,DAT}$	Data setup time	f_{SCL} = 100 kHz	2 V, 3 V	5.0			µs
		f_{SCL} > 100 kHz	2 V, 3 V	1.3			
$t_{SU,STO}$	Setup time for STOP	f_{SCL} = 100 kHz	2 V, 3 V	5.2			µs
		f_{SCL} > 100 kHz		1.7			
t_{SP}	Pulse duration of spikes suppressed by input filter	UCGLITx = 0	2 V, 3 V	75		220	ns
		UCGLITx = 1		35		120	
		UCGLITx = 2		30		60	
		UCGLITx = 3		20		35	
$t_{TIMEOUT}$	Clock low time-out	UCCLTOx = 1	2 V, 3 V		30		ms
		UCCLTOx = 2			33		
		UCCLTOx = 3			37		

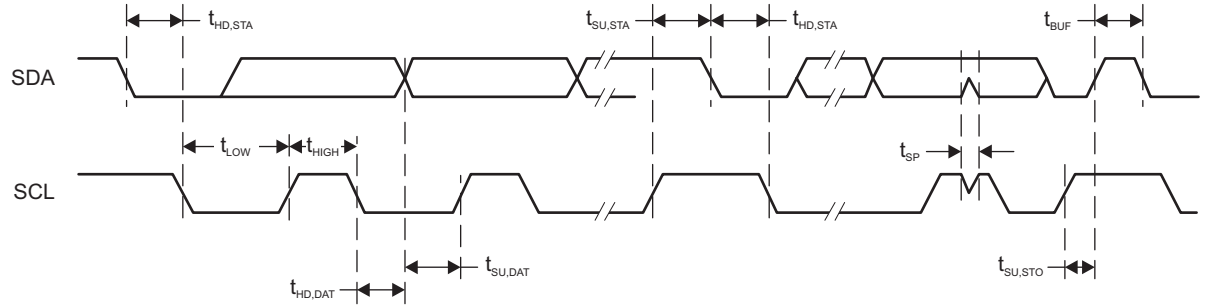


Figure 5-17. I²C Mode Timing

5.14 LCD Controller

Table 5-33 lists the recommended operating conditions of the LCD_C.

Table 5-33. LCD_C Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
$V_{CC,LCD_C,CP\ en,3.6}$	Supply voltage range, charge pump enabled, $V_{LCD} \le 3.6$ V	LCDCPEN = 1, 0000 < VLCDx ≤ 1111 (charge pump enabled, $V_{LCD} \le 3.6$ V)	2.2		3.6	V
$V_{CC,LCD_C,CP\ en,3.3}$	Supply voltage range, charge pump enabled, $V_{LCD} \le 3.3$ V	LCDCPEN = 1, 0000 < VLCDx ≤ 1100 (charge pump enabled, $V_{LCD} \le 3.3$ V)	2.0		3.6	V
$V_{CC,LCD_C,int.\ bias}$	Supply voltage range, internal biasing, charge pump disabled	LCDCPEN = 0, VLCDEXT = 0	2.4		3.6	V
$V_{CC,LCD_C,ext.\ bias}$	Supply voltage range, external biasing, charge pump disabled	LCDCPEN = 0, VLCDEXT = 0	2.4		3.6	V
$V_{CC,LCD_C,VLCDEXT}$	Supply voltage range, external LCD voltage, internal or external biasing, charge pump disabled	LCDCPEN = 0, VLCDEXT = 1	2.0		3.6	V
$V_{LCDCAP/R33}$	External LCD voltage at LCDCAP/R33, internal or external biasing, charge pump disabled	LCDCPEN = 0, VLCDEXT = 1	2.4		3.6	V
C_{LCDCAP}	Capacitor on LCDCAP when charge pump enabled	LCDCPEN = 1, VLCDx > 0000 (charge pump enabled)		4.7	10	µF
f_{LCD}	LCD frequency range	$f_{FRAME} = 1/(2 \times mux) \times f_{LCD}$ with mux = 1 (static) to 8	0		1024	Hz
$f_{FRAME,4mux}$	LCD frame frequency range	$f_{FRAME,4mux}(MAX) = 1/(2 \times 4) \times f_{LCD}(MAX) = 1/(2 \times 4) \times 1024$ Hz			128	Hz
$f_{FRAME,8mux}$	LCD frame frequency range	$f_{FRAME,8mux}(MAX) = 1/(2 \times 4) \times f_{LCD}(MAX) = 1/(2 \times 8) \times 1024$ Hz			64	Hz
$f_{ACLK,in}$	ACLK input frequency range		30	32	40	kHz
C_{Panel}	Panel capacitance	100-Hz frame frequency			10000	pF
V_{R33}	Analog input voltage at R33	LCDCPEN = 0, VLCDEXT = 1	2.4		V_{CC} + 0.2	V
$V_{R23,1/3bias}$	Analog input voltage at R23	LCDREXT = 1, LCDEXTBIAS = 1, LCD2B = 0	V_{R13}	$V_{R03} + 2/3 \times (V_{R33}-V_{R03})$	V_{R33}	V
$V_{R13,1/3bias}$	Analog input voltage at R13 with 1/3 biasing	LCDREXT = 1, LCDEXTBIAS = 1, LCD2B = 0	V_{R03}	$V_{R03} + 1/3 \times (V_{R33}-V_{R03})$	V_{R23}	V
$V_{R13,1/2bias}$	Analog input voltage at R13 with 1/2 biasing	LCDREXT = 1, LCDEXTBIAS = 1, LCD2B = 1	V_{R03}	$V_{R03} + 1/2 \times (V_{R33}-V_{R03})$	V_{R33}	V
V_{R03}	Analog input voltage at R03	R0EXT = 1	V_{SS}			V
$V_{LCD}–V_{R03}$	Voltage difference between V_{LCD} and R03	LCDCPEN = 0, R0EXT = 1	2.4		V_{CC} + 0.2	V
$V_{LCDREF/R13}$	External LCD reference voltage applied at LCDREF/R13	VLCDREFx = 01	0.8	1.2	1.5	V

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Table 5-34 lists the characteristics of the LCD_C.

Table 5-34. LCD_C Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{LCD}	LCD voltage	VLCDx = 0000, VLCDEXT = 0	2.4 V to 3.6 V		V_{CC}		V
		LCDCPEN = 1, VLCDx = 0001	2 V to 3.6 V		2.58		
		LCDCPEN = 1, VLCDx = 0010	2 V to 3.6 V		2.64		
		LCDCPEN = 1, VLCDx = 0011	2 V to 3.6 V		2.71		
		LCDCPEN = 1, VLCDx = 0100	2 V to 3.6 V		2.78		
		LCDCPEN = 1, VLCDx = 0101	2 V to 3.6 V		2.83		
		LCDCPEN = 1, VLCDx = 0110	2 V to 3.6 V		2.90		
		LCDCPEN = 1, VLCDx = 0111	2 V to 3.6 V		2.96		
		LCDCPEN = 1, VLCDx = 1000	2 V to 3.6 V		3.02		
		LCDCPEN = 1, VLCDx = 1001	2 V to 3.6 V		3.07		
		LCDCPEN = 1, VLCDx = 1010	2 V to 3.6 V		3.14		
		LCDCPEN = 1, VLCDx = 1011	2 V to 3.6 V		3.21		
		LCDCPEN = 1, VLCDx = 1100	2 V to 3.6 V		3.27		
		LCDCPEN = 1, VLCDx = 1101	2.2 V to 3.6 V		3.32		
		LCDCPEN = 1, VLCDx = 1110	2.2 V to 3.6 V		3.38		
		LCDCPEN = 1, VLCDx = 1111	2.2 V to 3.6 V		3.44	3.6	
$I_{CC,Peak,CP}$	Peak supply currents due to charge pump activities	LCDCPEN = 1, VLCDx = 1111	2.2 V		400		µA
$t_{LCD,CP,on}$	Time to charge C_{LCD} when discharged	C_{LCD} = 4.7µF, LCDCPEN = 0→1, VLCDx = 1111	2.2 V		150	500	ms
$I_{CP,Load}$	Maximum charge pump load current	LCDCPEN = 1, VLCDx = 1111	2.2 V	50			µA
$R_{LCD,Seg}$	LCD driver output impedance, segment lines	LCDCPEN = 1, VLCDx = 1000, I_{LOAD} = ±10 µA	2.2 V			10	kΩ
$R_{LCD,COM}$	LCD driver output impedance, common lines	LCDCPEN = 1, VLCDx = 1000, I_{LOAD} = ±10 µA	2.2 V			10	kΩ

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5.15 SD24_B

Table 5-35 lists the power supply and recommended operating conditions of the SD24_B.

Table 5-35. SD24_B Power Supply and Recommended Operating Conditions

				MIN	TYP	MAX	UNIT
AV_{CC}	Analog supply voltage	$AV_{CC} = DV_{CC}$, $AV_{SS} = DV_{SS} = 0$ V		2.4		3.6	V
f_{SD}	Modulator clock frequency(1)			0.03		2.3	MHz
V_I	Absolute input voltage range			$AV_{SS} - 1$		AV_{CC}	V
V_{IC}	Common-mode input voltage range			$AV_{SS} - 1$		AV_{CC}	V
$V_{ID,FS}$	Differential full-scale input voltage	$V_{ID} = V_{I,A+} - V_{I,A-}$		$-V_{REF}$/GAIN		$+V_{REF}$/GAIN	mV
V_{ID}	Differential input voltage for specified performance(2)	SD24REFS = 1	SD24GAINx = 1	±910	±920		mV
			SD24GAINx = 2	±455	±460		
			SD24GAINx = 4	±227	±230		
			SD24GAINx = 8	±113	±115		
			SD24GAINx = 16	±57	±58		
			SD24GAINx = 32	±28	±29		
			SD24GAINx = 64	±14	±14.5		
			SD24GAINx = 128	±7	±7.2		
C_{REF}	VREF load capacitance(3)	SD24REFS = 1			100		nF

(1) Modulator clock frequency: MIN = 32.768 kHz – 10% ≈ 30 kHz. MAX = 32.768 kHz × 64 + 10% ≈ 2.3 MHz
(2) The full-scale range (FSR) is defined by $V_{FS+} = +V_{REF}/GAIN$ and $V_{FS-} = -V_{REF}/GAIN$: $FSR = V_{FS+} - V_{FS-} = 2 \times V_{REF} / GAIN$. If V_{REF} is sourced externally, the analog input range should not exceed 80% of V_{FS+} or V_{FS-}; that is, $V_{ID} = 0.8\ V_{FS-}$ to $0.8\ V_{FS+}$. If V_{REF} is sourced internally, the given V_{ID} ranges apply.
(3) There is no capacitance required on VREF. However, a capacitance of 100 nF is recommended to reduce any reference voltage noise.

Table 5-36 lists the analog input characteristics of the SD24_B.

Table 5-36. SD24_B Analog Input (1)

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
C_I	Input capacitance	SD24GAINx = 1				5		pF
		SD24GAINx = 2				5		
		SD24GAINx = 4				5		
		SD24GAINx = 8				5		
		SD24GAINx = 16				5		
		SD24GAINx = 32, 64, 128				5		
Z_I	Input impedance (Pin A+ or A- to AV_{SS})	f_{SD24} = 1 MHz	SD24GAINx = 1	3 V		200		kΩ
			SD24GAINx = 8	3 V		200		
			SD24GAINx = 32	3 V		200		
Z_{ID}	Differential input impedance (Pin A+ to pin A-)	f_{SD24} = 1 MHz	SD24GAINx = 1	3 V	300	400		kΩ
			SD24GAINx = 8	3 V		400		
			SD24GAINx = 32	3 V	300	400		

(1) All parameters pertain to each SD24_B converter.

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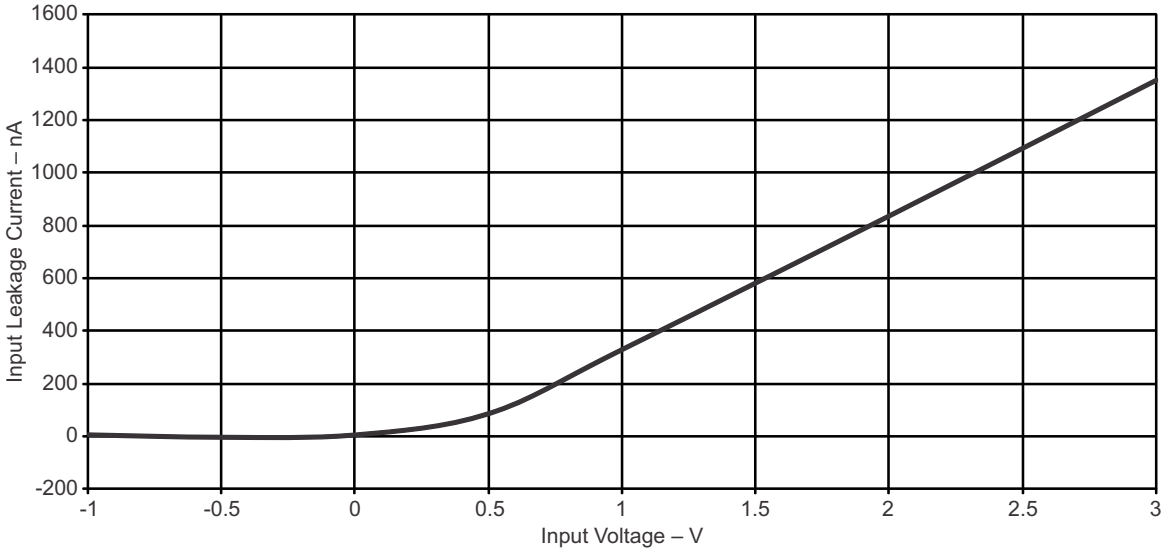


Figure 5-18. Input Leakage Current vs Input Voltage (Modulator OFF)

Table 5-37 lists the supply current of the SD24_B.

Table 5-37. SD24_B Supply Currents

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
$I_{SD,256}$	Analog plus digital supply current per converter (reference not included)	f_{SD24} = 1 MHz, SD24OSR = 256	SD24GAIN: 1	3 V		600	675	µA
			SD24GAIN: 2	3 V		600	675	
			SD24GAIN: 4	3 V		600	675	
			SD24GAIN: 8	3 V		700	750	
			SD24GAIN: 16	3 V		700	750	
			SD24GAIN: 32	3 V		775	850	
			SD24GAIN: 64	3 V		775	850	
			SD24GAIN: 128	3 V		775	850	
$I_{SD,512}$	Analog plus digital supply current per converter (reference not included)	f_{SD24} = 2 MHz, SD24OSR = 512	SD24GAIN: 1	3 V		750	800	µA
			SD24GAIN: 8	3 V		825	900	
			SD24GAIN: 32	3 V		900	1000	

Table 5-38 lists the performance characteristics of the SD24_B.

Table 5-38. SD24_B Performance

f_{SD24} = 1 MHz, SD24OSRx = 256, SD24REFS = 1

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
INL	Integral nonlinearity, end-point fit	SD24GAIN: 1	3 V	–0.01		0.01	% of FSR
		SD24GAIN: 8	3 V	–0.01		0.01	
		SD24GAIN: 32	3 V	–0.01		0.01	
G_{nom}	Nominal gain	SD24GAIN: 1	3 V		1		
		SD24GAIN: 2	3 V		2		
		SD24GAIN: 4	3 V		4		
		SD24GAIN: 8	3 V		8		
		SD24GAIN: 16	3 V		16		
		SD24GAIN: 32	3 V		31.7		
		SD24GAIN: 64	3 V		63.4		
		SD24GAIN: 128	3 V		126.8		

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Table 5-38. SD24_B Performance (continued)

f_{SD24} = 1 MHz, SD24OSRx = 256, SD24REFS = 1

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
E_G	Gain error (1)	SD24GAIN: 1, with external reference (1.2 V)	3 V	–1%		+1%	
		SD24GAIN: 8, with external reference (1.2 V)	3 V	–2%		+2%	
		SD24GAIN: 32, with external reference (1.2 V)	3 V	–2%		+2%	
$\Delta E_G/\Delta T$	Gain error temperature coefficient (2), internal reference	SD24GAIN: 1, 8, or 32 (with internal reference)	3 V			50	ppm/°C
$\Delta E_G/\Delta V_{CC}$	Gain error vs V_{CC} (3)	SD24GAIN: 1			0.15		%/V
		SD24GAIN: 8			0.15		
		SD24GAIN: 32			0.4		
E_{OS}[V]	Offset error (4)	SD24GAIN: 1 (with V_{diff} = 0 V)	3 V			2.3	mV
		SD24GAIN: 8	3 V			0.73	
		SD24GAIN: 32	3 V			0.18	
E_{OS}[FS]	Offset error (4)	SD24GAIN: 1 (with V_{diff} = 0 V)	3 V	–0.2		0.2	% FS
		SD24GAIN: 8	3 V	–0.5		0.5	
		SD24GAIN: 32	3 V	–0.5		0.5	
$\Delta E_{OS}/\Delta T$	Offset error temperature coefficient (5)	SD24GAIN: 1	3 V		1		µV/°C
		SD24GAIN: 8	3 V		0.15		
		SD24GAIN: 32	3 V		0.1		
$\Delta E_{OS}/\Delta V_{CC}$	Offset error vs V_{CC} (6)	SD24GAIN: 1			600		µV/V
		SD24GAIN: 8			100		
		SD24GAIN: 32			50		
CMRR,DC	Common-mode rejection at DC (7)	SD24GAIN: 1	3 V		–110		dB
		SD24GAIN: 8	3 V		–110		
		SD24GAIN: 32	3 V		–110		

(1) The gain error E_G specifies the deviation of the actual gain G_{act} from the nominal gain G_{nom}: $E_G = (G_{act} – G_{nom})/G_{nom}$. It covers process, temperature and supply voltage variations.

(2) The gain error temperature coefficient $\Delta E_G / \Delta T$ specifies the variation of the gain error E_G over temperature ($E_G(T) = (G_{act}(T) – G_{nom})/G_{nom}$) using the box method (that is, MIN and MAX values):
$\Delta E_G / \Delta T = (MAX(E_G(T)) – MIN(E_G(T)) / (MAX(T) – MIN(T)) = (MAX(G_{act}(T)) – MIN(G_{act}(T)) / G_{nom} / (MAX(T) – MIN(T))$
with T ranging from –40°C to +85°C.

(3) The gain error vs V_{CC} coefficient $\Delta E_G/ \Delta V_{CC}$ specifies the variation of the gain error E_G over supply voltage ($E_G(V_{CC}) = (G_{act}(V_{CC}) – G_{nom})/G_{nom}$) using the box method (that is, MIN and MAX values):
$\Delta E_G/ \Delta V_{CC} = (MAX(E_G(V_{CC})) – MIN(E_G(V_{CC})) / (MAX(V_{CC}) – MIN(V_{CC})) = (MAX(G_{act}(V_{CC})) – MIN(G_{act}(V_{CC})) / G_{nom} / (MAX(V_{CC}) – MIN(V_{CC}))$
with V_{CC} ranging from 2.4 V to 3.6 V.

(4) The offset error E_{OS} is measured with shorted inputs in 2s-complement mode with +100% FS = V_{REF} / G and –100% FS = $–V_{REF}$ / G. Conversion between E_{OS} [FS] and E_{OS} [V] is as follows: E_{OS} [FS] = E_{OS} [V]×G/V_{REF}; E_{OS} [V] = E_{OS} [FS]×V_{REF}/G.

(5) The offset error temperature coefficient $\Delta E_{OS} / \Delta T$ specifies the variation of the offset error E_{OS} over temperature using the box method (that is, MIN and MAX values):
$\Delta E_{OS} / \Delta T = (MAX(E_{OS}(T)) – MIN(E_{OS}(T)) / (MAX(T) – MIN(T))$
with T ranging from –40°C to +85°C.

(6) The offset error vs V_{CC} $\Delta E_{OS} / \Delta V_{CC}$ specifies the variation of the offset error E_{OS} over supply voltage using the box method (that is, MIN and MAX values):
$\Delta E_{OS} / \Delta V_{CC} = (MAX(E_{OS}(V_{CC})) – MIN(E_{OS}(V_{CC})) / (MAX(V_{CC}) – MIN(V_{CC}))$
with V_{CC} ranging from 2.4 V to 3.6 V.

(7) The DC CMRR specifies the change in the measured differential input voltage value when the common-mode voltage varies:
DC CMRR = $–20\log(\Delta_{MAX}/FSR)$ with Δ_{MAX} being the difference between the minium value and the maximum value measured when sweeping the common-mode voltage (for example, calculating with 16-bit FSR = 65536, a maximum change by 1 LSB results in $–20\log(1/65536) \approx –96$ dB) .
The DC CMRR is measured with both inputs connected to the common-mode voltage (that is, no differential input signal is applied), and the common-mode voltage is swept from –1 V to V_{CC}.

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Table 5-38. SD24_B Performance (continued)

f_{SD24} = 1 MHz, SD24OSRx = 256, SD24REFS = 1

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
CMRR,50Hz	Common-mode rejection at 50 Hz (8)	SD24GAIN: 1, f_{CM} = 50 Hz, V_{CM} = 930 mV	3 V		–110		dB
		SD24GAIN: 8, f_{CM} = 50 Hz, V_{CM} = 120 mV	3 V		–110		
		SD24GAIN: 32, f_{CM} = 50 Hz, V_{CM} = 30 mV	3 V		–110		
AC PSRR,ext	AC power supply rejection ratio, external reference (9)	SD24GAIN: 1, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–61		dB
		SD24GAIN: 8, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–77		
		SD24GAIN: 32, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–79		
AC PSRR,int	AC power supply rejection ratio, internal reference (9)	SD24GAIN: 1, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–61		dB
		SD24GAIN: 8, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–77		
		SD24GAIN: 32, V_{CC} = 3 V + 50 mV × sin(2π × f_{Vcc} × t), f_{Vcc} = 50 Hz			–79		
XT	Crosstalk between converters (10)	Crosstalk source: SD24GAIN: 1, Sine wave with maximum possible Vpp, f_{IN} = 50 Hz or 100 Hz, Converter under test: SD24GAIN: 1	3 V		–120		dB
		Crosstalk source: SD24GAIN: 1, Sine wave with maximum possible Vpp, f_{IN} = 50 Hz or 100 Hz, Converter under test: SD24GAIN: 8	3 V		–115		
		Crosstalk source: SD24GAIN: 1, Sine wave with maximum possible Vpp, f_{IN} = 50 Hz or 100 Hz, Converter under test: SD24GAIN: 32	3 V		–100		

(8) The AC CMRR is the difference between a hypothetical signal with the amplitude and frequency of the applied common-mode ripple applied to the inputs of the ADC and the actual common-mode signal spur visible in the FFT spectrum:
AC CMRR = Error Spur [dBFS] – 20log(V_{CM} / 1.2 V / G) [dBFS] with a common-mode signal of V_{CM} × sin(2π × f_{CM} × t) applied to the analog inputs.
The AC CMRR is measured with the both inputs connected to the common-mode signal (that is, no differential input signal is applied).
With the specified typical values the error spur is within the noise floor (as specified by the SINAD values).

(9) The AC PSRR is the difference between a hypothetical signal with the amplitude and frequency of the applied supply voltage ripple applied to the inputs of the ADC and the actual supply ripple spur visible in the FFT spectrum:
AC PSRR = Error Spur [dBFS] – 20log(50 mV / 1.2 V / G) [dBFS] with a signal of 50 mV × sin(2π × f_{Vcc} × t) added to V_{CC}.
The AC PSRR is measured with the inputs grounded (that is, no analog input signal is applied).
With the specified typical values the error spur is within the noise floor (as specified by the SINAD values).
SD24GAIN: 1 → Hypothetical signal: 20log(50 mV / 1.2 V / 1) = –27.6 dBFS
SD24GAIN: 8 → Hypothetical signal: 20log(50 mV / 1.2 V / 8) = –9.5 dBFS
SD24GAIN: 32 → Hypothetical signal: 20log(50 mV / 1.2 V / 32) = 2.5 dBFS

(10) The crosstalk (XT) is specified as the tone level of the signal applied to the crosstalk source seen in the spectrum of the converter under test. It is measured with the inputs of the converter under test being grounded.

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Table 5-39 lists the AC performance characteristics of the SD24_B.

Table 5-39. SD24_B AC Performance

f_{SD24} = 1 MHz, SD24OSRx = 256, SD24REFS = 1

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
SINAD	Signal-to-noise + distortion ratio	SD24GAIN: 1	f_{IN} = 50 Hz (1)	3 V	85	87		dB
		SD24GAIN: 2		3 V		86		
		SD24GAIN: 4		3 V		85		
		SD24GAIN: 8		3 V	82	84		
		SD24GAIN: 16		3 V		80		
		SD24GAIN: 32		3 V	73	74		
		SD24GAIN: 64		3 V		68		
		SD24GAIN: 128		3 V		62		
THD	Total harmonic distortion	SD24GAIN: 1	f_{IN} = 50 Hz (1)	3 V		100		dB
		SD24GAIN: 8		3 V		90		
		SD24GAIN: 32		3 V		80		

(1) The following voltages were applied to the SD24_B inputs:
$V_{I,A+}(t) = 0\ V + V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
$V_{I,A-}(t) = 0\ V - V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
resulting in a differential voltage of $V_{ID} = V_{I,A+}(t) - V_{I,A-}(t) = V_{PP} \times \sin(2\pi \times f_{IN} \times t)$ with V_{PP} being selected as the maximum value allowed for a given range (according to SD24_B recommended operating conditions).

Table 5-40 lists the AC performance characteristics of the SD24_B.

Table 5-40. SD24_B AC Performance

f_{SD24} = 2 MHz, SD24OSRx = 512, SD24REFS = 1

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
SINAD	Signal-to-noise + distortion ratio	SD24GAIN: 1	f_{IN} = 50 Hz (1)	3 V		87		dB
		SD24GAIN: 2		3 V		86		
		SD24GAIN: 4		3 V		85		
		SD24GAIN: 8		3 V		84		
		SD24GAIN: 16		3 V		81		
		SD24GAIN: 32		3 V		76		
		SD24GAIN: 64		3 V		71		
		SD24GAIN: 128		3 V		65		

(1) The following voltages were applied to the SD24_B inputs:
$V_{I,A+}(t) = 0\ V + V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
$V_{I,A-}(t) = 0\ V - V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
resulting in a differential voltage of $V_{ID} = V_{I,A+}(t) - V_{I,A-}(t) = V_{PP} \times \sin(2\pi \times f_{IN} \times t)$ with V_{PP} being selected as the maximum value allowed for a given range (according to SD24_B recommended operating conditions).

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Table 5-41 lists the AC performance characteristics of the SD24_B.

Table 5-41. SD24_B AC Performance

f_{SD24} = 32 kHz, SD24OSRx = 512, SD24REFS = 1

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP	MAX	UNIT
SINAD	Signal-to-noise + distortion ratio	SD24GAIN: 1	f_{IN} = 12 Hz (1)	3 V		89		dB
		SD24GAIN: 2		3 V		85		
		SD24GAIN: 4		3 V		84		
		SD24GAIN: 8		3 V		86		
		SD24GAIN: 16		3 V		80		
		SD24GAIN: 32		3 V		76		
		SD24GAIN: 64		3 V		67		
		SD24GAIN: 128		3 V		61		

(1) The following voltages were applied to the SD24_B inputs:
$V_{I,A+}(t) = 0\ V + V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
$V_{I,A-}(t) = 0\ V - V_{PP} / 2 \times \sin(2\pi \times f_{IN} \times t)$
resulting in a differential voltage of $V_{ID} = V_{I,A+}(t) - V_{I,A-}(t) = V_{PP} \times \sin(2\pi \times f_{IN} \times t)$ with V_{PP} being selected as the maximum value allowed for a given range (according to SD24_B recommended operating conditions).

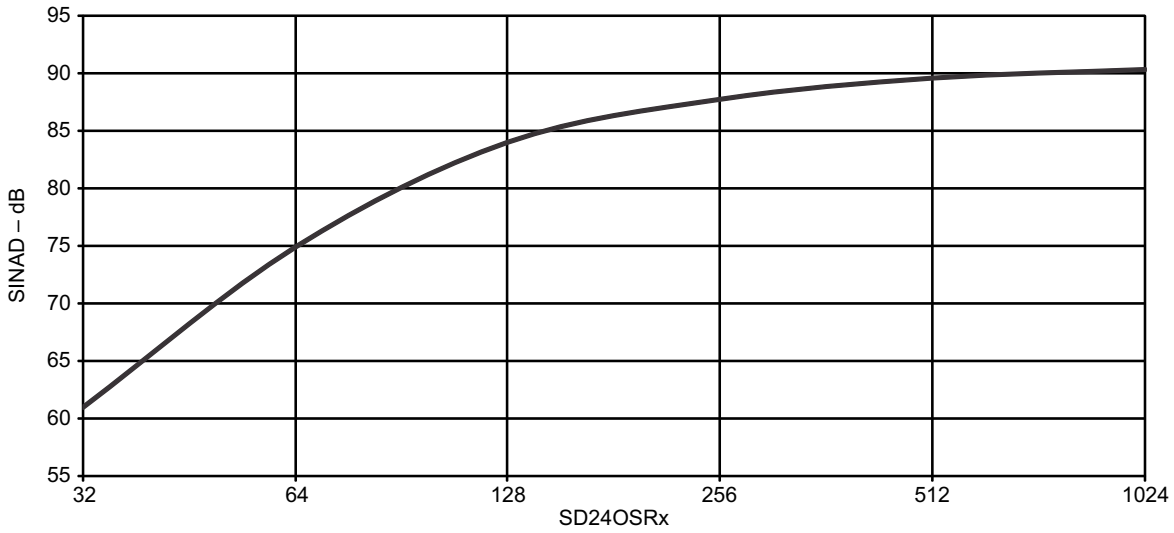


Figure 5-19. SINAD vs OSR
(f_{SD24} = 1 MHz, SD24REFS = 1, SD24GAIN = 1)

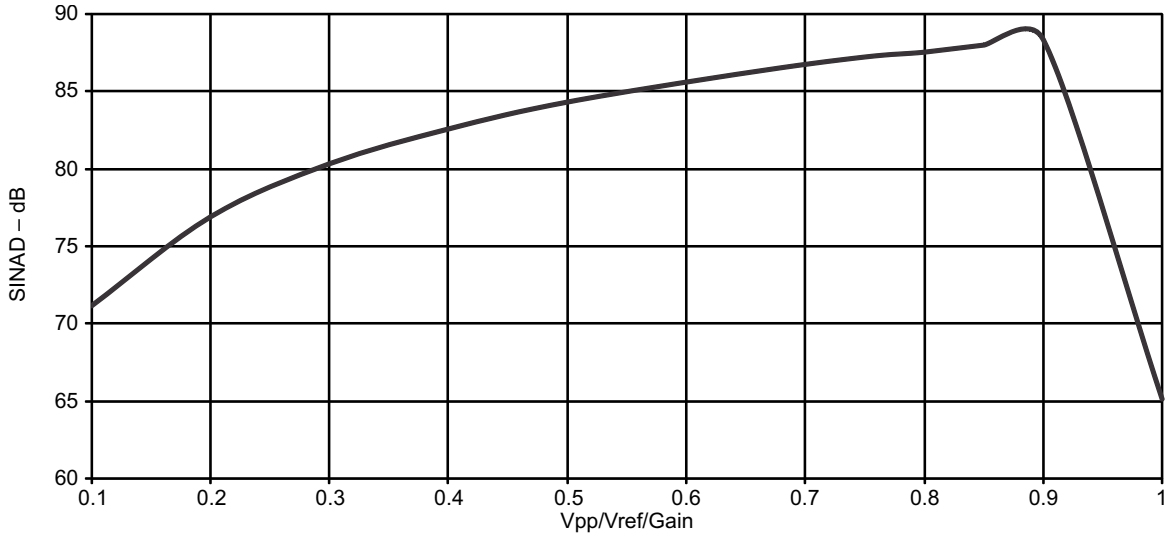


Figure 5-20. SINAD vs V_{PP}

Table 5-42 lists the external reference input requirements of the SD24_B.

Table 5-42. SD24_B External Reference Input

ensure correct input voltage range according to V_{REF}

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
$V_{REF(I)}$	Input voltage	SD24REFS = 0	3 V	1.0	1.20	1.5	V
$I_{REF(I)}$	Input current	SD24REFS = 0	3 V			50	nA

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5.16 ADC10_A

Table 5-43 lists the power supply and input range conditions of the ADC10_A.

Table 5-43. 10-Bit ADC, Power Supply and Input Range Conditions

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

			V_{CC}	MIN	TYP	MAX	UNIT
AV_{CC}	Analog supply voltage	AV_{CC} and DV_{CC} are connected together, AV_{SS} and DV_{SS} are connected together, $V_{(AVSS)} = V_{(DVSS)} = 0$ V		1.8		3.6	V
$V_{(Ax)}$	Analog input voltage range(1)	All ADC10_A pins		0		AV_{CC}	V
I_{ADC10_A}	Operating supply current into AVCC terminal, REF module and reference buffer off	$f_{ADC10CLK}$ = 5 MHz, ADC10ON =1, REFON = 0, SHT0 = 0, SHT1 = 0, ADC10DIV = 0, ADC10SREF = 00	2.2 V		70	105	µA
			3 V		80	115	
	Operating supply current into AVCC terminal, REF module on, reference buffer on	$f_{ADC10CLK}$ = 5 MHz, ADC10ON = 1, REFON = 1, SHT0 = 0, SHT1 = 0, ADC10DIV = 0, ADC10SREF = 01	3 V		130	185	
	Operating supply current into AVCC terminal, REF module off, reference buffer on	$f_{ADC10CLK}$ = 5 MHz, ADC10ON = 1, REFON = 0, SHT0 = 0, SHT1 = 0, ADC10DIV = 0, ADC10SREF = 10, VEREF = 2.5 V	3 V		108	160	
	Operating supply current into AVCC terminal, REF module off, reference buffer off	$f_{ADC10CLK}$ = 5 MHz, ADC10ON = 1, REFON = 0, SHT0 = 0, SHT1 = 0, ADC10DIV = 0, ADC10SREF = 11, VEREF = 2.5 V	3 V		74	105	
C_I	Input capacitance	Only one terminal Ax can be selected at one time from the pad to the ADC10_A capacitor array including wiring and pad.	2.2 V		3.5		pF
R_I	Input MUX ON resistance	AV_{CC} > 2 V, 0 V ≤ V_{Ax} ≤ AV_{CC}				36	kΩ
		1.8 V < AV_{CC} < 2 V, 0 V ≤ V_{Ax} ≤ AV_{CC}				96	

(1) The analog input voltage range must be within the selected reference voltage range V_{R+} to V_{R-} for valid conversion results. The external reference voltage requires decoupling capacitors. Two decoupling capacitors, 10 µF and 100 nF, should be connected to VREF to decouple the dynamic current required for an external reference source if it is used for the ADC10_A. Also see the *MSP430x5xx and MSP430x6xx Family User's Guide*.

Table 5-44 lists the timing parameters of the ADC10_A.

Table 5-44. 10-Bit ADC, Timing Parameters

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
$f_{ADC10CLK}$		For specified performance of ADC10_A linearity parameters	2.2 V, 3 V	0.45	5	5.5	MHz
$f_{ADC10OSC}$	Internal ADC10_A oscillator(1)	ADC10DIV = 0, $f_{ADC10CLK}$ = $f_{ADC10OSC}$	2.2 V, 3 V	4.4	5.0	5.6	MHz
$t_{CONVERT}$	Conversion time	REFON = 0, Internal oscillator, 12 ADC10CLK cycles, 10-bit mode $f_{ADC10OSC}$ = 4 MHz to 5 MHz	2.2 V, 3 V	2.4		3.0	µs
		External $f_{ADC10CLK}$ from ACLK, MCLK or SMCLK, ADC10SSEL ≠ 0			12 × 1 / $f_{ADC10CLK}$		
$t_{ADC10ON}$	Turnon settling time of the ADC	See (2)				100	ns
t_{Sample}	Sampling time	R_S = 1000 Ω, R_I = 96 kΩ, C_I = 3.5 pF(3)	1.8 V	3			µs
		R_S = 1000 Ω, R_I = 36 kΩ, C_I = 3.5 pF(3)	3 V	1			

(1) The ADC10OSC is sourced directly from MODOSC inside the UCS.
(2) The condition is that the error in a conversion started after $t_{ADC10ON}$ is less than ±0.5 LSB. The reference and input signal are already settled.
(3) Approximately ei8ght Tau (t) are needed to get an error of less than ±0.5 LSB

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Table 5-45. 10-Bit ADC, Linearity Parameters

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
E_I	Integral linearity error	1.4 V ≤ (V_{eREF+} – $V_{eREF–}$) ≤ 1.6 V, C_{VeREF+} = 20 pF	2.2 V, 3 V			±1.0	LSB
		1.6 V < (V_{eREF+} – $V_{eREF–}$) ≤ V_{AVCC}, C_{VeREF+} = 20 pF				±1.0	
E_D	Differential linearity error	1.4 V ≤ (V_{eREF+} – $V_{eREF–}$), C_{VeREF+} = 20 pF	2.2 V, 3 V			±1.0	LSB
E_O	Offset error	1.4 V ≤ (V_{eREF+} – $V_{eREF–}$), C_{VREF+} = 20 pF, Internal impedance of source R_S < 100 Ω	2.2 V, 3 V			±1.0	LSB
E_G	Gain error	1.4 V ≤ (V_{eREF+} – $V_{eREF–}$), C_{VeREF+} = 20 pF, ADC10SREFx = 11b	2.2 V, 3 V			±1.0	LSB
E_T	Total unadjusted error	1.4 V ≤ (V_{eREF+} – $V_{eREF–}$), C_{VeREF+} = 20 pF, ADC10SREFx = 11b	2.2 V, 3 V		±1.0	±2.0	LSB

Table 5-46 lists the external reference requirements of the ADC10_A.

Table 5-46. 10-Bit ADC, External Reference

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{eREF+}	Positive external reference voltage input	V_{eREF+} > $V_{eREF–}$ (2)		1.4		AV_{CC}	V
$V_{eREF–}$	Negative external reference voltage input	V_{eREF+} > $V_{eREF–}$ (3)		0		1.2	V
(V_{eREF+} – $V_{eREF–}$)	Differential external reference voltage input	V_{eREF+} > $V_{eREF–}$ (4)		1.4		AV_{CC}	V
I_{VeREF+}, $I_{VeREF–}$	Static input current	1.4 V ≤ V_{eREF+} ≤ V_{AVCC} , $V_{eREF–}$ = 0 V, $f_{ADC10CLK}$ = 5 MHz, ADC10SHTx = 0x0001, Conversion rate 200 ksps	2.2 V, 3 V		±8.5	±26	µA
		1.4 V ≤ V_{eREF+} ≤ V_{AVCC} , $V_{eREF–}$ = 0 V, $f_{ADC10CLK}$ = 5 MHz, ADC10SHTX = 0x1000, Conversion rate 20 ksps	2.2 V, 3 V			±1	µA
$C_{VeREF+/-}$	Capacitance at VeREF+ or VeREF- terminal	See (5)		10			µF

(1) The external reference is used during ADC conversion to charge and discharge the capacitance array. The input capacitance, C_I, is also the dynamic load for an external reference during conversion. The dynamic impedance of the reference supply should follow the recommendations on analog-source impedance to allow the charge to settle for 10-bit accuracy.
(2) The accuracy limits the minimum positive external reference voltage. Lower reference voltage levels may be applied with reduced accuracy requirements.
(3) The accuracy limits the maximum negative external reference voltage. Higher reference voltage levels may be applied with reduced accuracy requirements.
(4) The accuracy limits minimum external differential reference voltage. Lower differential reference voltage levels may be applied with reduced accuracy requirements.
(5) Two decoupling capacitors, 10 µF and 100 nF, should be connected to VeREF to decouple the dynamic current required for an external reference source if it is used for the ADC10_A. Also see the *MSP430x5xx and MSP430x6xx Family User's Guide*.

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5.17 REF

Table 5-47 lists the characteristics of the REF.

Table 5-47. REF, Built-In Reference

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{REF+}	Positive built-in reference voltage	REFVSEL = {2} for 2.5 V, REFON = 1	3 V	2.47	2.51	2.55	V
		REFVSEL = {1} for 2.0 V, REFON = 1	3 V	1.95	1.99	2.03	
		REFVSEL = {0} for 1.5 V, REFON = 1	2.2 V, 3 V	1.46	1.50	1.54	
$AV_{CC(min)}$	AVCC minimum voltage, Positive built-in reference active	REFVSEL = {0} for 1.5 V		1.8			V
		REFVSEL = {1} for 2.0 V		2.2			
		REFVSEL = {2} for 2.5 V		2.7			
I_{REF+}	Operating supply current into AVCC terminal (1)	$f_{ADC10CLK}$ = 5 MHz, REFON = 1, REFBURST = 0, REFVSEL = {2} for 2.5 V	3 V		23	30	µA
		$f_{ADC10CLK}$ = 5 MHz, REFON = 1, REFBURST = 0, REFVSEL = {1} for 2.0 V	3 V		21	27	
		$f_{ADC10CLK}$ = 5 MHz, REFON = 1, REFBURST = 0, REFVSEL = {0} for 1.5 V	3 V		19	25	
TC_{REF+}	Temperature coefficient of built-in reference (2)	REFVSEL = {0, 1, 2}, REFON = 1			10	50	ppm/°C
I_{SENSOR}	Operating supply current into AVCC terminal	REFON = 1, ADC10ON = 1, INCH = 0Ah, T_A = 30°C	2.2 V		145	220	µA
			3 V		170	245	
V_{SENSOR}	See (3)	REFON = 1, ADC10ON = 1, INCH = 0Ah, T_A = 30°C	2.2 V		780		mV
			3 V		780		
V_{MID}	AV_{CC} divider at channel 11	ADC10ON = 1, INCH = 0Bh, V_{MID} is ~0.5 × V_{AVCC}	2.2 V	1.08	1.1	1.12	V
			3 V	1.48	1.5	1.52	
$t_{SENSOR(sample)}$	Sample time required if channel 10 is selected (4)	REFON = 1, ADC10ON = 1, INCH = 0Ah, Error of conversion result ≤ 1 LSB		30			µs
$t_{VMID(sample)}$	Sample time required if channel 11 is selected (5)	ADC10ON = 1, INCH = 0Bh, Error of conversion result ≤ 1 LSB		1			µs
PSRR_DC	Power supply rejection ratio (DC)	AV_{CC} = $AV_{CC\ (min)}$ to $AV_{CC(max)}$, T_A = 25°C, REFVSEL = {0, 1, 2}, REFON = 1			120	300	µV/V
PSRR_AC	Power supply rejection ratio (AC)	AV_{CC} = $AV_{CC\ (min)}$ to $AV_{CC(max)}$, T_A = 25°C, f = 1 kHz, ΔVpp = 100 mV REFVSEL = {0, 1, 2}, REFON = 1			1		mV/V
t_{SETTLE}	Settling time of reference voltage (6)	AV_{CC} = $AV_{CC\ (min)}$ to $AV_{CC(max)}$, REFVSEL = {0, 1, 2}, REFON = 0→1			75		µs
$V_{SD24REF}$	SD24_B internal reference voltage	SD24REFS = 1	3 V	1.137	1.151	1.165	V
t_{ON}	SD24_B internal reference turnon time (7)	SD24REFS = 0→1, C_{REF} = 100 nF	3 V		200		µs

(1) The internal reference current is supplied through the AVCC terminal. Consumption is independent of the ADC10ON control bit, unless a conversion is active. The REFON bit enables to settle the built-in reference before starting an A/D conversion.
(2) Calculated using the box method: (MAX(–40°C to 85°C) – MIN(–40°C to 85°C)) / MIN(–40°C to 85°C)/(85°C – (–40°C)).
(3) The temperature sensor offset can be significant. TI recommends a single-point calibration to minimize the offset error of the built-in temperature sensor.
(4) The typical equivalent impedance of the sensor is 51 kΩ. The sample time required includes the sensor-on time $t_{SENSOR(on)}$.
(5) The on-time $t_{VMID(on)}$ is included in the sampling time $t_{VMID(sample)}$; no additional on time is needed.
(6) The condition is that the error in a conversion started after t_{REFON} is ≤ 1 LSB.
(7) The condition is that SD24_B conversion started after t_{ON} should guarantee specified SINAD values for the selected Gain, OSR and f_{SD24}.

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5.18 Flash Memory

Table 5-48 lists the characteristics of the flash memory.

Table 5-48. Flash Memory

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		T_J	MIN	TYP	MAX	UNIT
$DV_{CC(PGM/ERASE)}$	Program and erase supply voltage		1.8		3.6	V
I_{PGM}	Average supply current from DVCC during program			3	5	mA
I_{ERASE}	Average supply current from DVCC during erase			6	11	mA
I_{MERASE}, I_{BANK}	Average supply current from DVCC during mass erase or bank erase			6	11	mA
t_{CPT}	Cumulative program time(1)				16	ms
	Program and erase endurance		10^4	10^5		cycles
$t_{Retention}$	Data retention duration	25°C	100			years
t_{Word}	Word or byte program time(2)		64		85	µs
$t_{Block, 0}$	Block program time for first byte or word(2)		49		65	µs
$t_{Block, 1–(N–1)}$	Block program time for each additional byte or word, except for last byte or word(2)		37		49	µs
$t_{Block, N}$	Block program time for last byte or word(2)		55		73	µs
t_{Erase}	Erase time for segment erase, mass erase, and bank erase when available(2)		23		32	ms
$f_{MCLK,MGR}$	MCLK frequency in marginal read mode (FCTL4.MGR0 = 1 or FCTL4. MGR1 = 1)		0		1	MHz

(1) The cumulative program time must not be exceeded when writing to a 128-byte flash block. This parameter applies to all programming methods: individual word- or byte-write and block-write modes.
(2) These values are hardwired into the state machine of the flash controller.

5.19 Emulation and Debug

Table 5-49 lists the characteristics of the JTAG and Spy-Bi-Wire interface.

Table 5-49. JTAG and Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		V_{CC}	MIN	TYP	MAX	UNIT
f_{SBW}	Spy-Bi-Wire input frequency	2.2 V, 3 V	0		20	MHz
$t_{SBW,Low}$	Spy-Bi-Wire low clock pulse duration	2.2 V, 3 V	0.025		15	µs
$t_{SBW, En}$	Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge)(1)	2.2 V, 3 V			1	µs
$t_{SBW,Rst}$	Spy-Bi-Wire return to normal operation time		15		100	µs
f_{TCK}	TCK input frequency for 4-wire JTAG(2)	2.2 V	0		5	MHz
		3 V	0		10	
$R_{internal}$	Internal pulldown resistance on TEST	2.2 V, 3 V	45	60	80	kΩ

(1) Tools that access the Spy-Bi-Wire interface must wait for the minimum $t_{SBW,En}$ time after pulling the TEST/SBWTCK pin high before applying the first SBWTCK clock edge.
(2) f_{TCK} may be restricted to meet the timing requirements of the module selected.

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6 Detailed Description

6.1 CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock. Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator, respectively. The remaining registers are general-purpose registers (see 图 6-1).

Peripherals are connected to the CPU using data, address, and control buses. Peripherals can be managed with all instructions.

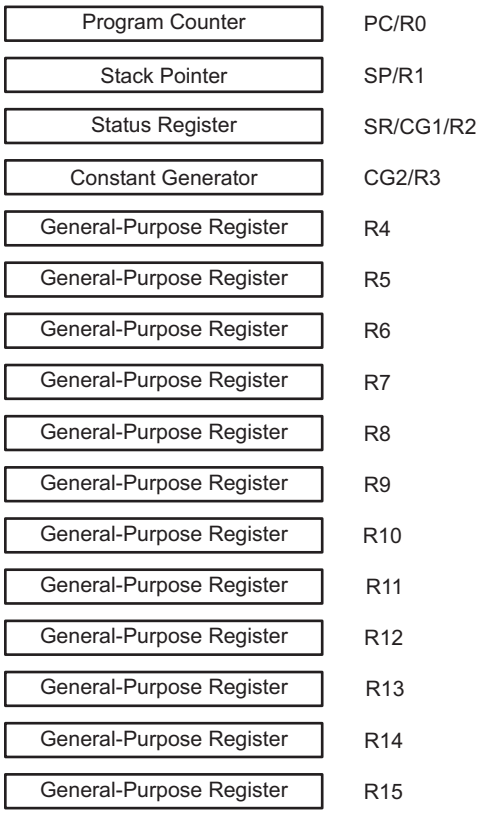


图 6-1. Integrated CPU Registers

6.2 Instruction Set

The instruction set consists of the original 51 instructions with three formats and seven address modes and additional instructions for the expanded address range. Each instruction can operate on word and byte data. 表 6-1 lists examples of the three types of instruction formats. 表 6-2 lists the address modes.

表 6-1. Instruction Word Formats

INSTRUCTION WORD FORMAT	EXAMPLE	OPERATION
Dual operands, source and destination	ADD R4,R5	R4 + R5 → R5
Single operands, destination only	CALL R8	PC → (TOS), R8 → PC
Relative jump, unconditional or conditional	JNE	Jump-on-equal bit = 0

表 6-2. Address Mode Descriptions

ADDRESS MODE	S(1)	D(1)	SYNTAX	EXAMPLE	OPERATION
Register	+	+	MOV Rs,Rd	MOV R10,R11	R10 → R11
Indexed	+	+	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5) → M(6+R6)
Symbolic (PC relative)	+	+	MOV EDE,TONI		M(EDE) → M(TONI)
Absolute	+	+	MOV & MEM, & TCDAT		M(MEM) → M(TCDAT)
Indirect	+		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10) → M(Tab+R6)
Indirect autoincrement	+		MOV @Rn+,Rm	MOV @R10+,R11	M(R10) → R11 R10 + 2 → R10
Immediate	+		MOV #X,TONI	MOV #45,TONI	#45 → M(TONI)

(1) S = source, D = destination

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6.3 Operating Modes

These microcontrollers have one active mode and seven software-selectable low-power modes of operation. An interrupt event can wake up the device from any of the low-power modes, service the request, and restore back to the low-power mode on return from the interrupt program.

Software can configure the following operating modes:

- Active mode (AM)
  - All clocks are active
- Low-power mode 0 (LPM0)
  - CPU is disabled
  - ACLK and SMCLK remain active, MCLK is disabled
  - FLL loop control remains active
- Low-power mode 1 (LPM1)
  - CPU is disabled
  - FLL loop control is disabled
  - ACLK and SMCLK remain active, MCLK is disabled
- Low-power mode 2 (LPM2)
  - CPU is disabled
  - MCLK and FLL loop control and DCOCLK are disabled
  - DC generator of the DCO remains enabled
  - ACLK remains active
- Low-power mode 3 (LPM3)
  - CPU is disabled
  - MCLK, FLL loop control, and DCOCLK are disabled
  - DC generator of the DCO is disabled
  - ACLK remains active
- Low-power mode 4 (LPM4)
  - CPU is disabled
  - ACLK is disabled
  - MCLK, FLL loop control, and DCOCLK are disabled
  - DC generator of the DCO is disabled
  - Crystal oscillator is stopped
  - Complete data retention
- Low-power mode 3.5 (LPM3.5)
  - Internal regulator disabled
  - No RAM retention, Backup RAM retained
  - I/O pad state retention
  - RTC clocked by low-frequency oscillator
  - Wake-up input from $\overline{\text{RST}}$/NMI, RTC_C events, Ports P1 and P2
- Low-power mode 4.5 (LPM4.5)
  - Internal regulator disabled
  - No RAM retention, Backup RAM retained
  - RTC is disabled
  - I/O pad state retention
  - Wake-up input from $\overline{\text{RST}}$/NMI, Ports P1 and P2

6.4 Interrupt Vector Addresses

The interrupt vectors and the power-up start address are in the address range 0FFFFh to 0FF80h (see 表 6-3). The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

表 6-3. Interrupt Sources, Flags, and Vectors of MSP430F67xx Configurations

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
System Reset Power up External reset Watchdog time-out, key violation Flash memory key violation	WDTIFG, KEYV (SYSRSTIV)(1)(2)	Reset	0FFFEh	63, highest
System NMI PMM Vacant memory access JTAG mailbox	SVMLIFG, SVMHIFG, DLYLIFG, DLYHIFG, VLRLIFG, VLRHIFG, VMAIFG, JMBNIFG, JMBOUTIFG (SYSSNIV) (1)(3)	(Non)maskable	0FFFCh	62
User NMI NMI Oscillator fault Flash memory access violation Supply switch	NMIIFG, OFIFG, ACCVIFG, AUXSWNMIFG (SYSUNIV)(1)(3)	(Non)maskable	0FFFAh	61
Watchdog Timer_A interval timer mode	WDTIFG	Maskable	0FFF8h	60
eUSCI_A0 receive or transmit	UCA0RXIFG, UCA0TXIFG (UCA0IV)(1)(4)	Maskable	0FFF6h	59
eUSCI_B0 receive or transmit	UCB0RXIFG, UCB0TXIFG (UCB0IV)(1)(4)	Maskable	0FFF4h	58
ADC10_A	ADC10IFG0, ADC10INIFG, ADC10LOIFG, ADC10HIIFG, ADC10TOVIFG, ADC10OVIFG (ADC10IV)(1)(4)	Maskable	0FFF2h	57
SD24_B	SD24_B Interrupt Flags (SD24IV)(1)(4)	Maskable	0FFF0h	56
Timer TA0	TA0CCR0 CCIFG0(4)	Maskable	0FFEEh	55
Timer TA0	TA0CCR1 CCIFG1, TA0CCR2 CCIFG2, TA0IFG (TA0IV)(1)(4)	Maskable	0FFECh	54
eUSCI_A1 receive or transmit	UCA1RXIFG, UCA1TXIFG (UCA1IV)(1)(4)	Maskable	0FFEAh	53
eUSCI_A2 receive or transmit	UCA2RXIFG, UCA2TXIFG (UCA2IV)(1)(4)	Maskable	0FFE8h	52
Auxiliary supplies	Auxiliary Supplies Interrupt Flags (AUXIV)(1)(4)	Maskable	0FFE6h	51
DMA	DMA0IFG, DMA1IFG, DMA2IFG (DMAIV)(1)(4)	Maskable	0FFE4h	50
Timer TA1	TA1CCR0 CCIFG0(4)	Maskable	0FFE2h	49
Timer TA1	TA1CCR1 CCIFG1, TA1IFG (TA1IV)(1)(4)	Maskable	0FFE0h	48
I/O port P1	P1IFG.0 to P1IFG.7 (P1IV)(1)(4)	Maskable	0FFDEh	47
Timer TA2	TA2CCR0 CCIFG0(4)	Maskable	0FFDCh	46
Timer TA2	TA2CCR1 CCIFG1, TA2IFG (TA2IV)(1)(4)	Maskable	0FFDAh	45
I/O port P2	P2IFG.0 to P2IFG.7 (P2IV)(1)(4)	Maskable	0FFD8h	44
Timer TA3	TA3CCR0 CCIFG0(4)	Maskable	0FFD6h	43
Timer TA3	TA3CCR1 CCIFG1, TA3IFG (TA3IV)(1)(4)	Maskable	0FFD4h	42
LCD_C	LCD_C Interrupt Flags (LCDCIV)(1)(4)	Maskable	0FFD2h	41
RTC_C	RTCOFIFG, RTCRDYIFG, RTCTEVIFG, RTCAIFG, RT0PSIFG, RT1PSIFG (RTCIV)(1)(4)	Maskable	0FFD0h	40

(1) Multiple source flags
(2) A reset is generated if the CPU tries to fetch instructions from within peripheral space or vacant memory space.
(3) (Non)maskable: the individual interrupt enable bit can disable an interrupt event, but the general interrupt enable bit cannot disable it.
(4) Interrupt flags are in the module.

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表 6-3. Interrupt Sources, Flags, and Vectors of MSP430F67xx Configurations (continued)

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Reserved	Reserved(5)		0FFCEh	39
			⋮	⋮
			0FF80h	0, lowest

(5) Reserved interrupt vectors at addresses are not used in this device and can be used for regular program code if necessary. To maintain compatibility with other devices, TI recommends reserving these locations.

6.5 Memory Organization

表 6-4 and 表 6-5 summarize the memory map for the devices.

表 6-4. Memory Organization

		MSP430F6730 MSP430F6720	MSP430F6731 MSP430F6721	MSP430F6733 MSP430F6723
Main Memory (flash)	Total Size	16KB	32KB	64KB
Main: Interrupt vector		00FFFFh to 00FF80h	00FFFFh to 00FF80h	00FFFFh to 00FF80h
Main: code memory	Bank 3	not available	not available	not available
	Bank 2	not available	not available	not available
	Bank 1	not available	16KB 00FFFFh to 00C000h	32KB 013FFFh to 00C000h
	Bank 0	16KB 00FFFFh to 00C000h	16KB 00BFFFh to 008000h	32KB 00BFFFh to 004000h
RAM	Total Size	1KB	2KB	4KB
	Sector 3	not available	not available	not available
	Sector 2	not available	not available	not available
	Sector 1	not available	not available	2KB 002BFFh to 002400h
	Sector 0	1KB 001FFFh to 001C00h	2KB 0023FFh to 001C00h	2KB 0023FFh to 001C00h
Information memory (flash)	Info A	128 B 0019FFh to 001980h	128 B 0019FFh to 001980h	128 B 0019FFh to 001980h
	Info B	128 B 00197Fh to 001900h	128 B 00197Fh to 001900h	128 B 00197Fh to 001900h
	Info C	128 B 0018FFh to 001880h	128 B 0018FFh to 001880h	128 B 0018FFh to 001880h
	Info D	128 B 00187Fh to 001800h	128 B 00187Fh to 001800h	128 B 00187Fh to 001800h
Bootloader (BSL) memory (flash)	BSL 3	512 B 0017FFh to 001600h	512 B 0017FFh to 001600h	512 B 0017FFh to 001600h
	BSL 2	512 B 0015FFh to 001400h	512 B 0015FFh to 001400h	512 B 0015FFh to 001400h
	BSL 1	512 B 0013FFh to 001200h	512 B 0013FFh to 001200h	512 B 0013FFh to 001200h
	BSL 0	512 B 0011FFh to 001000h	512 B 0011FFh to 001000h	512 B 0011FFh to 001000h
Peripherals		4KB 000FFFh to 0h	4KB 000FFFh to 0h	4KB 000FFFh to 0h

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表 6-5. Memory Organization

		MSP430F6734 MSP430F6724	MSP430F6735 MSP430F6725	MSP430F6736 MSP430F6726
Main Memory (flash)	Total Size	96KB	128KB	128KB
Main: Interrupt vector		00FFFFh to 00FF80h	00FFFFh to 00FF80h	00FFFFh to 00FF80h
Main: code memory	Bank 3	not available	32KB 023FFFh to 01C000h	32KB 023FFFh to 01C000h
	Bank 2	32KB 01BFFFh to 014000h	32KB 01BFFFh to 014000h	32KB 01BFFFh to 014000h
	Bank 1	32KB 013FFFh to 00C000h	32KB 013FFFh to 00C000h	32KB 013FFFh to 00C000h
	Bank 0	32KB 00BFFFh to 004000h	32KB 00BFFFh to 004000h	32KB 00BFFFh to 004000h
RAM	Total Size	4KB	4KB	8KB
	Sector 3	not available	not available	2KB 003BFFh to 003400h
	Sector 2	not available	not available	2KB 0033FFh to 002C00h
	Sector 1	2KB 002BFFh to 002400h	2KB 002BFFh to 002400h	2KB 002BFFh to 002400h
	Sector 0	2KB 0023FFh to 001C00h	2KB 0023FFh to 001C00h	2KB 0023FFh to 001C00h
Information memory (flash)	Info A	128 B 0019FFh to 001980h	128 B 0019FFh to 001980h	128 B 0019FFh to 001980h
	Info B	128 B 00197Fh to 001900h	128 B 00197Fh to 001900h	128 B 00197Fh to 001900h
	Info C	128 B 0018FFh to 001880h	128 B 0018FFh to 001880h	128 B 0018FFh to 001880h
	Info D	128 B 00187Fh to 001800h	128 B 00187Fh to 001800h	128 B 00187Fh to 001800h
Bootloader (BSL) memory (flash)	BSL 3	512 B 0017FFh to 001600h	512 B 0017FFh to 001600h	512 B 0017FFh to 001600h
	BSL 2	512 B 0015FFh to 001400h	512 B 0015FFh to 001400h	512 B 0015FFh to 001400h
	BSL 1	512 B 0013FFh to 001200h	512 B 0013FFh to 001200h	512 B 0013FFh to 001200h
	BSL 0	512 B 0011FFh to 001000h	512 B 0011FFh to 001000h	512 B 0011FFh to 001000h
Peripherals		4KB 000FFFh to 0h	4KB 000FFFh to 0h	4KB 000FFFh to 0h

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6.6 Bootloader (BSL)

The BSL enables users to program the flash memory or RAM using various serial interfaces. Access to the device memory through the BSL is protected by an user-defined password. BSL entry requires a specific entry sequence on the $\overline{\text{RST}}$/NMI/SBWTDIO and TEST/SBWTCK pins. For complete description of the features of the BSL and its implementation, see *MSP430™ Flash Device Bootloader (BSL) User's Guide*. 表 6-6 lists the BSL pin requirements.

表 6-6. UART BSL Pin Requirements and Functions

DEVICE SIGNAL	BSL FUNCTION
$\overline{\text{RST}}$/NMI/SBWTDIO	Entry sequence signal
TEST/SBWTCK	Entry sequence signal
P3.0	Data transmit
P3.1	Data receive
DVCC	Power supply
DVSS	Ground supply

6.7 JTAG Operation

6.7.1 JTAG Standard Interface

The MSP430 family supports the standard JTAG interface, which requires four signals for sending and receiving data. The JTAG signals are shared with general-purpose I/O. The TEST/SBWTCK pin is used to enable the JTAG signals. In addition to these signals, the $\overline{\text{RST}}$/NMI/SBWTDIO is required to interface with MSP430 development tools and device programmers. 表 6-7 lists the JTAG pin requirements. For further details on interfacing to development tools and device programmers, see the *MSP430 Hardware Tools User's Guide* and *MSP430 Programming With the JTAG Interface*.

表 6-7. JTAG Pin Requirements and Functions

DEVICE SIGNAL	DIRECTION	FUNCTION
PJ.3/ACLK/TCK	IN	JTAG clock input
PJ.2/ADC10CLK/TMS	IN	JTAG state control
PJ.1/MCLK/TDI/TCLK	IN	JTAG data input and TCLK input
PJ.0/SMCLK/TDO	OUT	JTAG data output
TEST/SBWTCK	IN	Enable JTAG pins
$\overline{\text{RST}}$/NMI/SBWTDIO	IN	External reset
DVCC		Power supply
DVSS		Ground supply

6.7.2 Spy-Bi-Wire Interface

In addition to the standard JTAG interface, the MSP430 family supports the 2-wire Spy-Bi-Wire interface. Spy-Bi-Wire can be used to interface with MSP430 development tools and device programmers. 表 6-8 lists the Spy-Bi-Wire interface pin requirements. For further details on interfacing to development tools and device programmers, see the *MSP430 Hardware Tools User's Guide* and *MSP430 Programming With the JTAG Interface*.

表 6-8. Spy-Bi-Wire Pin Requirements and Functions

DEVICE SIGNAL	DIRECTION	FUNCTION
TEST/SBWTCK	IN	Spy-Bi-Wire clock input
$\overline{\text{RST}}$/NMI/SBWTDIO	IN, OUT	Spy-Bi-Wire data input and output
DVCC		Power supply
DVSS		Ground supply

6.8 Flash Memory

The flash memory can be programmed through the JTAG port, Spy-Bi-Wire (SBW), the BSL, or in-system by the CPU. The CPU can perform single-byte, single-word, and long-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and four segments of information memory (A to D) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A to D can be erased individually, or as a group with segments 0 to n. Segments A to D are also called *information memory*.
- Segment A can be locked separately.

6.9 RAM

The RAM is made up of n sectors. Each sector can be completely powered down to save leakage; however, all data are lost. Features of the RAM include:

- RAM has n sectors of 2KB each.
- Each sector 0 to n can be complete disabled; however, data retention is lost.
- Each sector 0 to n automatically enters low-power retention mode when possible.

6.10 Backup RAM

The backup RAM provides a limited number of bytes of RAM that are retained during LPMx.5. This backup RAM is part of the Backup subsystem in MSP430F67xx that operates on dedicated power supply AUXVCC3. There are 8 bytes of backup RAM available in this device. The backup RAM can be word-wise accessed through the registers BAKMEM0, BAKMEM1, BAKMEM2, and BAKMEM3. The backup RAM registers cannot be accessed by the CPU when the high-side SVS is disabled by the user.

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6.11 Peripherals

Peripherals are connected to the CPU through data, address, and control buses. Peripherals can be managed using all instructions. For complete module descriptions, see the *MSP430x5xx and MSP430x6xx Family User's Guide*.

6.11.1 Oscillator and System Clock

The Unified Clock System (UCS) module includes support for a 32768-Hz watch crystal oscillator, an internal very-low-power low-frequency oscillator (VLO), an internal trimmed low-frequency oscillator (REFO), and an integrated internal digitally controlled oscillator (DCO). The UCS module is designed to meet the requirements of both low system cost and low power consumption. The UCS module features digital frequency-locked loop (FLL) hardware that, in conjunction with a digital modulator, stabilizes the DCO frequency to a programmable multiple of the selected FLL reference frequency. The internal DCO provides a fast turnon clock source and stabilizes in 3 µs (typical). The UCS module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal, the internal low-frequency oscillator (VLO), or the trimmed low-frequency oscillator (REFO).
- Main clock (MCLK), the system clock used by the CPU. MCLK can be sourced by same sources made available to ACLK.
- Sub-Main clock (SMCLK), the subsystem clock used by the peripheral modules. SMCLK can be sourced by same sources made available to ACLK.
- ACLK/n, the buffered output of ACLK, ACLK/2, ACLK/4, ACLK/8, ACLK/16, ACLK/32.

6.11.2 Power Management Module (PMM)

The PMM includes an integrated voltage regulator that supplies the core voltage to the device and contains programmable output levels to provide for power optimization. The PMM also includes supply voltage supervisor (SVS) and supply voltage monitor (SVM) circuitry, as well as brownout protection. The brownout circuit is implemented to provide the proper internal reset signal to the device during power on and power off. The SVS and SVM circuitry detects if the supply voltage drops below a user-selectable level and supports both supply voltage supervision (the device is automatically reset) and supply voltage monitoring (the device is not automatically reset). SVS and SVM circuitry is available on the primary supply and core supply.

6.11.3 Auxiliary Supply System

The auxiliary supply system provides the possibility to operate the device from auxiliary supplies when the primary supply fails.There are two auxililary supplies AUXVCC1 and AUXVCC2 supported in MSP430F67xx. This module supports automatic and manual switching from primary supply to auxiliary suppllies while maintaining full functionality. It allows threshold based monitoring of primary and auxiliary supplies. The device can be started from primary supply or from AUXVCC1, whichever is higher. The auxiliary supply system enables internal monitoring of voltage levels on the primary and auxiliary supplies using ADC10_A. This module also implements a simple charger for the backup supplies.

6.11.4 Backup Subsystem

The backup subsystem operates on a dedicated power supply, AUXVCC3. This subsystem includes low-frequency oscillator (XT1), RTC module, and backup RAM. The functionality of backup subsystem is retained during LPM3.5. The backup subsystem module registers cannot be accessed by CPU when the high-side SVS is disabled by the user. Keep the high-side SVS enabled (SVSHMD = 1 and SVSMHACE = 0) to turn off the low-frequency oscillator (XT1) in LPM4.

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6.11.5 Digital I/O

Up to nine 8-bit I/O ports are implemented. For 100-pin options, Ports P1 to P8 are complete, and P9 is reduced to 4-bit I/O. For 80-pin options, Ports P1 to P6 are complete, and P7, P8, and P9 are completely removed. Port PJ contains four individual I/O pins, common to all devices. All I/O bits are individually programmable.

- Any combination of input, output, and interrupt conditions is possible.
- Pullup or pulldown on all ports is programmable.
- Programmable drive strength on all ports.
- Edge-selectable interrupt and LPM3.5 or LPM4.5 wake-up input are available for all bits of ports P1 and P2.
- Read and write access to port-control registers is supported by all instructions.
- Ports can be accessed byte-wise (P1 through P9) or word-wise in pairs (PA through PE).

6.11.6 Port Mapping Controller

The port mapping controller allows flexible and reconfigurable mapping of digital functions to P1, P2, and P3 (see 表 6-9). 表 6-10 lists the default settings for all pins that support port mapping.

表 6-9. Port Mapping Mnemonics and Functions

VALUE	PxMAPy MNEMONIC	INPUT PIN FUNCTION	OUTPUT PIN FUNCTION
0	PM_NONE	None	DVSS
1	PM_UCA0RXD	eUSCI_A0 UART RXD (direction controlled by eUSCI – Input)	
	PM_UCA0SOMI	eUSCI_A0 SPI slave out master in (direction controlled by eUSCI)	
2	PM_UCA0TXD	eUSCI_A0 UART TXD (direction controlled by eUSCI – Output)	
	PM_UCA0SIMO	eUSCI_A0 SPI slave in master out (direction controlled by eUSCI)	
3	PM_UCA0CLK	eUSCI_A0 clock input/output (direction controlled by eUSCI)	
4	PM_UCA0STE	eUSCI_A0 SPI slave transmit enable (direction controlled by eUSCI)	
5	PM_UCA1RXD	eUSCI_A1 UART RXD (direction controlled by eUSCI – Input)	
	PM_UCA1SOMI	eUSCI_A1 SPI slave out master in (direction controlled by eUSCI)	
6	PM_UCA1TXD	eUSCI_A1 UART TXD (direction controlled by eUSCI – Output)	
	PM_UCA1SIMO	eUSCI_A1 SPI slave in master out (direction controlled by eUSCI)	
7	PM_UCA1CLK	eUSCI_A1 clock input/output (direction controlled by eUSCI)	
8	PM_UCA1STE	eUSCI_A1 SPI slave transmit enable (direction controlled by eUSCI)	
9	PM_UCA2RXD	eUSCI_A2 UART RXD (direction controlled by eUSCI – Input)	
	PM_UCA2SOMI	eUSCI_A2 SPI slave out master in (direction controlled by eUSCI)	
10	PM_UCA2TXD	eUSCI_A2 UART TXD (direction controlled by eUSCI – Output)	
	PM_ UCA2SIMO	eUSCI_A2 SPI slave in master out (direction controlled by eUSCI)	
11	PM_UCA2CLK	eUSCI_A2 clock input/output (direction controlled by eUSCI)	
12	PM_UCA2STE	eUSCI_A2 SPI slave transmit enable (direction controlled by eUSCI)	
13	PM_UCB0SIMO	eUSCI_B0 SPI slave in master out (direction controlled by eUSCI)	
	PM_UCB0SDA	eUSCI_B0 I2C data (open drain and direction controlled by eUSCI)	
14	PM_UCB0SOMI	eUSCI_B0 SPI slave out master in (direction controlled by eUSCI)	
	PM_UCB0SCL	eUSCI_B0 I2C clock (open drain and direction controlled by eUSCI)	
15	PM_UCB0CLK	eUSCI_B0 clock input/output (direction controlled by eUSCI)	
16	PM_UCB0STE	eUSCI_B0 SPI slave transmit enable (direction controlled by eUSCI)	
17	PM_TA0.0	TA0 CCR0 capture input CCI0A	TA0 CCR0 compare output Out0
18	PM_TA0.1	TA0 CCR1 capture input CCI1A	TA0 CCR1 compare output Out1
19	PM_TA0.2	TA0 CCR2 capture input CCI2A	TA0 CCR2 compare output Out2
20	PM_TA1.0	TA1 CCR0 capture input CCI0A	TA1 CCR0 compare output Out0
21	PM_TA1.1	TA1 CCR1 capture input CCI1A	TA1 CCR1 compare output Out1

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表 6-9. Port Mapping Mnemonics and Functions (continued)

VALUE	PxMAPy MNEMONIC	INPUT PIN FUNCTION	OUTPUT PIN FUNCTION
22	PM_TA2.0	TA2 CCR0 capture input CCI0A	TA2 CCR0 compare output Out0
23	PM_TA2.1	TA2 CCR1 capture input CCI1A	TA2 CCR1 compare output Out1
24	PM_TA3.0	TA3 CCR0 capture input CCI0A	TA3 CCR0 compare output Out0
25	PM_TA3.1	TA3 CCR1 capture input CCI1A	TA3 CCR1 compare output Out1
26	PM_TACLK	Timer_A clock input to TA0, TA1, TA2, TA3	None
	PM_RTCCLK	None	RTC_C clock output
27	PM_SDCLK	SD24_B bitstream clock input/output (direction controlled by SD24_B)	
28	PM_SD0DIO	SD24_B converter-0 bitstream data input/output (direction controlled by SD24_B)	
29	PM_SD1DIO	SD24_B converter-1 bitstream data input/output (direction controlled by SD24_B)	
30	PM_SD2DIO	SD24_B converter-2 bitstream data input/output (direction controlled by SD24_B)	
31 (0FFh)(1)	PM_ANALOG	Disables the output driver and the input Schmitt-trigger to prevent parasitic cross currents when applying analog signals.	

(1) The value of the PM_ANALOG mnemonic is set to 0FFh. The port mapping registers are only 5 bits wide, and the upper bits are ignored, which results in a read value of 31.

表 6-10. Default Mapping

PIN NAME		PxMAPy MNEMONIC	INPUT PIN FUNCTION	OUTPUT PIN FUNCTION
PZ	PN			
P1.0/PM_TA0.0/ VeREF-/A2	P1.0/PM_TA0.0/ VeREF-/A2	PM_TA0.0	TA0 CCR0 capture input CCI0A	TA0 CCR0 compare output Out0
P1.1/PM_TA0.1/ VeREF+/A1	P1.1/PM_TA0.1/ VeREF+/A1	PM_TA0.1	TA0 CCR1 capture input CCI1A	TA0 CCR1 compare output Out1
P1.2/PM_UCA0RXD/ PM_UCA0SOMI/A0	P1.2/PM_UCA0RXD/ PM_UCA0SOMI/A0	PM_UCA0RXD, PM_UCA0SOMI	eUSCI_A0 UART RXD (direction controlled by eUSCI – input), eUSCI_A0 SPI slave out master in (direction controlled by eUSCI)	
P1.3/PM_UCA0TXD/ PM_UCA0SIMO/R03	P1.3/PM_UCA0TXD/ PM_UCA0SIMO/R03	PM_UCA0TXD, PM_UCA0SIMO	eUSCI_A0 UART TXD (direction controlled by eUSCI – output), eUSCI_A0 SPI slave in master out (direction controlled by eUSCI)	
P1.4/PM_UCA1RXD/ PM_UCA1SOMI/ LCDREF/R13	P1.4/PM_UCA1RXD/ PM_UCA1SOMI/ LCDREF/R13	PM_UCA1RXD, PM_UCA1SOMI	eUSCI_A1 UART RXD (direction controlled by eUSCI – input), eUSCI_A1 SPI slave out master in (direction controlled by eUSCI)	
P1.5/PM_UCA1TXD/ PM_UCA1SIMO/R23	P1.5/PM_UCA1TXD/ PM_UCA1SIMO/R23	PM_UCA1TXD, PM_UCA1SIMO	eUSCI_A1 UART TXD (direction controlled by eUSCI – output), eUSCI_A1 SPI slave in master out (direction controlled by eUSCI)	
P1.6/PM_UCA0CLK/ COM4	P1.6/PM_UCA0CLK/ COM4	PM_UCA0CLK	eUSCI_A0 clock input/output (direction controlled by eUSCI)	
P1.7/PM_UCB0CLK/ COM5	P1.7/PM_UCB0CLK/ COM5	PM_UCB0CLK	eUSCI_B0 clock input/output (direction controlled by eUSCI)	
P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6	P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6/S39	PM_UCB0SOMI, PM_UCB0SCL	eUSCI_B0 SPI slave out master in (direction controlled by eUSCI), eUSCI_B0 I^2C clock (open drain and direction controlled by eUSCI)	
P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7	P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7/S38	PM_UCB0SIMO, PM_UCB0SDA	eUSCI_B0 SPI slave in master out (direction controlled by eUSCI), eUSCI_B0 I^2C data (open drain and direction controlled by eUSCI)	
P2.2/PM_UCA2RXD/ PM_UCA2SOMI	P2.2/PM_UCA2RXD/ PM_UCA2SOMI/S37	PM_UCA2RXD, PM_UCA2SOMI	eUSCI_A2 UART RXD (direction controlled by eUSCI – input), eUSCI_A2 SPI slave out master in (direction controlled by eUSCI)	
P2.3/PM_UCA2TXD/ PM_UCA2SIMO	P2.3/PM_UCA2TXD/ PM_UCA2SIMO/S36	PM_UCA2TXD, PM_UCA2SIMO	eUSCI_A2 UART TXD (direction controlled by eUSCI – output), eUSCI_A2 SPI slave in master out (direction controlled by eUSCI)	
P2.4/PM_UCA1CLK	P2.4/PM_UCA1CLK/S35	PM_UCA1CLK	eUSCI_A1 clock input/output (direction controlled by eUSCI)	

表 6-10. Default Mapping (continued)

PIN NAME		PxMAPy MNEMONIC	INPUT PIN FUNCTION	OUTPUT PIN FUNCTION
PZ	PN			
P2.5/PM_UCA2CLK	P2.5/PM_UCA2CLK/S34	PM_UCA2CLK	eUSCI_A2 clock input/output (direction controlled by eUSCI)	
P2.6/PM_TA1.0	P2.6/PM_TA1.0/S33	PM_TA1.0	TA1 CCR0 capture input CCI0A	TA1 CCR0 compare output Out0
P2.7/PM_TA1.1	P2.7/PM_TA1.1/S32	PM_TA1.1	TA1 CCR1 capture input CCI1A	TA1 CCR1 compare output Out1
P3.0/PM_TA2.0	P3.0/PM_TA2.0/S31	PM_TA2.0	TA2 CCR0 capture input CCI0A	TA2 CCR0 compare output Out0
P3.1/PM_TA2.1	P3.1/PM_TA2.1/S30	PM_TA2.1	TA2 CCR1 capture input CCI1A	TA2 CCR1 compare output Out1
P3.2/PM_TACLK/ PM_RTCCLK	P3.2/PM_TACLK/ PM_RTCCLK/S29	PM_TACLK, PM_RTCCLK	Timer_A clock input to TA0, TA1, TA2, TA3	RTC_C clock output
P3.3/PM_TA0.2	P3.3/PM_TA0.2/S28	PM_TA0.2	TA0 CCR2 capture input CCI2A	TA0 CCR2 compare output Out2
P3.4/PM_SDCLK/S39	P3.4/PM_SDCLK/S27	PM_SDCLK	SD24_B bitstream clock input/output (direction controlled by SD24_B)	
P3.5/PM_SD0DIO/S38	P3.5/PM_SD0DIO/S26	PM_SD0DIO	SD24_B converter-0 bitstream data input/output (direction controlled by SD24_B)	
P3.6/PM_SD1DIO/S37	P3.6/PM_SD1DIO/S25	PM_SD1DIO	SD24_B converter-1 bitstream data input/output (direction controlled by SD24_B)	
P3.7/PM_SD2DIO/S36	P3.7/PM_SD2DIO/S24	PM_SD2DIO	SD24_B converter-2 bitstream data input/output (direction controlled by SD24_B)	

6.11.7 System Module (SYS)

The SYS module handles many of the system functions within the device. These include power-on reset (POR) and power-up clear (PUC) handling, NMI source selection and management, reset interrupt vector generators, bootloader entry mechanisms, as well as, configuration management (device descriptors). It also includes a data exchange mechanism through JTAG called a JTAG mailbox that can be used in the application. 表 6-11 lists the SYS module interrupt vector registers.

表 6-11. System Module Interrupt Vector Registers

INTERRUPT VECTOR REGISTER	INTERRUPT EVENT	WORD ADDRESS	OFFSET	PRIORITY
SYSRSTIV, System Reset	No interrupt pending	019Eh	00h	
	Brownout (BOR)		02h	Highest
	RST/NMI (POR)		04h	
	DoBOR (BOR)		06h	
	Wakeup from LPMx.5 (BOR)		08h	
	Security violation (BOR)		0Ah	
	SVSL (POR)		0Ch	
	SVSH (POR)		0Eh	
	SVML_OVP (POR)		10h	
	SVMH_OVP (POR)		12h	
	DoPOR (POR)		14h	
	WDT time-out (PUC)		16h	
	WDT key violation (PUC)		18h	
	KEYV flash key violation (PUC)		1Ah	
	Reserved		1Ch	
	Peripheral area fetch (PUC)		1Eh	
	PMM key violation (PUC)		20h	
	Reserved		22h to 3Eh	Lowest

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表 6-11. System Module Interrupt Vector Registers (continued)

INTERRUPT VECTOR REGISTER	INTERRUPT EVENT	WORD ADDRESS	OFFSET	PRIORITY
SYSSNIV, System NMI	No interrupt pending	019Ch	00h	
	SVMLIFG		02h	Highest
	SVMHIFG		04h	
	DLYLIFG		06h	
	DLYHIFG		08h	
	VMAIFG		0Ah	
	JMBINIFG		0Ch	
	JMBOUTIFG		0Eh	
	VLRLIFG		10h	
	VLRHIFG		12h	
	Reserved		14h to 1Eh	Lowest
SYSUNIV, User NMI	No interrupt pending	019Ah	00h	
	NMIIFG		02h	Highest
	OFIFG		04h	
	ACCVIFG		06h	
	AUXSWNMIFG		08h	
	Reserved		0Ah to 1Eh	Lowest

6.11.8 Watchdog Timer (WDT_A)

The primary function of the WDT_A module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the timer can be configured as an interval timer and can generate interrupts at selected time intervals.

6.11.9 DMA Controller

The DMA controller allows movement of data from one memory address to another without CPU intervention. For example, the DMA controller can be used to move data from the ADC10_A conversion memory to RAM. Using the DMA controller can increase the throughput of peripheral modules. The DMA controller reduces system power consumption by allowing the CPU to remain in sleep mode, without having to awaken to move data to or from a peripheral. 表 6-12 lists the triggers that are available to start DMA transfer.

表 6-12. DMA Trigger Assignments(1)

TRIGGER	CHANNEL		
	0	1	2
0	DMAREQ		
1	TA0CCR0 CCIFG		
2	TA0CCR2 CCIFG		
3	TA1CCR0 CCIFG		
4	Reserved		
5	TA2CCR0 CCIFG		
6	Reserved		
7	TA3CCR0 CCIFG		
8	Reserved		

(1) Reserved DMA triggers may be used by other devices in the family. Reserved DMA triggers do not cause a DMA trigger event when selected.

表 6-12. DMA Trigger Assignments[1] (continued)

TRIGGER	CHANNEL		
	0	1	2
9	Reserved		
10	Reserved		
11	Reserved		
12	Reserved		
13	SD24IFG		
14	Reserved		
15	Reserved		
16	UCA0RXIFG		
17	UCA0TXIFG		
18	UCA1RXIFG		
19	UCA1TXIFG		
20	UCA2RXIFG		
21	UCA2TXIFG		
22	UCB0RXIFG0		
23	UCB0TXIFG0		
24	ADC10IFG0		
25	Reserved		
26	Reserved		
27	Reserved		
28	Reserved		
29	MPY ready		
30	DMA2IFG	DMA0IFG	DMA1IFG
31	Reserved		

6.11.10 CRC16

The CRC16 module produces a signature based on a sequence of entered data values and can be used for data checking purposes. The CRC16 module signature is based on the CRC-CCITT standard.

6.11.11 Hardware Multiplier

The multiplication operation is supported by a dedicated peripheral module. The module performs operations with 32-, 24-, 16-, and 8-bit operands. The module supports signed and unsigned multiplication as well as signed and unsigned multiply-and-accumulate operations.

6.11.12 Enhanced Universal Serial Communication Interface (eUSCI)

The eUSCI module is used for serial data communication. The eUSCI module supports synchronous communication protocols such as SPI (3- or 4-pin) and I^2C, and asynchronous communication protocols such as UART, enhanced UART with automatic baudrate detection, and IrDA.

The eUSCI_An module supports for SPI (3- or 4-pin), UART, enhanced UART, or IrDA.

The eUSCI_Bn module supports for SPI (3- or 4-pin) or I^2C.

Three eUSCI_A and one eUSCI_B modules are implemented in MSP430F67xx devices.

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6.11.13 ADC10_A

The ADC10_A module supports fast 10-bit analog-to-digital conversions. The module implements a 10-bit SAR core, sample select control, reference generator, and a conversion results buffer. A window comparator with a lower and upper limits allows CPU-independent result monitoring with three window comparator interrupt flags.

6.11.14 SD24_B

The SD24_B module integrates up to three independent 24-bit sigma-delta analog-to-digital converters. Each converter is designed with a fully differential analog input pair and programmable gain amplifier input stage. The converters are based on second-order over-sampling sigma-delta modulators and digital decimation filters. The decimation filters are comb type filters with selectable oversampling ratios of up to 1024.

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6.11.15 TA0

TA0 is a 16-bit timer/counter (Timer_A type) with three capture/compare registers. TA0 can support multiple capture/compares, PWM outputs, and interval timing (see 表 6-13). TA0 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

表 6-13. TA0 Signal Connections

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
PM_TACLK	TACLK	Timer	NA	NA
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
PM_TACLK	INCLK			
PM_TA0.0	CCI0A	CCR0	TA0	PM_TA0.0
DVSS	CCI0B			
DVSS	GND			
DVCC	VCC			
PM_TA0.1	CCI1A	CCR1	TA1	PM_TA0.1
ACLK (internal)	CCI1B			ADC10_A (internal) ADC10SHSx = {1}
DVSS	GND			SD24_B (internal) SD24SCSx = {1}
DVCC	VCC			
PM_TA0.2	CCI2A	CCR2	TA2	PM_TA0.2
DVSS	CCI2B			
DVSS	GND			
DVCC	VCC			

6.11.16 TA1

TA1 is a 16-bit timer/counter (Timer_A type) with two capture/compare registers. TA1 can support multiple capture/compares, PWM outputs, and interval timing (see 表 6-14). TA1 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

表 6-14. TA1 Signal Connections

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
				PZ
PM_TACLK	TACLK	Timer	NA	NA
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
PM_TACLK	INCLK			
PM_TA1.0	CCI0A	CCR0	TA0	PM_TA1.0
DVSS	CCI0B			
DVSS	GND			
DVCC	VCC			
PM_TA1.1	CCI1A	CCR1	TA1	PM_TA1.1
ACLK (internal)	CCI1B			
DVSS	GND			
DVCC	VCC			

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6.11.17 TA2

TA2 is a 16-bit timer/counter (Timer_A type) with two capture/compare registers. TA2 can support multiple capture/compares, PWM outputs, and interval timing (see 表 6-15). TA2 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

表 6-15. TA2 Signal Connections

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
PM_TACLK	TACLK	Timer	NA	NA
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
PM_TACLK	INCLK			
PM_TA2.0	CCI0A	CCR0	TA0	PM_TA2.0
DVSS	CCI0B			
DVSS	GND			
DVCC	VCC			
PM_TA2.1	CCI1A	CCR1	TA1	PM_TA2.1
ACLK (internal)	CCI1B			SD24_B (internal) SD24SCSx = {2}
DVSS	GND			
DVCC	VCC			

6.11.18 TA3

TA3 is a 16-bit timer/counter (Timer_A type) with two capture/compare registers. TA3 can support multiple capture/compares, PWM outputs, and interval timing (see 表 6-16). TA3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

表 6-16. TA3 Signal Connections

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
PM_TACLK	TACLK	Timer	NA	
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
PM_TACLK	INCLK			
PM_TA3.0	CCI0A	CCR0	TA0	PM_TA3.0
DVSS	CCI0B			ADC10_A (internal) ADC10SHSx = {2}
DVSS	GND			
DVCC	VCC			
PM_TA3.1	CCI1A	CCR1	TA1	PM_TA3.1
ACLK (internal)	CCI1B			SD24_B (internal) SD24SCSx = {3}
DVSS	GND			
DVCC	VCC			

6.11.19 SD24_B Triggers

表 6-17 lists the input trigger connections to SD24_B converters from Timer_A modules and output trigger pulse connection from SD24_B to ADC10_A.

表 6-17. SD24_B Input/Output Trigger Connections

DEVICE INPUT SIGNAL	MODULE INPUT SIGNAL	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
TA0.1 (internal)	SD24_B SD24SCSx = {1}	SD24_B	Trigger Pulse	ADC10_A (internal) ADC10SHSx = {3}
TA2.1 (internal)	SD24_B SD24SCSx = {2}			
TA3.1 (internal)	SD24_B SD24SCSx = {3}			

6.11.20 ADC10_A Triggers

表 6-18 lists the input trigger connections to ADC10_A from Timer_A modules and SD24_B.

表 6-18. ADC10_A Input Trigger Connections

DEVICE INPUT SIGNAL	MODULE INPUT SIGNAL	MODULE BLOCK
TA0.1 (internal)	ADC10_A ADC10SHSx = {1}	ADC10_A
TA3.0 (internal)	ADC10_A ADC10SHSx = {2}	
SD24_B trigger pulse (internal)	ADC10_A ADC10SHSx = {3}	

6.11.21 Real-Time Clock (RTC_C)

The RTC_C module can be configured for calendar mode providing seconds, hours, day of week, day of month, month, and year. The RTC_C control and configuration registers are password protected to ensure clock integrity against runaway code. Calendar mode integrates an internal calendar that compensates for months with less than 31 days and includes leap year correction. The RTC_C also supports flexible alarm functions, offset calibration, and temperature compensation. The RTC_C on this device operates on dedicated AUXVCC3 supply and supports operation in LPM3.5.

6.11.22 Reference (REF) Module Voltage Reference

The REF module generates all critical reference voltages that can be used by the various analog peripherals in the device. These include the ADC10_A, LCD_C, and SD24_B modules.

6.11.23 LCD_C

The LCD_C driver generates the segment and common signals required to drive a liquid crystal display (LCD). The LCD_C controller has dedicated data memories to hold segment drive information. Common and segment signals are generated as defined by the mode. Static, 2-mux, 3-mux, 4-mux, up to 8-mux LCDs are supported. The module can provide a LCD voltage independent of the supply voltage with its integrated charge pump. It is possible to control the level of the LCD voltage, and thus contrast, by software. The module also provides an automatic blinking capability for individual segments in static, 2-mux, 3-mux, and 4-mux modes.

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6.11.24 Embedded Emulation Module (EEM) (S Version)

The EEM supports real-time in-system debugging. The S version of the EEM has the following features:

- Three hardware triggers or breakpoints on memory access
- One hardware trigger or breakpoint on CPU register write access
- Up to four hardware triggers can be combined to form complex triggers or breakpoints
- One cycle counter
- Clock control on module level

6.11.25 Peripheral File Map

表 6-19 lists the base address for the registers of each supported peripheral.

表 6-19. Peripherals

MODULE NAME	BASE ADDRESS	OFFSET ADDRESS RANGE
Special Functions (see 表 6-20)	0100h	000h to 01Fh
PMM (see 表 6-21)	0120h	000h to 01Fh
Flash Control (see 表 6-22)	0140h	000h to 00Fh
CRC16 (see 表 6-23)	0150h	000h to 007h
RAM Control (see 表 6-24)	0158h	000h to 001h
Watchdog (see 表 6-25)	015Ch	000h to 001h
UCS (see 表 6-26)	0160h	000h to 01Fh
SYS (see 表 6-27)	0180h	000h to 01Fh
Shared Reference (see 表 6-28)	01B0h	000h to 001h
Port Mapping Control (see 表 6-29)	01C0h	000h to 007h
Port Mapping Port P1 (see 表 6-30)	01C8h	000h to 007h
Port Mapping Port P2 (see 表 6-31)	01D0h	000h to 007h
Port Mapping Port P3 (see 表 6-32)	01D8h	000h to 007h
Port P1 and P2 (see 表 6-33)	0200h	000h to 01Fh
Port P3 and P4 (see 表 6-34)	0220h	000h to 00Bh
Port P5 and P6 (see 表 6-35)	0240h	000h to 00Bh
Port P7 and P8 (see 表 6-36) (Port P7 and P8 not available in MSP430F67xxIPN)	0260h	000h to 00Bh
Port P9 (Port P9 not available in MSP430F67xxIPN) (see 表 6-37)	0280h	000h to 00Bh
Port PJ (refer to表 6-38)	0320h	000h to 01Fh
Timer TA0 (see 表 6-39)	0340h	000h to 03Fh
Timer TA1 (see 表 6-40)	0380h	000h to 03Fh
Timer TA2 (see 表 6-41)	0400h	000h to 03Fh
Timer TA3 (see 表 6-42)	0440h	000h to 03Fh
Backup Memory (see 表 6-43)	0480h	000h to 00Fh
RTC_C (see 表 6-44)	04A0h	000h to 01Fh
32-Bit Hardware Multiplier (see 表 6-45)	04C0h	000h to 02Fh
DMA General Control (see 表 6-46)	0500h	000h to 00Fh
DMA Channel 0 (see 表 6-47)	0500h	010h to 01Fh
DMA Channel 1 (see 表 6-48)	0500h	020h to 02Fh
DMA Channel 2 (see 表 6-49)	0500h	030h to 03Fh
eUSCI_A0 (see 表 6-50)	05C0h	000h to 01Fh
eUSCI_A1 (see 表 6-51)	05E0h	000h to 01Fh
eUSCI_A2 (see 表 6-52)	0600h	000h to 01Fh
eUSCI_B0 (see 表 6-53)	0640h	000h to 02Fh
ADC10_A (see 表 6-54)	0740h	000h to 01Fh
SD24_B(see 表 6-55)	0800h	000h to 06Fh
Auxiliary Supply (see 表 6-49)	09E0h	000h to 01Fh
LCD_C (see 表 6-57)	0A00h	000h to 05Fh

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表 6-20. Special Function Registers (Base Address: 0100h)

REGISTER DESCRIPTION	REGISTER	OFFSET
SFR interrupt enable	SFRIE1	00h
SFR interrupt flag	SFRIFG1	02h
SFR reset pin control	SFRRPCR	04h

表 6-21. PMM Registers (Base Address: 0120h)

REGISTER DESCRIPTION	REGISTER	OFFSET
PMM control 0	PMMCTL0	00h
PMM control 1	PMMCTL1	02h
SVS high-side control	SVSMHCTL	04h
SVS low-side control	SVSMLCTL	06h
PMM interrupt flags	PMMIFG	0Ch
PMM interrupt enable	PMMIE	0Eh
PMM power mode 5 control 0	PM5CTL0	10h

表 6-22. Flash Control Registers (Base Address: 0140h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Flash control 1	FCTL1	00h
Flash control 3	FCTL3	04h
Flash control 4	FCTL4	06h

表 6-23. CRC16 Registers (Base Address: 0150h)

REGISTER DESCRIPTION	REGISTER	OFFSET
CRC data input	CRC16DI	00h
CRC data input reverse byte	CRC16DIRB	02h
CRC result	CRCINIRES	04h
CRC result reverse byte	CRCRESR	06h

表 6-24. RAM Control Registers (Base Address: 0158h)

REGISTER DESCRIPTION	REGISTER	OFFSET
RAM control 0	RCCTL0	00h

表 6-25. Watchdog Registers (Base Address: 015Ch)

REGISTER DESCRIPTION	REGISTER	OFFSET
Watchdog timer control	WDTCTL	00h

表 6-26. UCS Registers (Base Address: 0160h)

REGISTER DESCRIPTION	REGISTER	OFFSET
UCS control 0	UCSCTL0	00h
UCS control 1	UCSCTL1	02h
UCS control 2	UCSCTL2	04h
UCS control 3	UCSCTL3	06h
UCS control 4	UCSCTL4	08h
UCS control 5	UCSCTL5	0Ah
UCS control 6	UCSCTL6	0Ch
UCS control 7	UCSCTL7	0Eh

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表 6-26. UCS Registers (Base Address: 0160h) (continued)

REGISTER DESCRIPTION	REGISTER	OFFSET
UCS control 8	UCSCTL8	10h

表 6-27. SYS Registers (Base Address: 0180h)

REGISTER DESCRIPTION	REGISTER	OFFSET
System control	SYSCTL	00h
Bootloader configuration area	SYSBSLC	02h
JTAG mailbox control	SYSJMBC	06h
JTAG mailbox input 0	SYSJMBI0	08h
JTAG mailbox input 1	SYSJMBI1	0Ah
JTAG mailbox output 0	SYSJMBO0	0Ch
JTAG mailbox output 1	SYSJMBO1	0Eh
Bus error vector generator	SYSBERRIV	18h
User NMI vector generator	SYSUNIV	1Ah
System NMI vector generator	SYSSNIV	1Ch
Reset vector generator	SYSRSTIV	1Eh

表 6-28. Shared Reference Registers (Base Address: 01B0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Shared reference control	REFCTL	00h

表 6-29. Port Mapping Controller (Base Address: 01C0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port mapping password	PMAPPWD	00h
Port mapping control	PMAPCTL	02h

表 6-30. Port Mapping for Port P1 (Base Address: 01C8h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P1.0 mapping	P1MAP0	00h
Port P1.1 mapping	P1MAP1	01h
Port P1.2 mapping	P1MAP2	02h
Port P1.3 mapping	P1MAP3	03h
Port P1.4 mapping	P1MAP4	04h
Port P1.5 mapping	P1MAP5	05h
Port P1.6 mapping	P1MAP6	06h
Port P1.7 mapping	P1MAP7	07h

表 6-31. Port Mapping for Port P2 (Base Address: 01D0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P2.0 mapping	P2MAP0	00h
Port P2.1 mapping	P2MAP2	01h
Port P2.2 mapping	P2MAP2	02h
Port P2.3 mapping	P2MAP3	03h
Port P2.4 mapping	P2MAP4	04h
Port P2.5 mapping	P2MAP5	05h
Port P2.6 mapping	P2MAP6	06h
Port P2.7 mapping	P2MAP7	07h

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表 6-32. Port Mapping for Port P3 (Base Address: 01D8h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P3.0 mapping	P3MAP0	00h
Port P3.1 mapping	P3MAP3	01h
Port P3.2 mapping	P3MAP2	02h
Port P3.3 mapping	P3MAP3	03h
Port P3.4 mapping	P3MAP4	04h
Port P3.5 mapping	P3MAP5	05h
Port P3.6 mapping	P3MAP6	06h
Port P3.7 mapping	P3MAP7	07h

表 6-33. Port P1 and P2 Registers (Base Address: 0200h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P1 input	P1IN	00h
Port P1 output	P1OUT	02h
Port P1 direction	P1DIR	04h
Port P1 resistor enable	P1REN	06h
Port P1 drive strength	P1DS	08h
Port P1 selection	P1SEL	0Ah
Port P1 interrupt vector word	P1IV	0Eh
Port P1 interrupt edge select	P1IES	18h
Port P1 interrupt enable	P1IE	1Ah
Port P1 interrupt flag	P1IFG	1Ch
Port P2 input	P2IN	01h
Port P2 output	P2OUT	03h
Port P2 direction	P2DIR	05h
Port P2 resistor enable	P2REN	07h
Port P2 drive strength	P2DS	09h
Port P2 selection	P2SEL	0Bh
Port P2 interrupt vector word	P2IV	1Eh
Port P2 interrupt edge select	P2IES	19h
Port P2 interrupt enable	P2IE	1Bh
Port P2 interrupt flag	P2IFG	1Dh

表 6-34. Port P3 and P4 Registers (Base Address: 0220h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P3 input	P3IN	00h
Port P3 output	P3OUT	02h
Port P3 direction	P3DIR	04h
Port P3 resistor enable	P3REN	06h
Port P3 drive strength	P3DS	08h
Port P3 selection	P3SEL	0Ah
Port P4 input	P4IN	01h
Port P4 output	P4OUT	03h
Port P4 direction	P4DIR	05h
Port P4 resistor enable	P4REN	07h
Port P4 drive strength	P4DS	09h
Port P4 selection	P4SEL	0Bh

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表 6-35. Port P5 and P6 Registers (Base Address: 0240h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P5 input	P5IN	00h
Port P5 output	P5OUT	02h
Port P5 direction	P5DIR	04h
Port P5 resistor enable	P5REN	06h
Port P5 drive strength	P5DS	08h
Port P5 selection	P5SEL	0Ah
Port P6 input	P6IN	01h
Port P6 output	P6OUT	03h
Port P6 direction	P6DIR	05h
Port P6 resistor enable	P6REN	07h
Port P6 drive strength	P6DS	09h
Port P6 selection	P6SEL	0Bh

表 6-36. Port P7 and P8 Registers (Base Address: 0260h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P7 input	P7IN	00h
Port P7 output	P7OUT	02h
Port P7 direction	P7DIR	04h
Port P7 resistor enable	P7REN	06h
Port P7 drive strength	P7DS	08h
Port P7 selection	P7SEL	0Ah
Port P8 input	P8IN	01h
Port P8 output	P8OUT	03h
Port P8 direction	P8DIR	05h
Port P8 resistor enable	P8REN	07h
Port P8 drive strength	P8DS	09h
Port P8 selection	P8SEL	0Bh

表 6-37. Port P9 Registers (Base Address: 0280h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P9 input	P9IN	00h
Port P9 output	P9OUT	02h
Port P9 direction	P9DIR	04h
Port P9 resistor enable	P9REN	06h
Port P9 drive strength	P9DS	08h
Port P9 selection	P9SEL	0Ah

表 6-38. Port J Registers (Base Address: 0320h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Port PJ input	PJIN	00h
Port PJ output	PJOUT	02h
Port PJ direction	PJDIR	04h
Port PJ resistor enable	PJREN	06h
Port PJ drive strength	PJDS	08h
Port PJ selection	PJSEL	0Ah

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表 6-39. TA0 Registers (Base Address: 0340h)

REGISTER DESCRIPTION	REGISTER	OFFSET
TA0 control	TA0CTL	00h
Capture/compare control 0	TA0CCTL0	02h
Capture/compare control 1	TA0CCTL1	04h
Capture/compare control 2	TA0CCTL2	06h
TA0 counter	TA0R	10h
Capture/compare 0	TA0CCR0	12h
Capture/compare 1	TA0CCR1	14h
Capture/compare 2	TA0CCR2	16h
TA0 expansion 0	TA0EX0	20h
TA0 interrupt vector	TA0IV	2Eh

表 6-40. TA1 Registers (Base Address: 0380h)

REGISTER DESCRIPTION	REGISTER	OFFSET
TA1 control	TA1CTL	00h
Capture/compare control 0	TA1CCTL0	02h
Capture/compare control 1	TA1CCTL1	04h
TA1 counter	TA1R	10h
Capture/compare 0	TA1CCR0	12h
Capture/compare 1	TA1CCR1	14h
TA1 expansion 0	TA1EX0	20h
TA1 interrupt vector	TA1IV	2Eh

表 6-41. TA2 Registers (Base Address: 0400h)

REGISTER DESCRIPTION	REGISTER	OFFSET
TA2 control	TA2CTL	00h
Capture/compare control 0	TA2CCTL0	02h
Capture/compare control 1	TA2CCTL1	04h
TA2 counter	TA2R	10h
Capture/compare 0	TA2CCR0	12h
Capture/compare 1	TA2CCR1	14h
TA2 expansion 0	TA2EX0	20h
TA2 interrupt vector	TA2IV	2Eh

表 6-42. TA3 Registers (Base Address: 0440h)

REGISTER DESCRIPTION	REGISTER	OFFSET
TA3 control	TA3CTL	00h
Capture/compare control 0	TA3CCTL0	02h
Capture/compare control 1	TA3CCTL1	04h
TA3 counter	TA3R	10h
Capture/compare 0	TA3CCR0	12h
Capture/compare 1	TA3CCR1	14h
TA3 expansion 0	TA3EX0	20h
TA3 interrupt vector	TA3IV	2Eh

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表 6-43. Backup Memory Registers (Base Address: 0480h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Backup memory 0	BAKMEM0	00h
Backup memory 1	BAKMEM1	02h
Backup memory 2	BAKMEM2	04h
Backup memory 3	BAKMEM3	06h

表 6-44. RTC_C Registers (Base Address: 04A0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
RTC control 0	RTCCTL0	00h
RTC password	RTCPWD	01h
RTC control 1	RTCCTL1	02h
RTC control 3	RTCCTL3	03h
RTC offset calibration	RTCOCAL	04h
RTC temperature compensation	RTCTCMP	06h
RTC prescaler 0 control	RTCPS0CTL	08h
RTC prescaler 1 control	RTCPS1CTL	0Ah
RTC prescaler 0	RTCPS0	0Ch
RTC prescaler 1	RTCPS1	0Dh
RTC interrupt vector word	RTCIV	0Eh
RTC seconds	RTCSEC	10h
RTC minutes	RTCMIN	11h
RTC hours	RTCHOUR	12h
RTC day of week	RTCDOW	13h
RTC days	RTCDAY	14h
RTC month	RTCMON	15h
RTC year	RTCYEAR	16h
RTC alarm minutes	RTCAMIN	18h
RTC alarm hours	RTCAHOUR	19h
RTC alarm day of week	RTCADOW	1Ah
RTC alarm days	RTCADAY	1Bh
Binary-to-BCD conversion	BIN2BCD	1Ch
BCD-to-binary conversion	BCD2BIN	1Eh

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表 6-45. 32-Bit Hardware Multiplier Registers (Base Address: 04C0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
16-bit operand 1 – multiply	MPY	00h
16-bit operand 1 – signed multiply	MPYS	02h
16-bit operand 1 – multiply accumulate	MAC	04h
16-bit operand 1 – signed multiply accumulate	MACS	06h
16-bit operand 2	OP2	08h
16 × 16 result low word	RESLO	0Ah
16 × 16 result high word	RESHI	0Ch
16 × 16 sum extension	SUMEXT	0Eh
32-bit operand 1 – multiply low word	MPY32L	10h
32-bit operand 1 – multiply high word	MPY32H	12h
32-bit operand 1 – signed multiply low word	MPYS32L	14h
32-bit operand 1 – signed multiply high word	MPYS32H	16h
32-bit operand 1 – multiply accumulate low word	MAC32L	18h
32-bit operand 1 – multiply accumulate high word	MAC32H	1Ah
32-bit operand 1 – signed multiply accumulate low word	MACS32L	1Ch
32-bit operand 1 – signed multiply accumulate high word	MACS32H	1Eh
32-bit operand 2 – low word	OP2L	20h
32-bit operand 2 – high word	OP2H	22h
32 × 32 result 0 – least significant word	RES0	24h
32 × 32 result 1	RES1	26h
32 × 32 result 2	RES2	28h
32 × 32 result 3 – most significant word	RES3	2Ah
MPY32 control 0	MPY32CTL0	2Ch

表 6-46. DMA General Control Registers (Base Address: 0500h)

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA module control 0	DMACTL0	00h
DMA module control 1	DMACTL1	02h
DMA module control 2	DMACTL2	04h
DMA module control 3	DMACTL3	06h
DMA module control 4	DMACTL4	08h
DMA interrupt vector	DMAIV	0Eh

表 6-47. DMA Channel 0 Registers (Base Address: 0500h)

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 0 control	DMA0CTL	10h
DMA channel 0 source address low	DMA0SAL	12h
DMA channel 0 source address high	DMA0SAH	14h
DMA channel 0 destination address low	DMA0DAL	16h
DMA channel 0 destination address high	DMA0DAH	18h
DMA channel 0 transfer size	DMA0SZ	1Ah

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表 6-48. DMA Channel 1 Registers (Base Address: 0500h)

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 1 control	DMA1CTL	20h
DMA channel 1 source address low	DMA1SAL	22h
DMA channel 1 source address high	DMA1SAH	24h
DMA channel 1 destination address low	DMA1DAL	26h
DMA channel 1 destination address high	DMA1DAH	28h
DMA channel 1 transfer size	DMA1SZ	2Ah

表 6-49. DMA Channel 2 Registers (Base Address: 0500h)

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 2 control	DMA2CTL	30h
DMA channel 2 source address low	DMA2SAL	32h
DMA channel 2 source address high	DMA2SAH	34h
DMA channel 2 destination address low	DMA2DAL	36h
DMA channel 2 destination address high	DMA2DAH	38h
DMA channel 2 transfer size	DMA2SZ	3Ah

表 6-50. eUSCI_A0 Registers (Base Address: 05C0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
eUSCI_A control word 0	UCA0CTLW0	00h
eUSCI _A control word 1	UCA0CTLW1	02h
eUSCI_A baud rate 0	UCA0BR0	06h
eUSCI_A baud rate 1	UCA0BR1	07h
eUSCI_A modulation control	UCA0MCTLW	08h
eUSCI_A status	UCA0STAT	0Ah
eUSCI_A receive buffer	UCA0RXBUF	0Ch
eUSCI_A transmit buffer	UCA0TXBUF	0Eh
eUSCI_A LIN control	UCA0ABCTL	10h
eUSCI_A IrDA transmit control	UCA0IRTCTL	12h
eUSCI_A IrDA receive control	UCA0IRRCTL	13h
eUSCI_A interrupt enable	UCA0IE	1Ah
eUSCI_A interrupt flags	UCA0IFG	1Ch
eUSCI_A interrupt vector word	UCA0IV	1Eh

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表 6-51. eUSCI_A1 Registers (Base Address:05E0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
eUSCI_A control word 0	UCA1CTLW0	00h
eUSCI _A control word 1	UCA1CTLW1	02h
eUSCI_A baud rate 0	UCA1BR0	06h
eUSCI_A baud rate 1	UCA1BR1	07h
eUSCI_A modulation control	UCA1MCTLW	08h
eUSCI_A status	UCA1STAT	0Ah
eUSCI_A receive buffer	UCA1RXBUF	0Ch
eUSCI_A transmit buffer	UCA1TXBUF	0Eh
eUSCI_A LIN control	UCA1ABCTL	10h
eUSCI_A IrDA transmit control	UCA1IRTCTL	12h
eUSCI_A IrDA receive control	UCA1IRRCTL	13h
eUSCI_A interrupt enable	UCA1IE	1Ah
eUSCI_A interrupt flags	UCA1IFG	1Ch
eUSCI_A interrupt vector word	UCA1IV	1Eh

表 6-52. eUSCI_A2 Registers (Base Address:0600h)

REGISTER DESCRIPTION	REGISTER	OFFSET
eUSCI_A control word 0	UCA2CTLW0	00h
eUSCI _A control word 1	UCA2CTLW1	02h
eUSCI_A baud rate 0	UCA2BR0	06h
eUSCI_A baud rate 1	UCA2BR1	07h
eUSCI_A modulation control	UCA2MCTLW	08h
eUSCI_A status	UCA2STAT	0Ah
eUSCI_A receive buffer	UCA2RXBUF	0Ch
eUSCI_A transmit buffer	UCA2TXBUF	0Eh
eUSCI_A LIN control	UCA2ABCTL	10h
eUSCI_A IrDA transmit control	UCA2IRTCTL	12h
eUSCI_A IrDA receive control	UCA2IRRCTL	13h
eUSCI_A interrupt enable	UCA2IE	1Ah
eUSCI_A interrupt flags	UCA2IFG	1Ch
eUSCI_A interrupt vector word	UCA2IV	1Eh

表 6-53. eUSCI_B0 Registers (Base Address: 0640h)

REGISTER DESCRIPTION	REGISTER	OFFSET
eUSCI_B control word 0	UCB0CTLW0	00h
eUSCI_B control word 1	UCB0CTLW1	02h
eUSCI_B bit rate 0	UCB0BR0	06h
eUSCI_B bit rate 1	UCB0BR1	07h
eUSCI_B status word	UCB0STATW	08h
eUSCI_B byte counter threshold	UCB0TBCNT	0Ah
eUSCI_B receive buffer	UCB0RXBUF	0Ch
eUSCI_B transmit buffer	UCB0TXBUF	0Eh
eUSCI_B I2C own address 0	UCB0I2COA0	14h
eUSCI_B I2C own address 1	UCB0I2COA1	16h
eUSCI_B I2C own address 2	UCB0I2COA2	18h
eUSCI_B I2C own address 3	UCB0I2COA3	1Ah
eUSCI_B received address	UCB0ADDRX	1Ch
eUSCI_B address mask	UCB0ADDMASK	1Eh
eUSCI I2C slave address	UCB0I2CSA	20h
eUSCI interrupt enable	UCB0IE	2Ah
eUSCI interrupt flags	UCB0IFG	2Ch
eUSCI interrupt vector word	UCB0IV	2Eh

表 6-54. ADC10_A Registers (Base Address: 0740h)

REGISTER DESCRIPTION	REGISTER	OFFSET
ADC10_A control 0	ADC10CTL0	00h
ADC10_A control 1	ADC10CTL1	02h
ADC10_A control 2	ADC10CTL2	04h
ADC10_A window comparator low threshold	ADC10LO	06h
ADC10_A window comparator high threshold	ADC10HI	08h
ADC10_A memory control 0	ADC10MCTL0	0Ah
ADC10_A conversion memory	ADC10MCTL0	12h
ADC10_A interrupt enable	ADC10IE	1Ah
ADC10_A interrupt flags	ADC10IGH	1Ch
ADC10_A interrupt vector word	ADC10IV	1Eh

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表 6-55. SD24_B Registers (Base Address: 0800h)

REGISTER DESCRIPTION	REGISTER	OFFSET
SD24_B control 0	SD24BCTL0	00h
SD24_B control 1	SD24BCTL1	02h
SD24_B interrupt flag	SD24BIFG	0Ah
SD24_B interrupt enable	SD24BIE	0Ch
SD24_B interrupt vector	SD24BIV	0Eh
SD24_B converter 0 control	SD24BCCTL0	10h
SD24_B converter 0 input control	SD24BINCTL0	12h
SD24_B converter 0 OSR control	SD24BOSR0	14h
SD24_B converter 0 preload	SD24BPRE0	16h
SD24_B converter 1 control	SD24BCCTL1	18h
SD24_B converter 1 input control	SD24BINCTL1	1Ah
SD24_B converter 1 OSR control	SD24BOSR1	1Ch
SD24_B converter 1 preload	SD24BPRE1	1Eh
SD24_B converter 2 control	SD24BCCTL2	20h
SD24_B converter 2 input control	SD24BINCTL2	22h
SD24_B converter 2 OSR control	SD24BOSR2	24h
SD24_B converter 2 preload	SD24BPRE2	26h
SD24_B converter 0 conversion memory low word	SD24BMEML0	50h
SD24_B converter 0 conversion memory high word	SD24BMEMH0	52h
SD24_B converter 1 conversion memory low word	SD24BMEML1	54h
SD24_B converter 1 conversion memory high word	SD24BMEMH1	56h
SD24_B converter 2 conversion memory low word	SD24BMEML2	58h
SD24_B converter 2 conversion memory high word	SD24BMEMH2	5Ah

表 6-56. Auxiliary Supplies Registers (Base Address: 09E0h)

REGISTER DESCRIPTION	REGISTER	OFFSET
Auxiliary supply control 0	AUXCTL0	00h
Auxiliary supply control 1	AUXCTL1	02h
Auxiliary supply control 2	AUXCTL2	04h
AUX2 charger control	AUX2CHCTL	12h
AUX3 charger control	AUX3CHCTL	14h
AUX ADC control	AUXADCCTL	16h
AUX interrupt flag	AUXIFG	1Ah
AUX interrupt enable	AUXIE	1Ch
AUX interrupt vector word	AUXIV	1Eh

表 6-57. LCD_C Registers (Base Address: 0A00h)

REGISTER DESCRIPTION	REGISTER	OFFSET
LCD_C control 0	LCDCCTL0	000h
LCD_C control 1	LCDCCTL1	002h
LCD_C blinking control	LCDCBLKCTL	004h
LCD_C memory control	LCDCMEMCTL	006h
LCD_C voltage control	LCDCVCTL	008h
LCD_C port control 0	LCDCPCTL0	00Ah
LCD_C port control 1	LCDCPCTL1	00Ch
LCD_C port control 2	LCDCPCTL2	00Eh
LCD_C charge pump control	LCDCCPCTL	012h
LCD_C interrupt vector	LCDCIV	01Eh
Static and 2- to 4-mux modes		
LCD_C memory 1	LCDM1	020h
LCD_C memory 2	LCDM2	021h
⋮	⋮	⋮
LCD_C memory 20	LCDM20	033h
LCD_C blinking memory 1	LCDBM1	040h
LCD_C blinking memory 2	LCDBM2	041h
⋮	⋮	⋮
LCD_C blinking memory 20	LCDBM20	053h
5- to 8-mux modes		
LCD_C memory 1	LCDM1	020h
LCD_C memory 2	LCDM2	021h
⋮	⋮	⋮
LCD_C memory 40	LCDM40	047h

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6.12 Input/Output Diagrams

6.12.1 Port P1 (P1.0 and P1.1) Input/Output With Schmitt Trigger (MSP430F67xxIPZ and MSP430F67xxIPN)

图 6-2 shows the port diagram. 表 6-58 summarizes the selection of the pin functions.

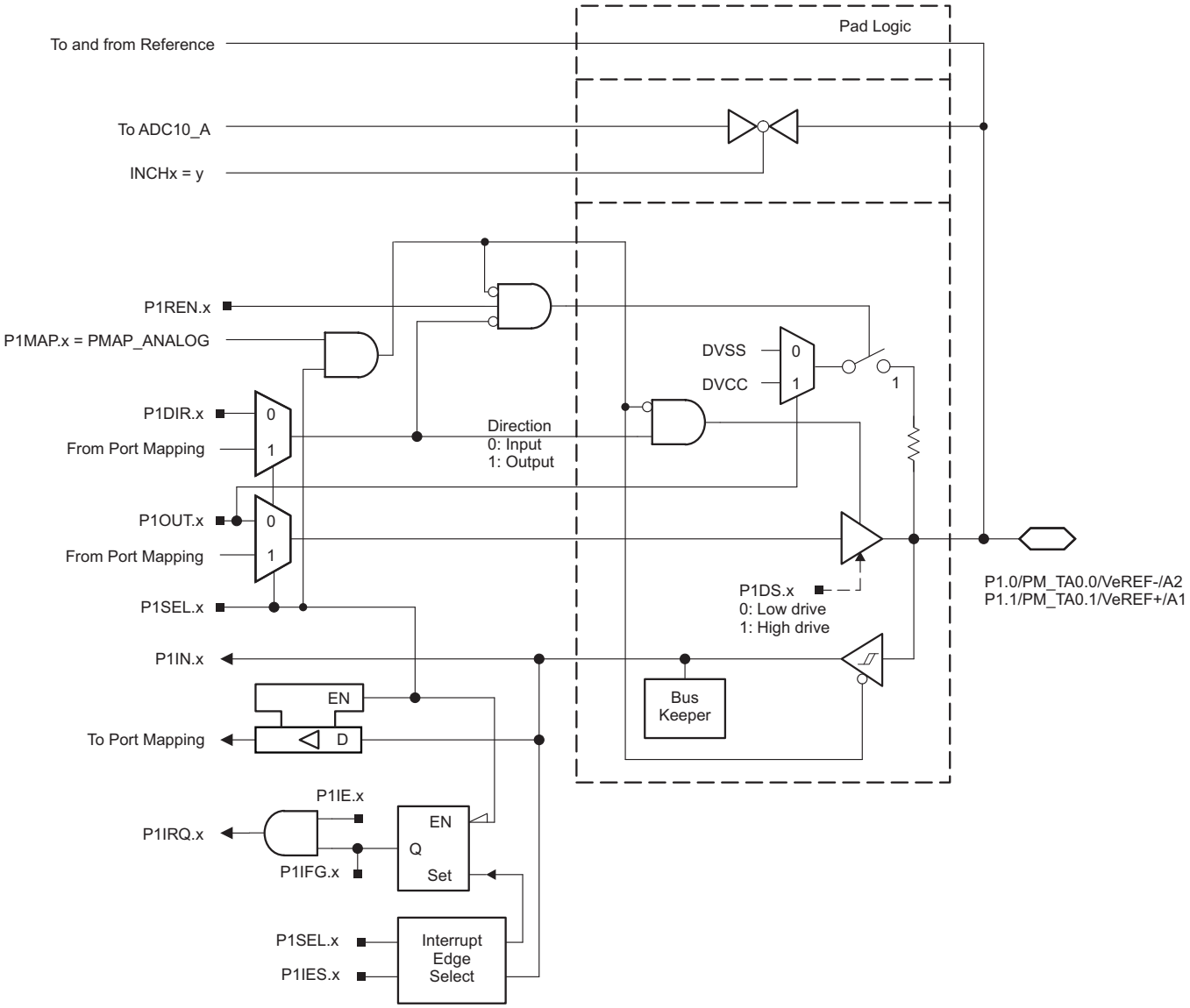


图 6-2. Port P1 (P1.0 and P1.1) Diagram (MSP430F67xxIPZ and MSP430F67xxIPN)

表 6-58. Port P1 (P1.0 and P1.1) Pin Functions (MSP430F67xxIPZ and MSP430F67xxIPN)

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P1DIR.x	P1SEL.x	P1MAPx
P1.0/PM_TA0.0/ VeREF-/A2	0	P1.0 (I/O)	I: 0; O: 1	0	X
		TA0.CCI0A	0	1	default
		TA0.TA0	1	1	default
		VeREF-/A2(2)	X	1	= 31
P1.1/PM_TA0.1/ VeREF+/A1	1	P1.1 (I/O)	I: 0; O: 1	0	X
		TA0.CCI1A	0	1	default
		TA0.TA1	1	1	default
		VeREF+/A1(2)	X	1	= 31

(1) X = Don't care
(2) Setting P1SEL.x bit together with P1MAPx = PM_ANALOG disables the output driver and the input Schmitt trigger.

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6.12.2 Port P1 (P1.2) Input/Output With Schmitt Trigger (MSP430F67xxIPZ and MSP430F67xxIPN)

图 6-3 shows the port diagram. 表 6-59 summarizes the selection of the pin functions.

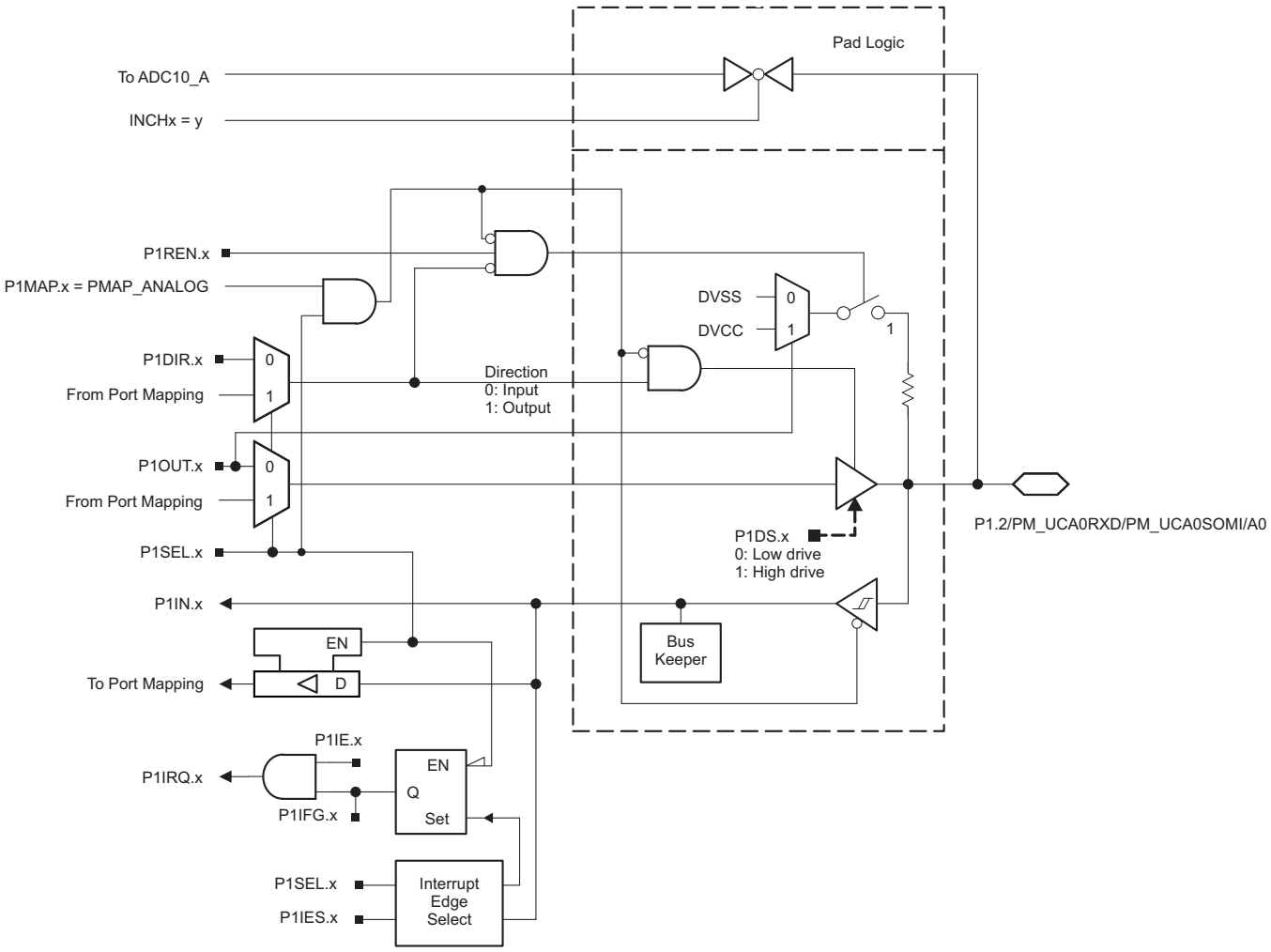


图 6-3. Port P1 (P1.2) Pin Functions (MSP430F67xxIPZ and MSP430F67xxIPN)

表 6-59. Port P1 (P1.2) Pin Functions (MSP430F67xxIPZ and MSP430F67xxIPN)

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P1DIR.x	P1SEL.x	P1MAPx
P1.2/PM_UCA0RXD/ PM_UCA0SOMI/A0	2	P1.2 (I/O)	I: 0; O: 1	0	X
		UCA0RXD/UCA0SOMI	X	1	default
		A0(2)	X	1	= 31

(1) X = Don't care
(2) Setting P1SEL.x bit together with P1MAPx = PM_ANALOG disables the output driver and the input Schmitt trigger.

6.12.3 Port P1 (P1.3 to P1.5) Input/Output With Schmitt Trigger (MSP430F67xxIPZ and MSP430F67xxIPN)

图 6-4 shows the port diagram. 表 6-60 summarizes the selection of the pin functions.

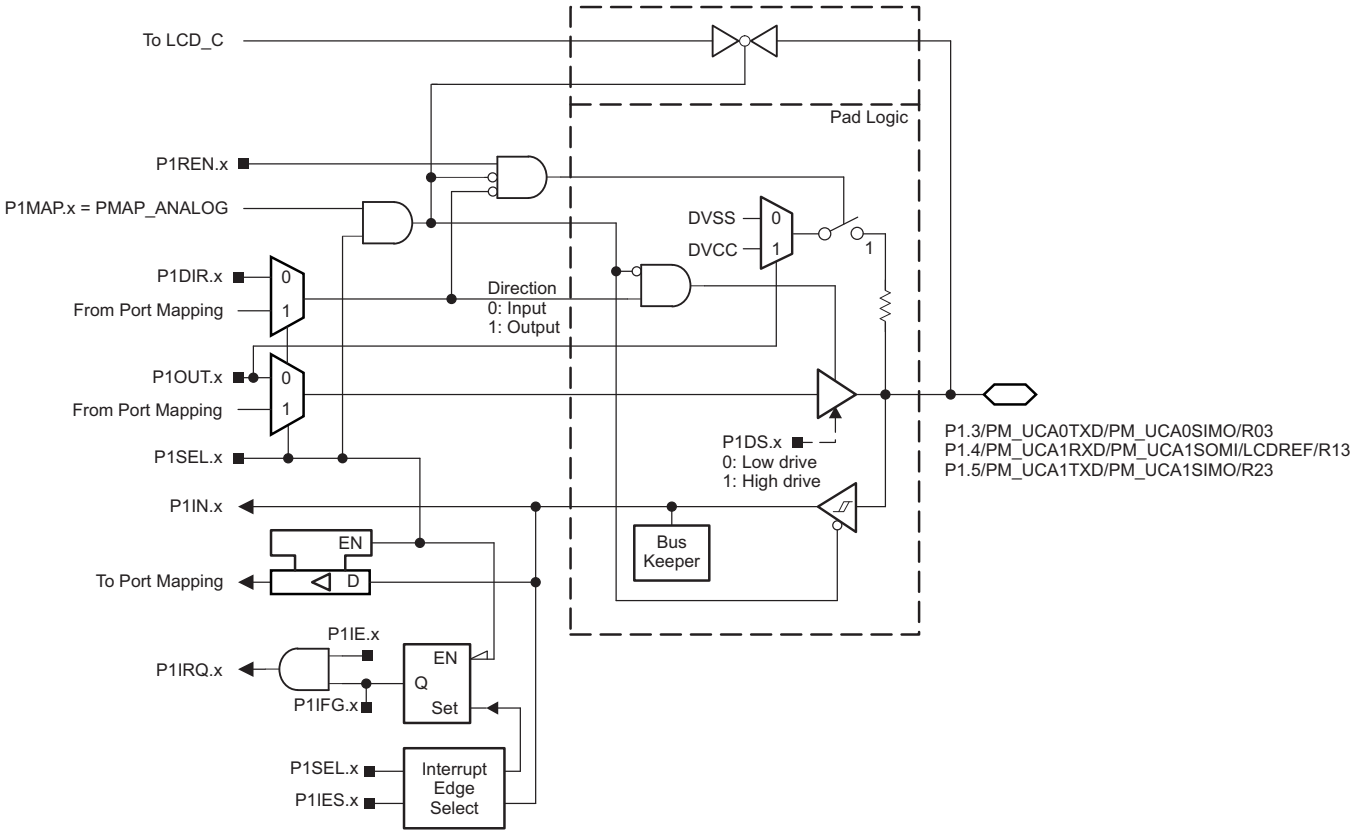


图 6-4. Port P1 (P1.3 to P1.5) Diagram (MSP430F67xxIPZ and MSP430F67xxIPN)

表 6-60. Port P1 (P1.3 to P1.5) Pin Functions (MSP430F67xxIPZ and MSP430F67xxIPN)

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P1DIR.x	P1SEL.x	P1MAPx
P1.3/PM_UCA0TXD/ PM_UCA0SIMO/R03	3	P1.3 (I/O)	I: 0; O: 1	0	X
		UCA0TXD/UCA0SIMO	X	1	default
		R03(2)	X	1	= 31
P1.4/PM_UCA1RXD/ PM_UCA1SOMI/ LCDREF/R13	4	P1.4 (I/O)	I: 0; O: 1	0	X
		UCA1RXD/UCA1SOMI	X	1	default
		LCDREF/R13(2)	X	1	= 31
P1.5/PM_UCA1TXD/ PM_UCA1SIMO/R23	5	P1.5 (I/O)	I: 0; O: 1	0	X
		UCA1TXD/UCA1SIMO	X	1	default
		R23(2)	X	1	= 31

(1) X = Don't care
(2) Setting P1SEL.x bit together with P1MAPx = PM_ANALOG disables the output driver and the input Schmitt trigger.

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6.12.4 Port P1 (P1.6 and P1.7) (MSP430F67xxIPZ and MSP430F67xxIPN), Port P2 (P2.0 and P2.1) (MSP430F67xxIPZ Only) Input/Output With Schmitt Trigger

图 6-5 shows the port diagram. 表 6-61 and 表 6-62 summarize the selection of the pin functions.

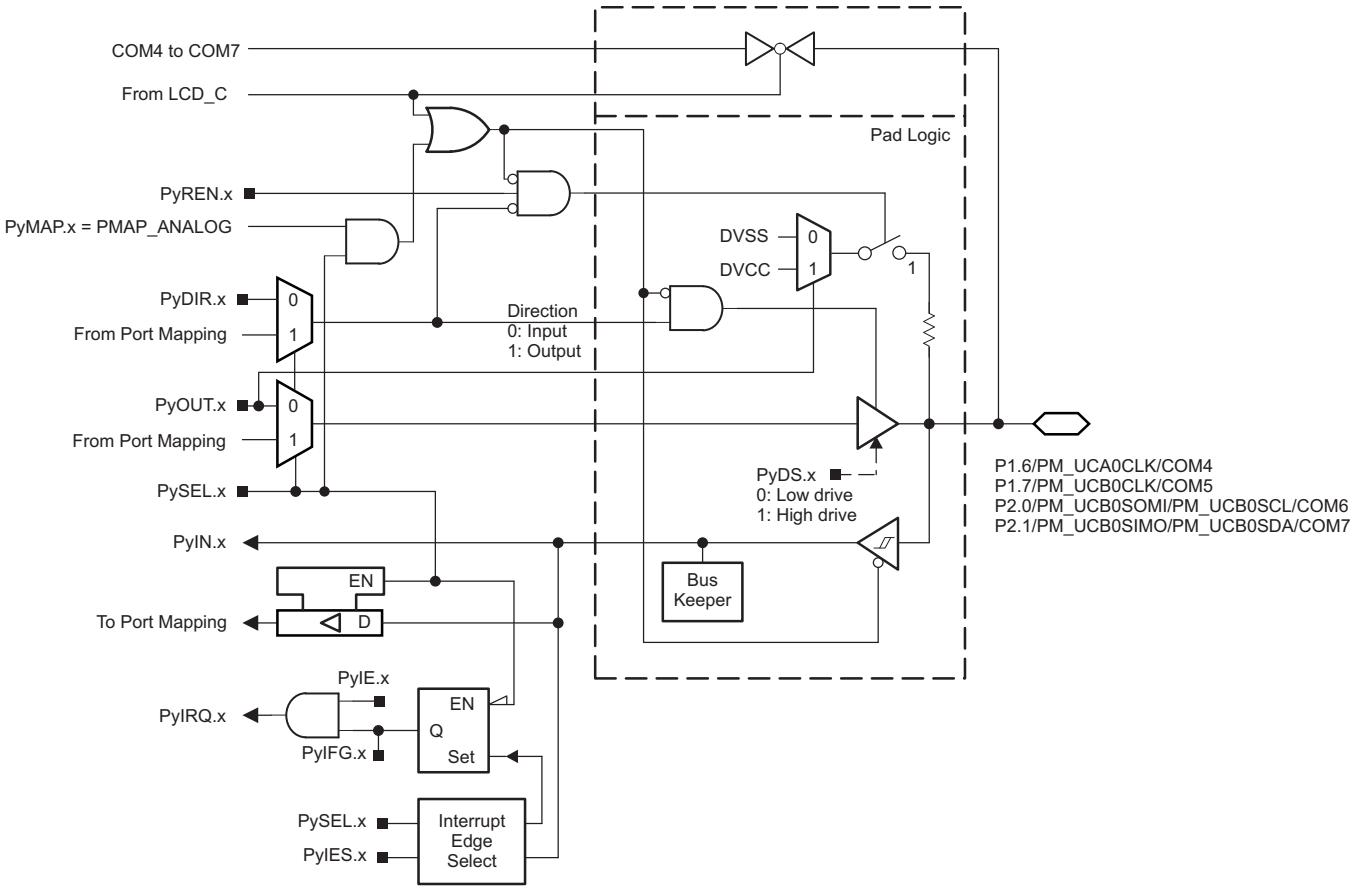


图 6-5. Port P1 (P1.6 and P1.7) (MSP430F67xxIPZ and MSP430F67xxIPN), Port P2 (P2.0 and P2.1) (MSP430F67xxIPZ Only) Diagram

表 6-61. Port P1 (P1.6 and P1.7) Pin Functions (MSP430F67xxIPZ and MSP430F67xxIPN)

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)			
			P1DIR.x	P1SEL.x	P1MAPx	COM4, COM5 Enable Signal
P1.6/PM_UCA0CLK/COM4	6	P1.6 (I/O)	I: 0; O: 1	0	X	0
		UCA0CLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		COM4	X	X	X	1
P1.7/PM_UCB0CLK/COM5	7	P1.7 (I/O)	I: 0; O: 1	0	X	0
		UCB0CLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		COM5	X	X	X	1

(1) X = Don't care

表 6-62. Port P2 (P2.0 and P2.1) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)			
			P2DIR.x	P2SEL.x	P2MAPx	COM6, COM7 Enable Signal
P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6	0	P2.0 (I/O)	I: 0; O: 1	0	X	0
		UCB0SOMI/UCB0SCL	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		COM6	X	X	X	1
P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7	1	P2.1 (I/O)	I: 0; O: 1	0	X	0
		UCB0SIMO/UCB0SDA	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		COM7	X	X	X	1

(1) X = Don't care

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6.12.5 Port P2 (P2.2 to P2.7) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-6 shows the port diagram. 表 6-63 summarizes the selection of the pin functions.

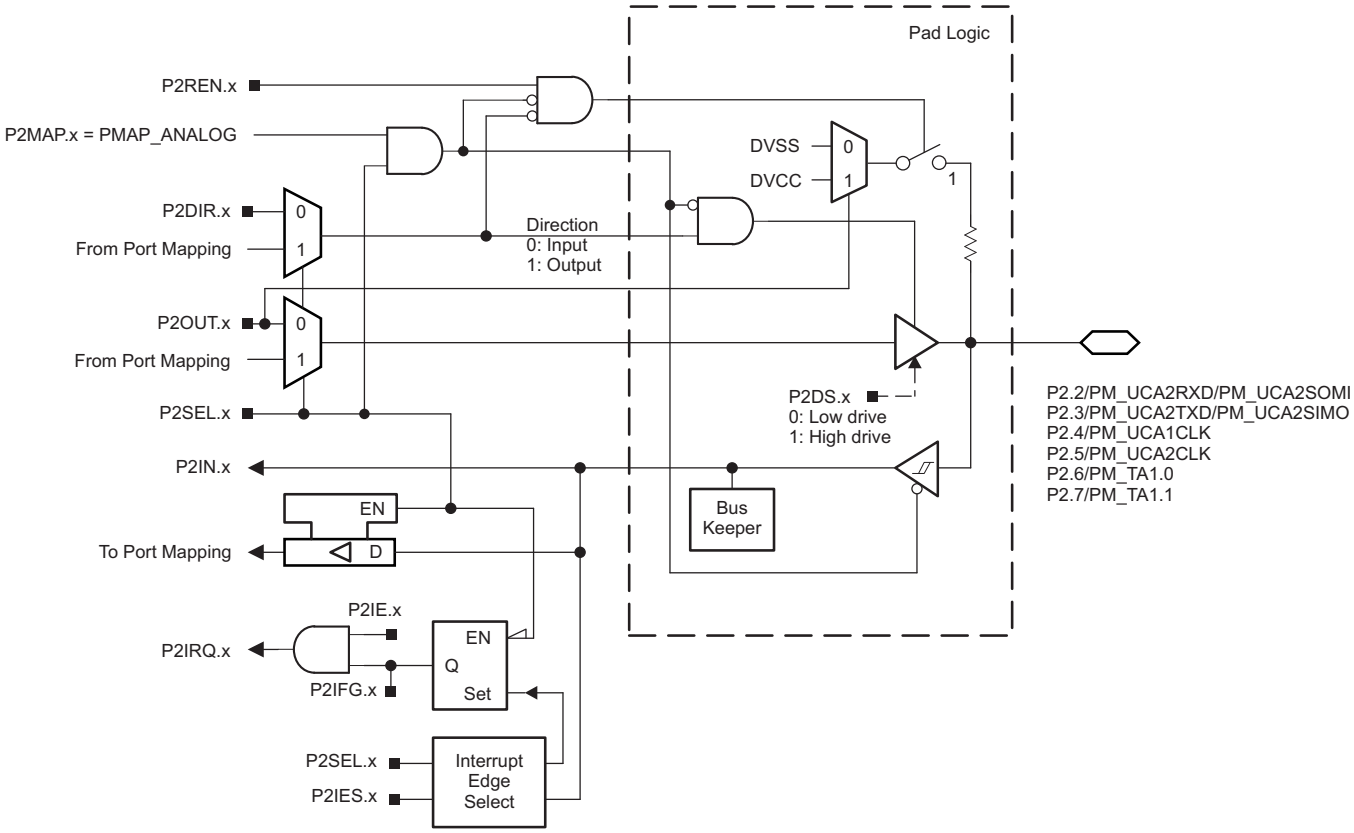


图 6-6. Port P2 (P2.2 to P2.7) Diagram (MSP430F67xxIPZ Only)

表 6-63. Port P2 (P2.2 to P2.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P2DIR.x	P2SEL.x	P2MAPx
P2.2/PM_UCA2RXD/ PM_UCA2SOMI	2	P2.2 (I/O)	I: 0; O: 1	0	X
		UCA2RXD/UCA2SOMI	X	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P2.3/PM_UCA2TXD/ PM_UCA2SIMO	3	P2.3 (I/O)	I: 0; O: 1	0	X
		UCA2TXD/UCA2SIMO	X	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P2.4/PM_UCA1CLK	4	P2.4 (I/O)	I: 0; O: 1	0	X
		UCA1CLK	X	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P2.5/PM_UCA2CLK	5	P2.5 (I/O)	I: 0; O: 1	0	X
		UCA2CLK	X	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P2.6/PM_TA1.0	6	P2.6 (I/O)	I: 0; O: 1	0	X
		TA1.CC10A	0	1	default
		TA1.TA0	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P2.7/PM_TA1.1	7	P2.7 (I/O)	I: 0; O: 1	0	X
		TA1.CCI1A	0	1	default
		TA1.TA1	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31

(1) X = Don't care

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6.12.6 Port P3 (P3.0 to P3.3) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-7 shows the port diagram. 表 6-64 summarizes the selection of the pin functions.

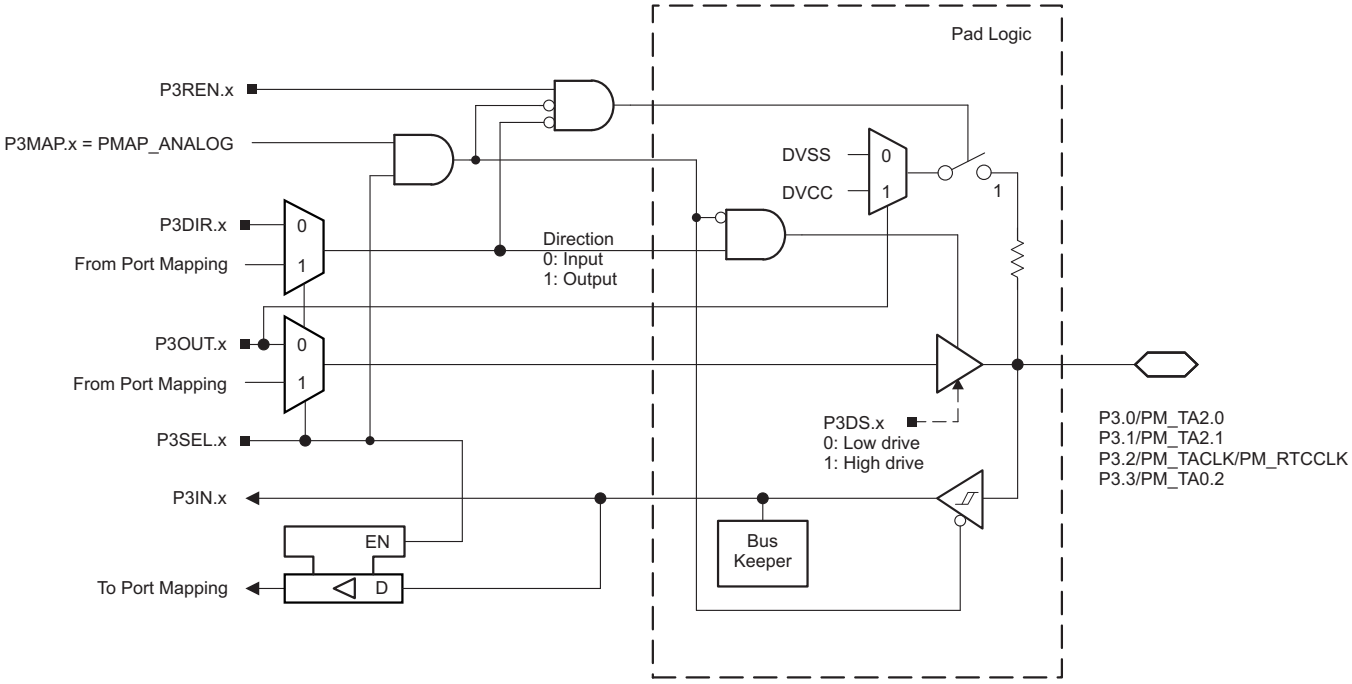


图 6-7. Port P3 (P3.0 to P3.3) Diagram (MSP430F67xxIPZ Only)

表 6-64. Port P3 (P3.0 to P3.3) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P3.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P3DIR.x	P3SEL.x	P3MAPx
P3.0/PM_TA2.0	0	P3.0 (I/O)	I: 0; O: 1	0	X
		TA2.CC10A	0	1	default
		TA2.TA0	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P3.1/PM_TA2.1	1	P3.1 (I/O)	I: 0; O: 1	0	X
		TA2.CCI1A	0	1	default
		TA2.TA1	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P3.2/PM_TACLK/ PM_RTCCLK	2	P3.2 (I/O)	I: 0; O: 1	0	X
		TACLK	0	1	default
		RTCCLK	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31
P3.3/PM_TA0.2	3	P3.3 (I/O)	I: 0; O: 1	0	X
		TA0.CCI2A	0	1	default
		TA0.TA2	1	1	default
		Output driver and input Schmitt trigger disabled	X	1	= 31

(1) X = Don't care

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6.12.7 Port P3 (P3.4 to P3.7) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-8 shows the port diagram. 表 6-65 summarizes the selection of the pin functions.

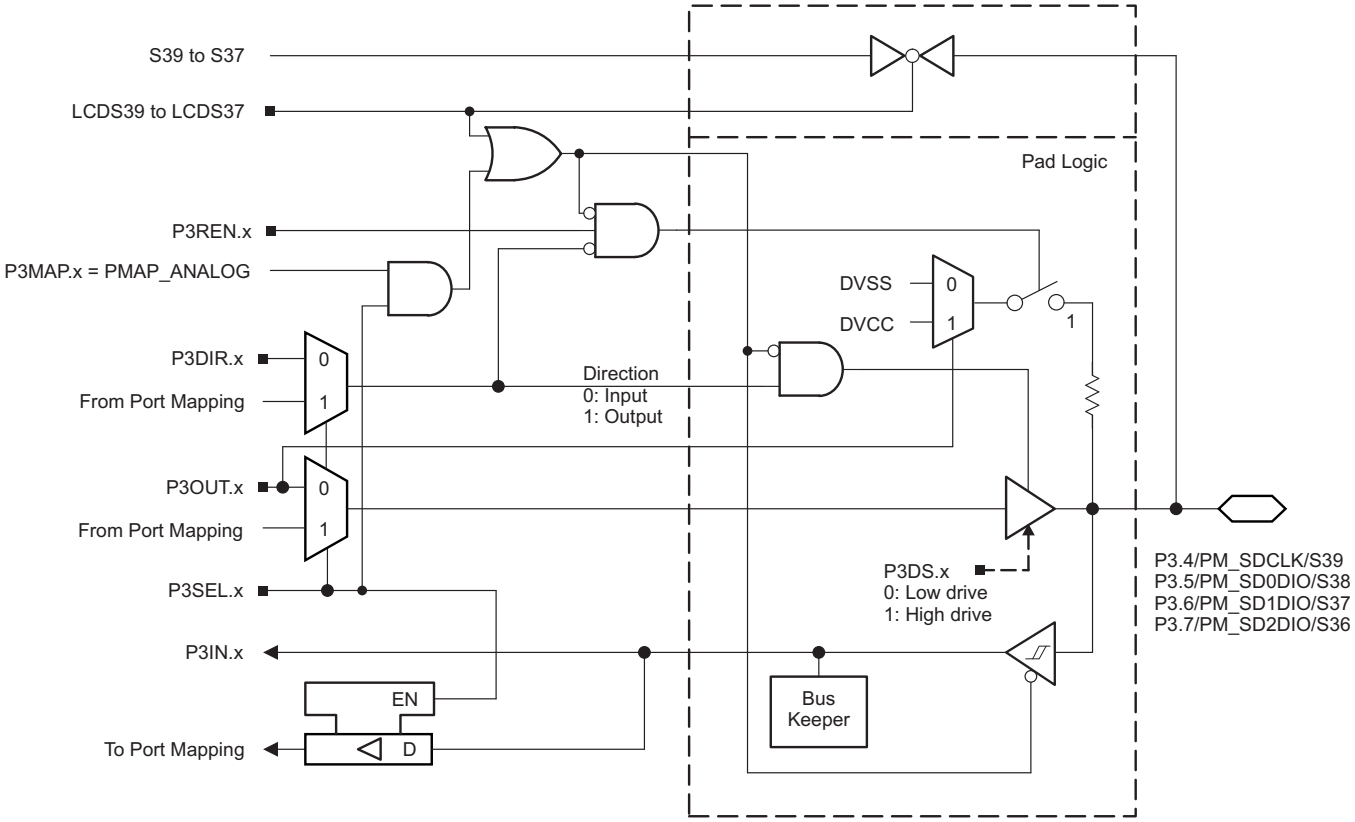


图 6-8. Port P3 (P3.4 to P3.7) Diagram (MSP430F67xxIPZ Only)

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表 6-65. Port P3 (P3.4 to P3.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P3.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)			
			P3DIR.x	P3SEL.x	P3MAPx	LCDS39... LCDS36
P3.4/PM_SDCLK/S39	4	P3.4 (I/O)	I: 0; O: 1	0	X	0
		SDCLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S39	X	X	X	1
P3.5/PM_SD0DIO/S38	5	P3.5 (I/O)	I: 0; O: 1	0	X	0
		SD0DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S38	X	X	X	1
P3.6/PM_SD1DIO/S37	6	P3.6 (I/O)	I: 0; O: 1	0	X	0
		SD1DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S37	X	X	X	1
P3.7/PM_SD2DIO/S36	7	P3.7 (I/O)	I: 0; O: 1	0	X	0
		SD2DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S36	X	X	X	1

(1) X = Don't care

6.12.8 Port P4 (P4.0 to P4.7), Port P5 (P5.0 to P5.7), Port P6 (P6.0 to P6.7), Port P7 (P7.0 to P7.7), Port P8 (P8.0 to P8.3) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-9 shows the port diagram. 表 6-66 through 表 6-70 summarize the selection of the pin functions.

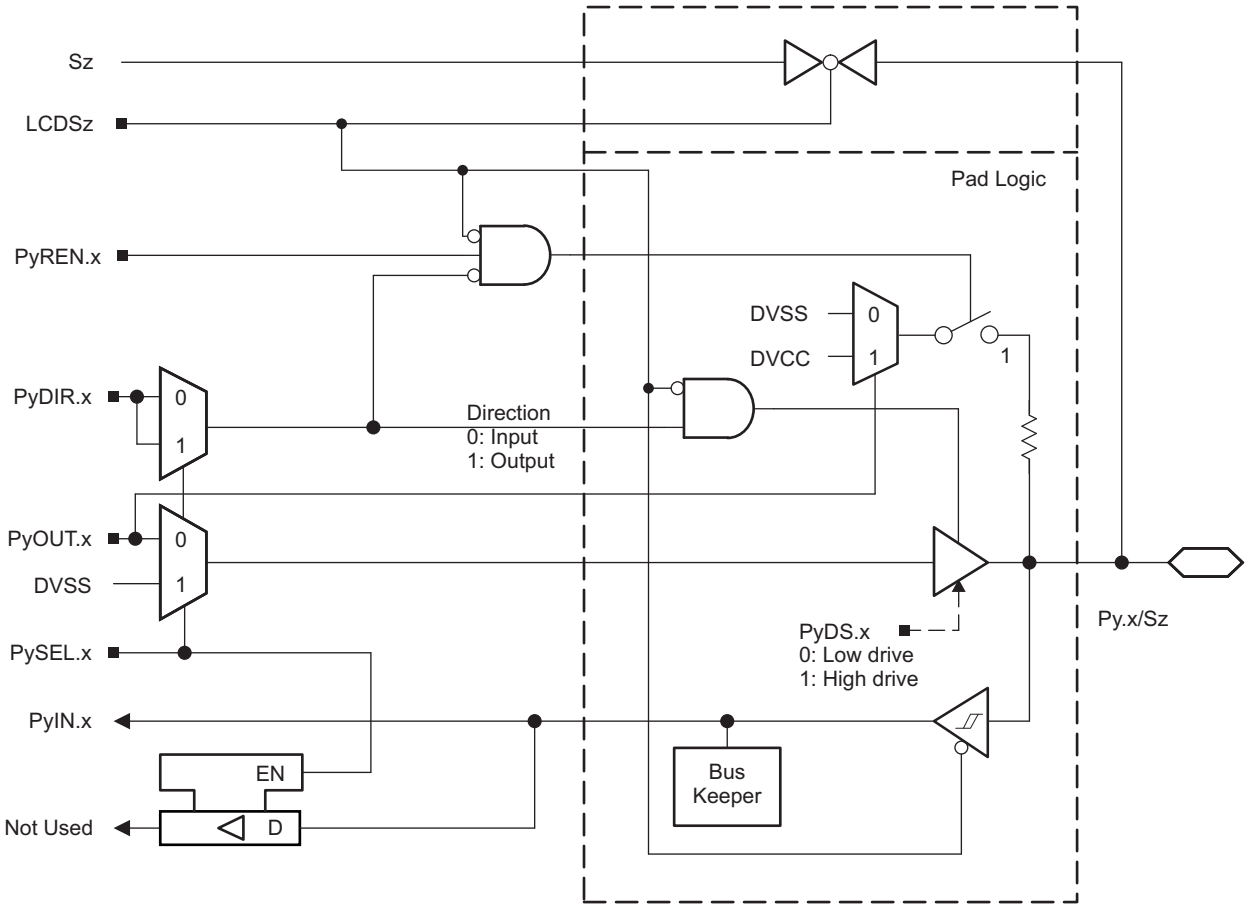


图 6-9. Port P4 (P4.0 to P4.7), Port P5 (P5.0 to P5.7), Port P6 (P6.0 to P6.7), Port P7 (P7.0 to P7.7), Port P8 (P8.0 to P8.3) Diagram (MSP430F67xxIPZ Only)

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表 6-66. Port P4 (P4.0 to P4.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P4.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P4DIR.x	P4SEL.x	LCDS35... LCDS28
P4.0/S35	0	P4.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S35	X	X	1
P4.1/S34	1	P4.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S34	X	X	1
P4.2/S33	2	P4.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S33	X	X	1
P4.3/S32	3	P4.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S32	X	X	1
P4.4/S31	4	P4.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S31	X	X	1
P4.5/S30	5	P4.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S30	X	X	1
P4.6/S29	6	P4.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S29	X	X	1
P4.7/S28	7	P4.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S28	X	X	1

(1) X = Don't care

表 6-67. Port P5 (P5.0 to P5.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P5.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P5DIR.x	P5SEL.x	LCDS27... LCDS20
P5.0/S27	0	P5.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S27	X	X	1
P5.1/S26	1	P5.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S26	X	X	1
P5.2/S25	2	P5.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S25	X	X	1
P5.3/S24	3	P5.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S24	X	X	1
P5.4/S23	4	P5.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S23	X	X	1
P5.5/S22	5	P5.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S22	X	X	1
P5.6/S21	6	P5.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S21	X	X	1
P5.7/S20	7	P5.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S20	X	X	1

(1) X = Don't care

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表 6-68. Port P6 (P6.0 to P6.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P6.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P6DIR.x	P6SEL.x	LCDS19... LCDS12
P6.0/S19	0	P6.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S19	X	X	1
P6.1/S18	1	P6.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S18	X	X	1
P6.2/S17	2	P6.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S17	X	X	1
P6.3/S16	3	P6.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S16	X	X	1
P6.4/S15	4	P6.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S15	X	X	1
P6.5/S14	5	P6.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S14	X	X	1
P6.6/S13	6	P6.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S13	X	X	1
P6.7/S12	7	P6.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S12	X	X	1

(1) X = Don't care

表 6-69. Port P7 (P7.0 to P7.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P7.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P7DIR.x	P7SEL.x	LCDS11... LCDS4
P7.0/S11	0	P7.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S11	X	X	1
P7.1/S10	1	P7.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S10	X	X	1
P7.2/S9	2	P7.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S9	X	X	1
P7.3/S8	3	P7.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S8	X	X	1
P7.4/S7	4	P7.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S7	X	X	1
P7.5/S6	5	P7.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S6	X	X	1
P7.6/S5	6	P7.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S5	X	X	1
P7.7/S4	7	P7.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S4	X	X	1

(1) X = Don't care

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表 6-70. Port P8 (P8.0 to P8.3) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P8.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P8DIR.x	P8SEL.x	LCDS3... LCDS0
P8.0/S3	0	P8.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S3	X	X	1
P8.1/S2	1	P8.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S2	X	X	1
P8.2/S1	2	P8.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S1	X	X	1
P8.3/S0	3	P8.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S0	X	X	1

(1) X = Don't care

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6.12.9 Port P8 (P8.4 to P8.7) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-10 shows the port diagram. 表 6-71 summarizes the selection of the pin functions.

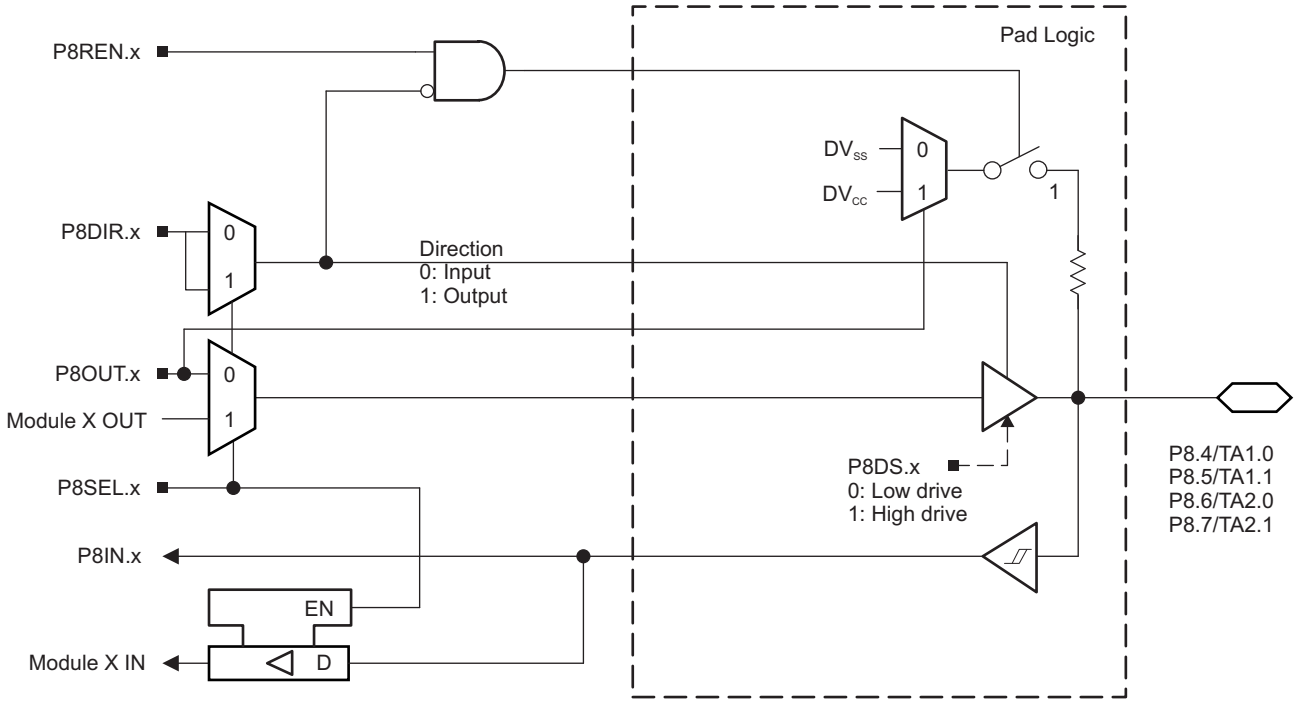


图 6-10. Port P8 (P8.4 to P8.7) Diagram (MSP430F67xxIPZ Only)

表 6-71. Port P8 (P8.4 to P8.7) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P8.x)	x	FUNCTION	CONTROL BITS OR SIGNALS	
			P8DIR.x	P8SEL.x
P8.4/TA1.0	4	P8.4 (I/O)	I: 0; O: 1	0
		TA1.CCI0A	0	1
		TA1.TA0	1	1
P8.5/TA1.1	5	P8.5 (I/O)	I: 0; O: 1	0
		TA1.CCI1A	0	1
		TA1.TA1	1	1
P8.6/TA2.0	6	P8.6 (I/O)	I: 0; O: 1	0
		TA2.CCI0A	0	1
		TA2.TA0	1	1
P8.7/TA2.1	7	P8.7 (I/O)	I: 0; O: 1	0
		TA2.CCI1A	0	1
		TA2.TA1	1	1

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6.12.10 Port P9 (P9.0) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-11 shows the port diagram. 表 6-72 summarizes the selection of the pin functions.

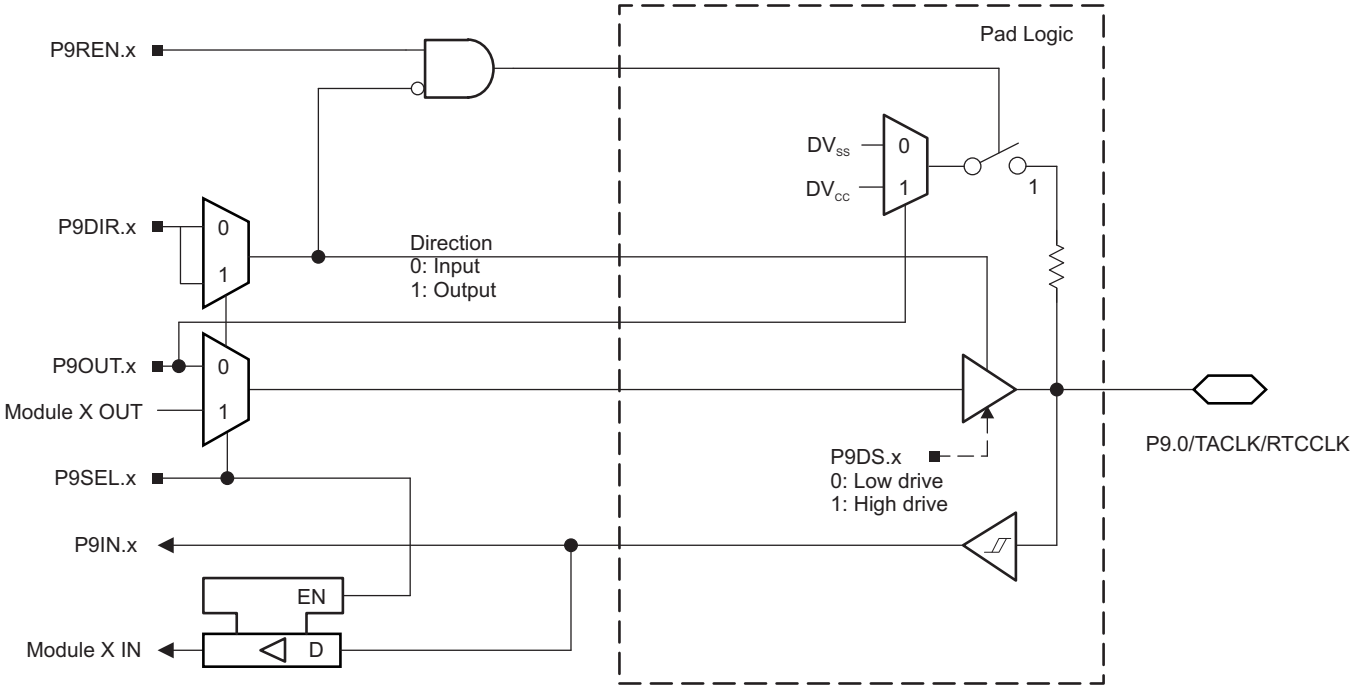


图 6-11. Port P9 (P9.0) Diagram (MSP430F67xxIPZ Only)

表 6-72. Port P9 (P9.0) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P9.x)	x	FUNCTION	CONTROL BITS OR SIGNALS	
			P9DIR.x	P9SEL.x
P9.0/TACLK/RTCCLK	0	P9.0 (I/O)	I: 0; O: 1	0
		TACLK	0	1
		RTCCLK	1	1

6.12.11 Port P9 (P9.1 to P9.3) Input/Output With Schmitt Trigger (MSP430F67xxIPZ Only)

图 6-12 shows the port diagram. 表 6-73 summarizes the selection of the pin functions.

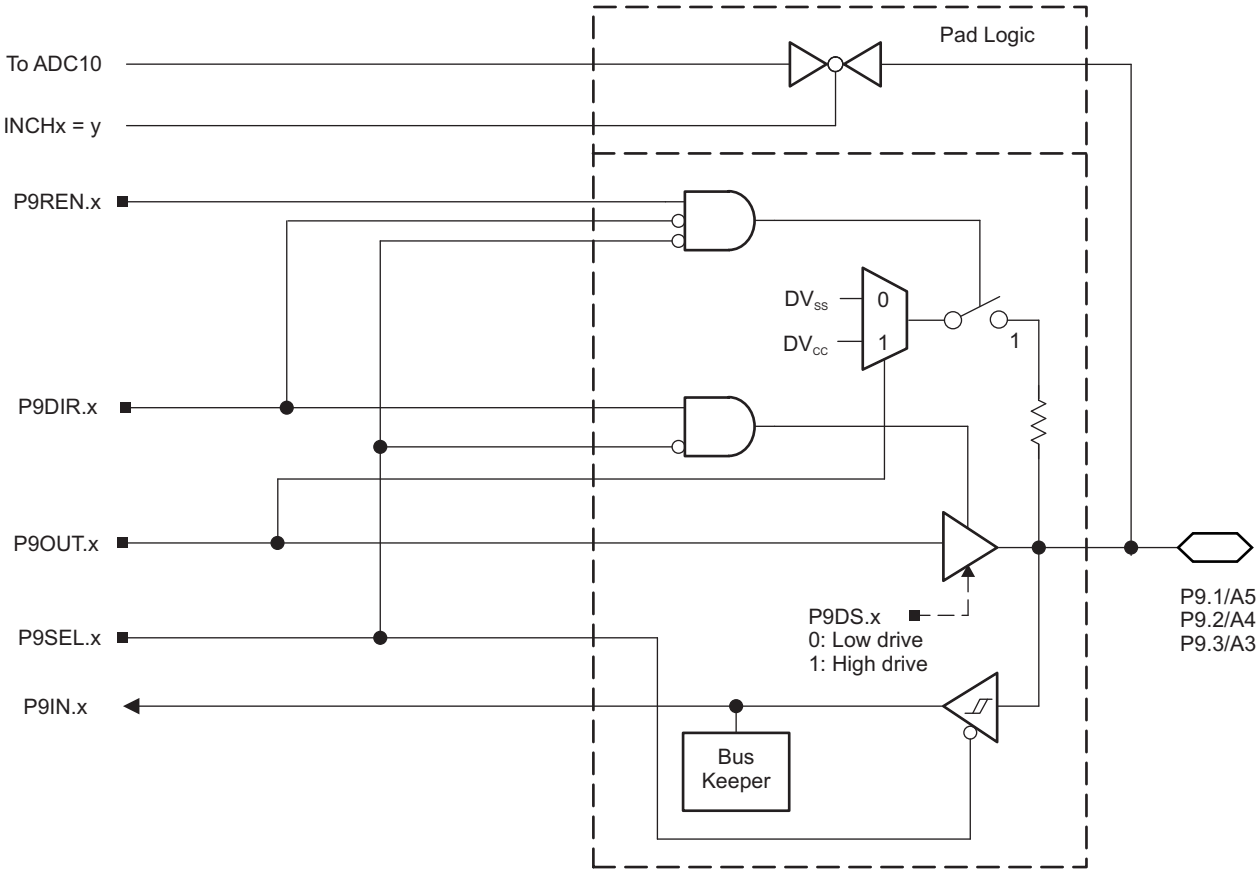


图 6-12. Port P9 (P9.1 to P9.3) Diagram (MSP430F67xxIPZ Only)

表 6-73. Port P9 (P9.1 to P9.3) Pin Functions (MSP430F67xxIPZ Only)

PIN NAME (P9.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)	
			P9DIR.x	P9SEL.x
P9.1/A5	1	P9.1 (I/O)	I: 0; O: 1	0
		A5(2)	X	1
P9.2/A4	2	P9.2 (I/O)	I: 0; O: 1	0
		A4(2)	X	1
P9.3/A3	3	P9.3 (I/O)	I: 0; O: 1	0
		A3(2)	X	1

(1) X = Don't care
(2) Setting P9SEL.x bit disables the output driver and the input Schmitt trigger.

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6.12.12 Port P2 (P2.0 and P2.1) Input/Output With Schmitt Trigger (MSP430F67xxIPN Only)

图 6-13 shows the port diagram. 表 6-74 summarizes the selection of the pin functions.

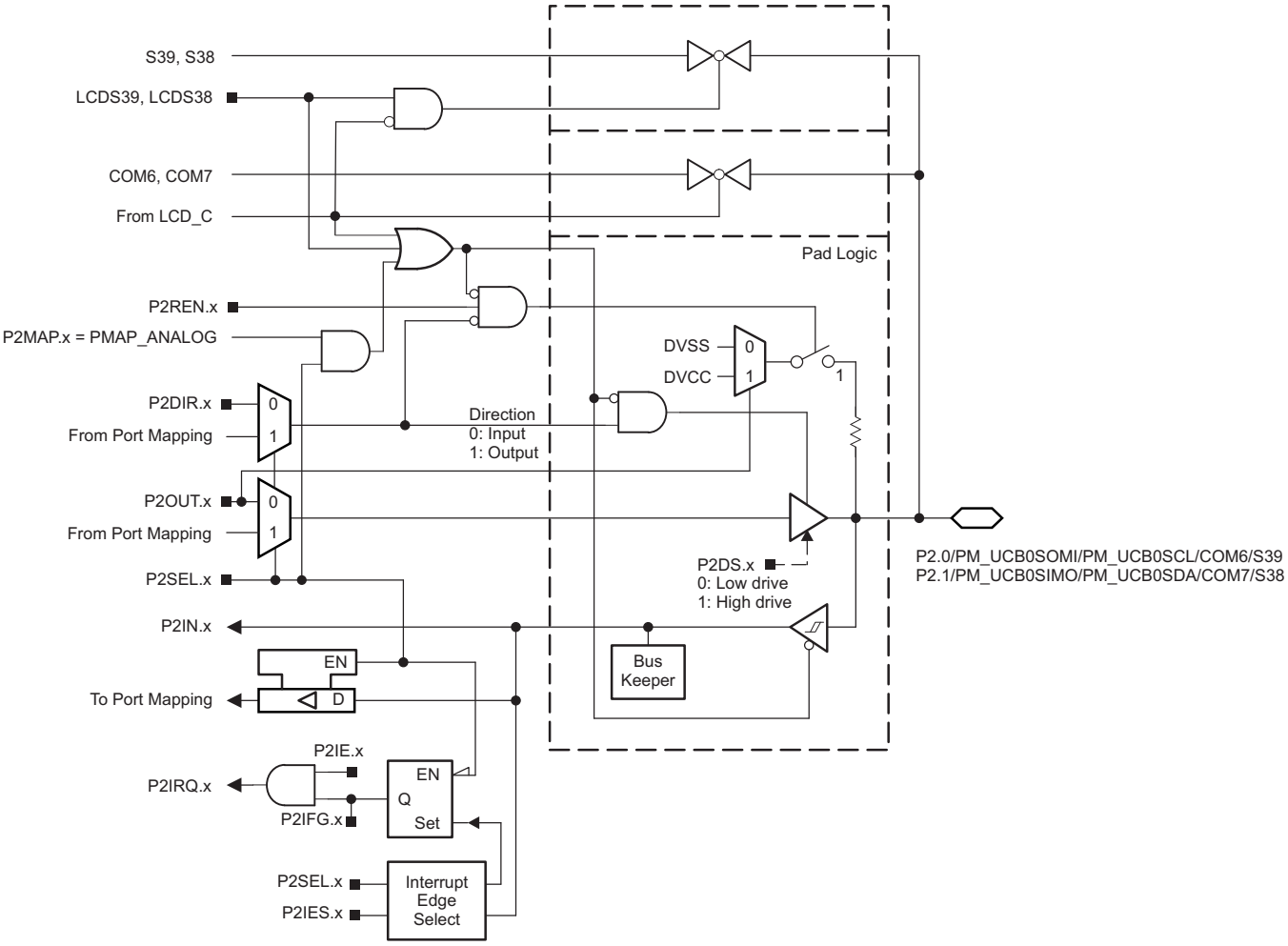


图 6-13. Port P2 (P2.0 and P2.1) Diagram (MSP430F67xxIPN Only)

表 6-74. Port P2 (P2.0 and P2.1) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)				
			P2DIR.x	P2SEL.x	P2MAPx	LCDS39, LCDS38	COM6, COM7 Enable Signal
P2.0/PM_UCB0SOMI/ PM_UCB0SCL/COM6/ S39	0	P2.0 (I/O)	I: 0; O: 1	0	X	0	0
		UCB0SOMI/UCB0SCL	X	1	default	0	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0	0
		COM6	X	X	X	X	1
		S39	X	X	X	1	0
P2.1/PM_UCB0SIMO/ PM_UCB0SDA/COM7/ S38	1	P2.1 (I/O)	I: 0; O: 1	0	X	0	0
		UCB0SIMO/UCB0SDA	X	1	default	0	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0	0
		COM7	X	X	X	X	1
		S38	X	X	X	1	0

(1) X = Don't care

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6.12.13 Port P2 (P2.2 to P2.7) Input/Output With Schmitt Trigger (MSP430F67xxIPN Only)

图 6-14 shows the port diagram. 表 6-75 summarizes the selection of the pin functions.

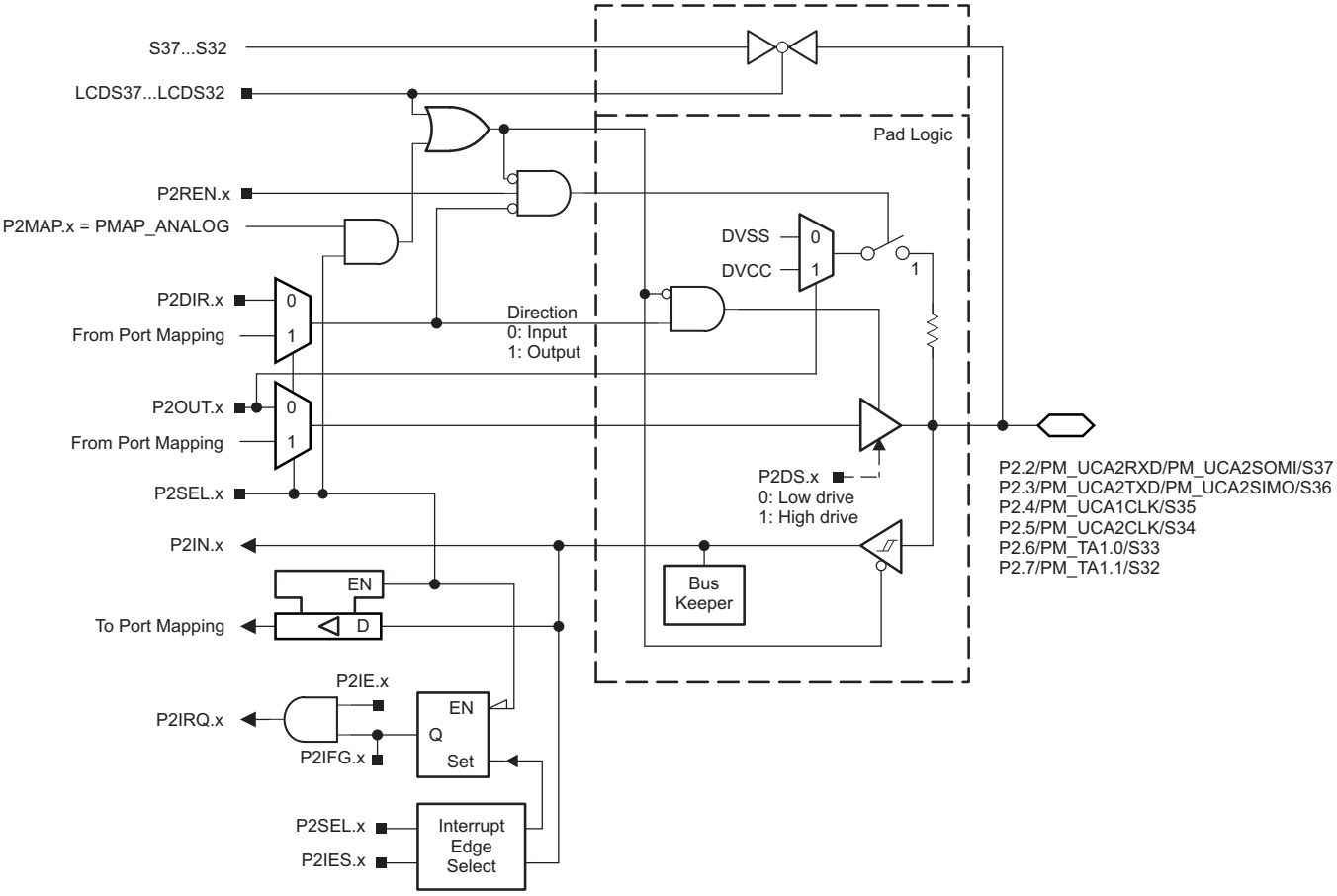


图 6-14. Port P2 (P2.2 to P2.7) Diagram (MSP430F67xxIPN Only)

表 6-75. Port P2 (P2.2 to P2.7) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)			
			P2DIR.x	P2SEL.x	P2MAPx	LCDS37... LCDS32
P2.2/PM_UCA2RXD/ PM_UCA2SOMI/S37	2	P2.2 (I/O)	I: 0; O: 1	0	X	0
		UCA2RXD/UCA2SOMI	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S37	X	X	X	1
P2.3/PM_UCA2TXD/ PM_UCA2SIMO/S36	3	P2.3 (I/O)	I: 0; O: 1	0	X	0
		UCA2TXD/UCA2SIMO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S36	X	X	X	1
P2.4/PM_UCA1CLK/S35	4	P2.4 (I/O)	I: 0; O: 1	0	X	0
		UCA1CLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S35	X	X	X	1
P2.5/PM_UCA2CLK/S34	5	P2.5 (I/O)	I: 0; O: 1	0	X	0
		UCA2CLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S34	X	X	X	1
P2.6/PM_TA1.0/S33	6	P2.6 (I/O)	I: 0; O: 1	0	X	0
		TA1.CCI0A	0	1	default	0
		TA1.TA0	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S33	X	X	X	1
P2.7/PM_TA1.1/S32	7	P2.7 (I/O)	I: 0; O: 1	0	X	0
		TA1.CCI1A	0	1	default	0
		TA1.TA1	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S32	X	X	X	1

(1) X = Don't care

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6.12.14 Port P3 (P3.0 to P3.7) Input/Output With Schmitt Trigger (MSP430F67xxIPN Only)

图 6-15 shows the port diagram. 表 6-76 summarizes the selection of the pin functions.

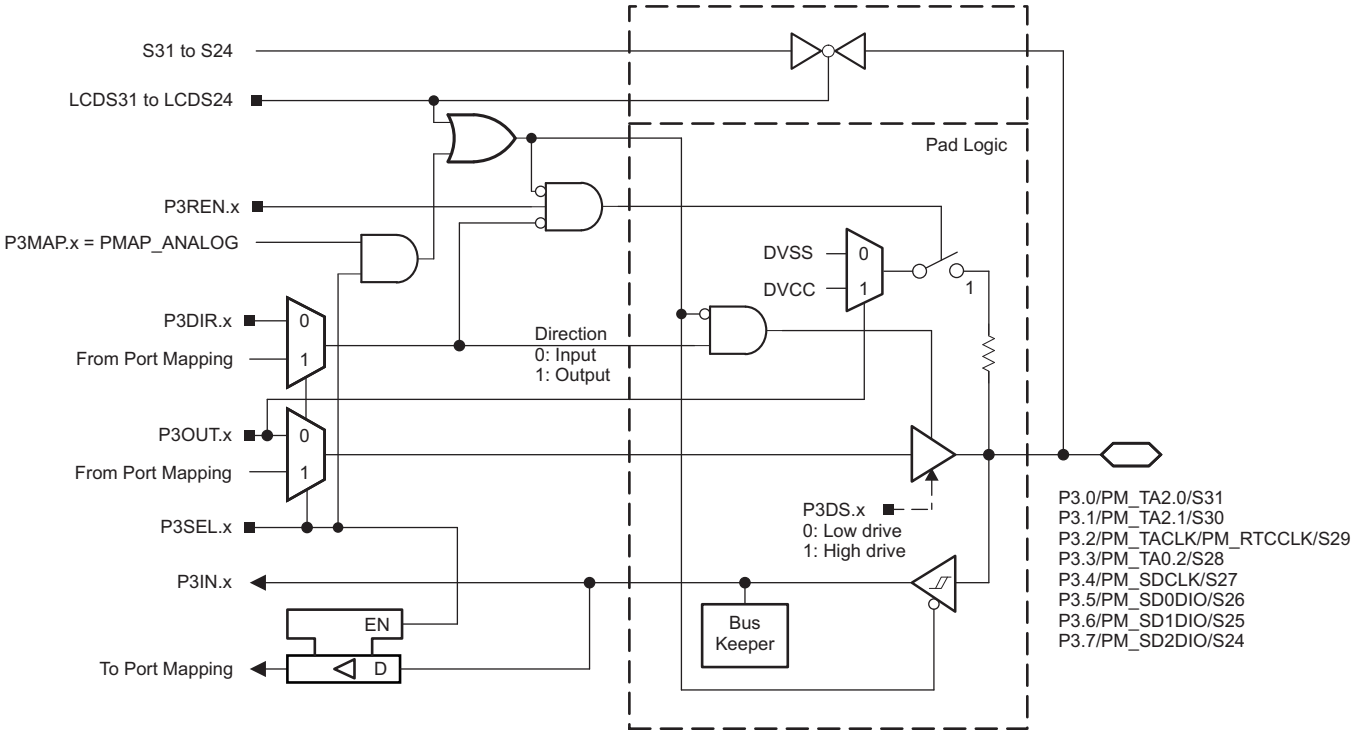


图 6-15. Port P3 (P3.0 to P3.7) Diagram (MSP430F67xxIPN Only)

表 6-76. Port P3 (P3.0 to P3.7) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P3.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)			
			P3DIR.x	P3SEL.x	P3MAPx	LCDS31... LCDS24
P3.0/PM_TA2.0/S31	0	P3.0 (I/O)	I: 0; O: 1	0	X	0
		TA2.CCI0A	0	1	default	0
		TA2.TA0	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S31	X	X	X	1
P3.1/PM_TA2.1/S30	1	P3.1 (I/O)	I: 0; O: 1	0	X	0
		TA2.CCI1A	0	1	default	0
		TA2.TA1	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S30	X	X	X	1
P3.2/PM_TACLK/ PM_RTCCLK/S29	2	P3.2 (I/O)	I: 0; O: 1	0	X	0
		TACLK	0	1	default	0
		RTCCLK	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S29	X	X	X	1
P3.3/PM_TA0.2/S28	3	P3.3 (I/O)	I: 0; O: 1	0	X	0
		TA0.CCI2A	0	1	default	0
		TA0.TA2	1	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S28	X	X	X	1
P3.4/PM_SDCLK/S27	4	P3.4 (I/O)	I: 0; O: 1	0	X	0
		SDCLK	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S27	X	X	X	1
P3.5/PM_SD0DIO/S26	5	P3.5 (I/O)	I: 0; O: 1	0	X	0
		SD0DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S26	X	X	X	1
P3.6/PM_SD1DIO/S25	6	P3.6 (I/O)	I: 0; O: 1	0	X	0
		SD1DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S25	X	X	X	1
P3.7/PM_SD2DIO/S24	7	P3.7 (I/O)	I: 0; O: 1	0	X	0
		SD2DIO	X	1	default	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S24	X	X	X	1

(1) X = Don't care

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6.12.15 Port P4 (P4.0 to P4.7), Port P5 (P5.0 to P5.7), Port P6 (P6.0 to P6.7) Input/Output With Schmitt Trigger (MSP430F67xxIPN Only)

图 6-16 shows the port diagram. 表 6-77 through 表 6-79 summarize the selection of the pin functions.

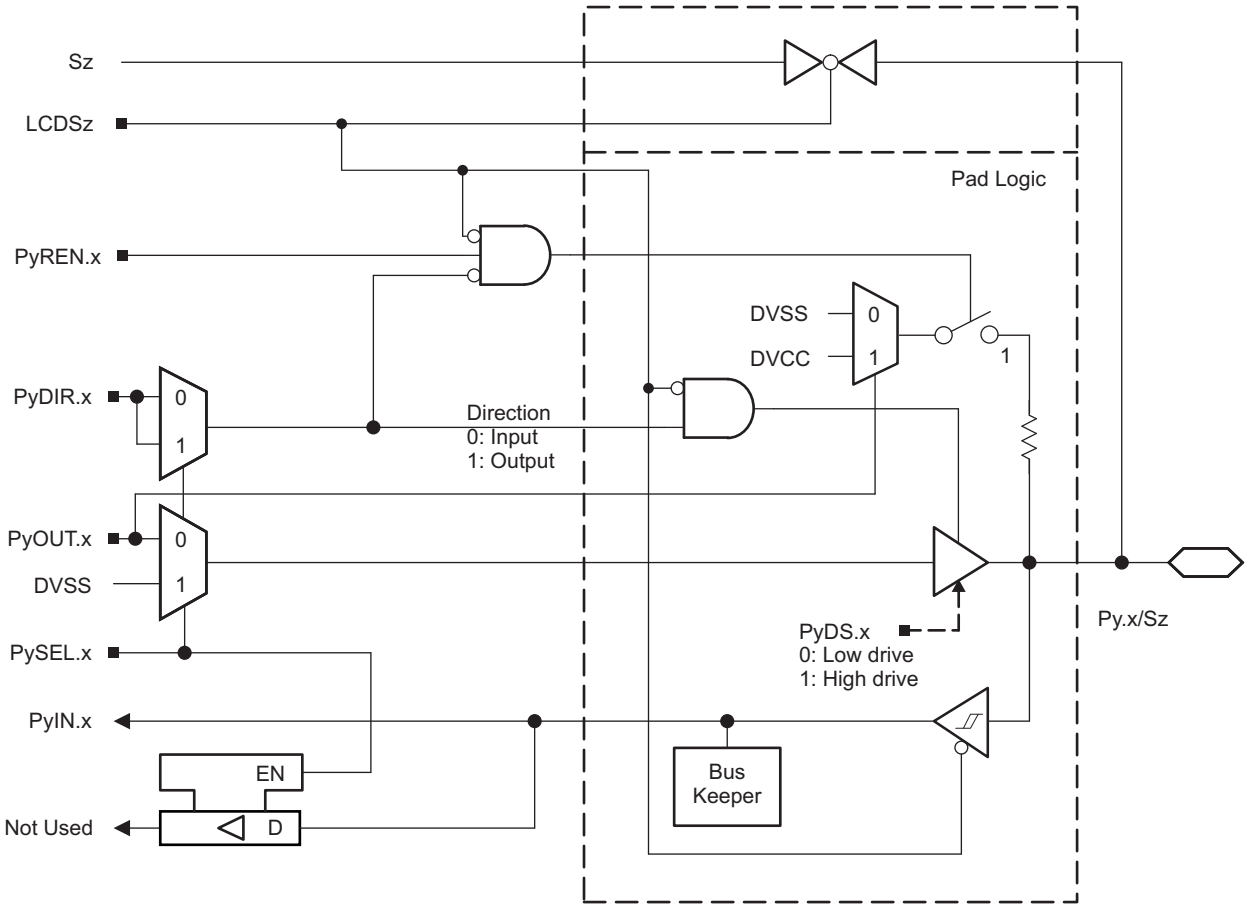


图 6-16. Port P4 (P4.0 to P4.7), Port P5 (P5.0 to P5.7), Port P6 (P6.0 to P6.7) Diagram (MSP430F67xxIPN Only)

表 6-77. Port P4 (P4.0 to P4.7) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P4.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P4DIR.x	P4SEL.x	LCDS23... LCDS16
P4.0/S23	0	P4.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S23	X	X	1
P4.1/S22	1	P4.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S22	X	X	1
P4.2/S21	2	P4.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S21	X	X	1
P4.3/S20	3	P4.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S20	X	X	1
P4.4/S19	4	P4.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S19	X	X	1
P4.5/S18	5	P4.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S18	X	X	1
P4.6/S17	6	P4.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S17	X	X	1
P4.7/S16	7	P4.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S16	X	X	1

(1) X = Don't care

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表 6-78. Port P5 (P5.0 to P5.7) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P5.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P5DIR.x	P5SEL.x	LCDS15... LCDS8
P5.0/S15	0	P5.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S15	X	X	1
P5.1/S14	1	P5.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S14	X	X	1
P5.2/S13	2	P5.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S13	X	X	1
P5.3/S12	3	P5.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S12	X	X	1
P5.4/S11	4	P5.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S11	X	X	1
P5.5/S10	5	P5.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S10	X	X	1
P5.6/S9	6	P5.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S9	X	X	1
P5.7/S8	7	P5.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S8	X	X	1

(1) X = Don't care

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表 6-79. Port P6 (P6.0 to P6.7) Pin Functions (MSP430F67xxIPN Only)

PIN NAME (P6.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			P6DIR.x	P6SEL.x	LCDS7... LCDS0
P6.0/S7	0	P6.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S7	X	X	1
P6.1/S6	1	P6.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S6	X	X	1
P6.2/S5	2	P6.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S5	X	X	1
P6.3/S4	3	P6.3 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S4	X	X	1
P6.4/S3	4	P6.4 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S3	X	X	1
P6.5/S2	5	P6.5 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S2	X	X	1
P6.6/S1	6	P6.6 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S1	X	X	1
P6.7/S0	7	P6.7 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S0	X	X	1

(1) X = Don't care

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6.12.16 Port PJ (PJ.0) JTAG Pin TDO, Input/Output With Schmitt Trigger or Output

图 6-17 shows the port diagram. 表 6-80 summarizes the selection of the pin functions.

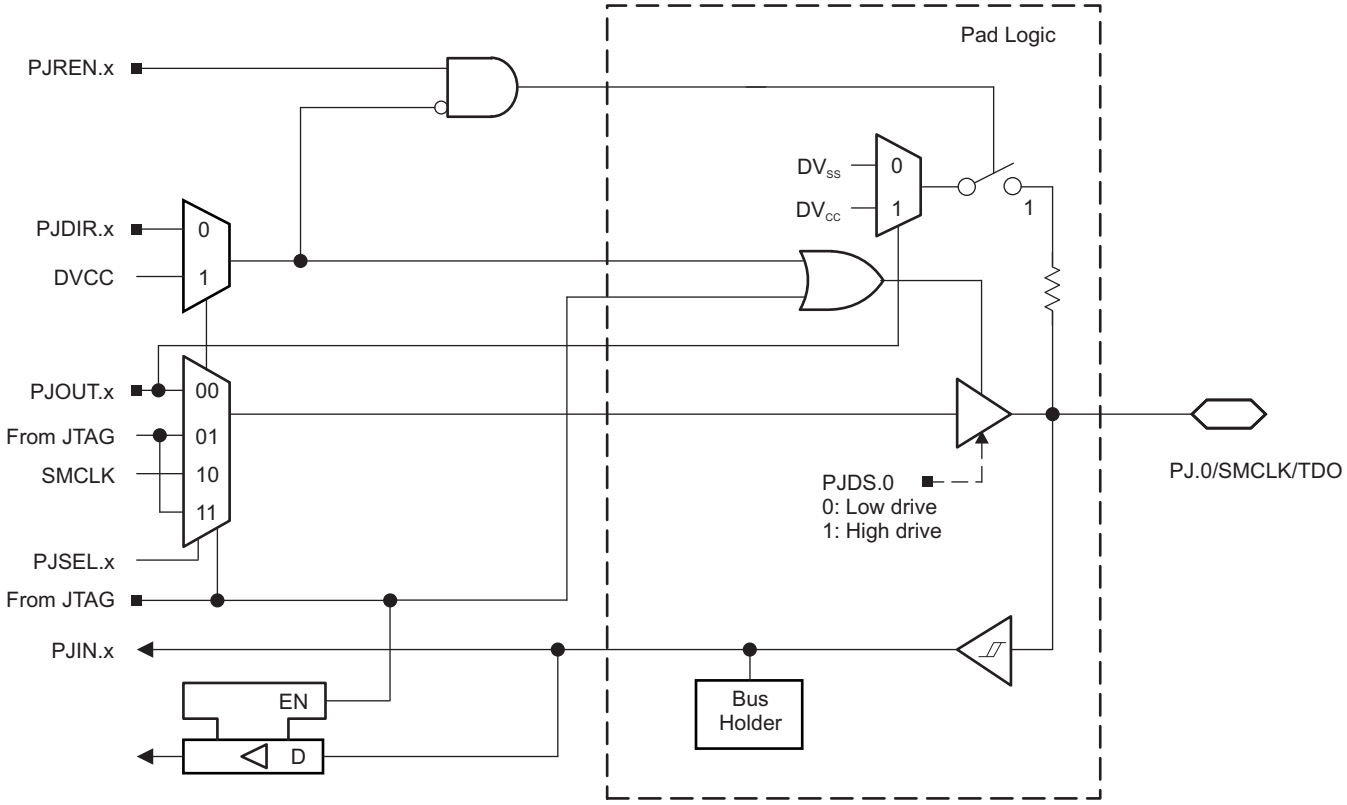


图 6-17. Port PJ (PJ.0) Diagram

6.12.17 Port PJ (PJ.1 to PJ.3) JTAG Pins TMS, TCK, TDI/TCLK, Input/Output With Schmitt Trigger or Output

图 6-18 shows the port diagram. 表 6-80 summarizes the selection of the pin functions.

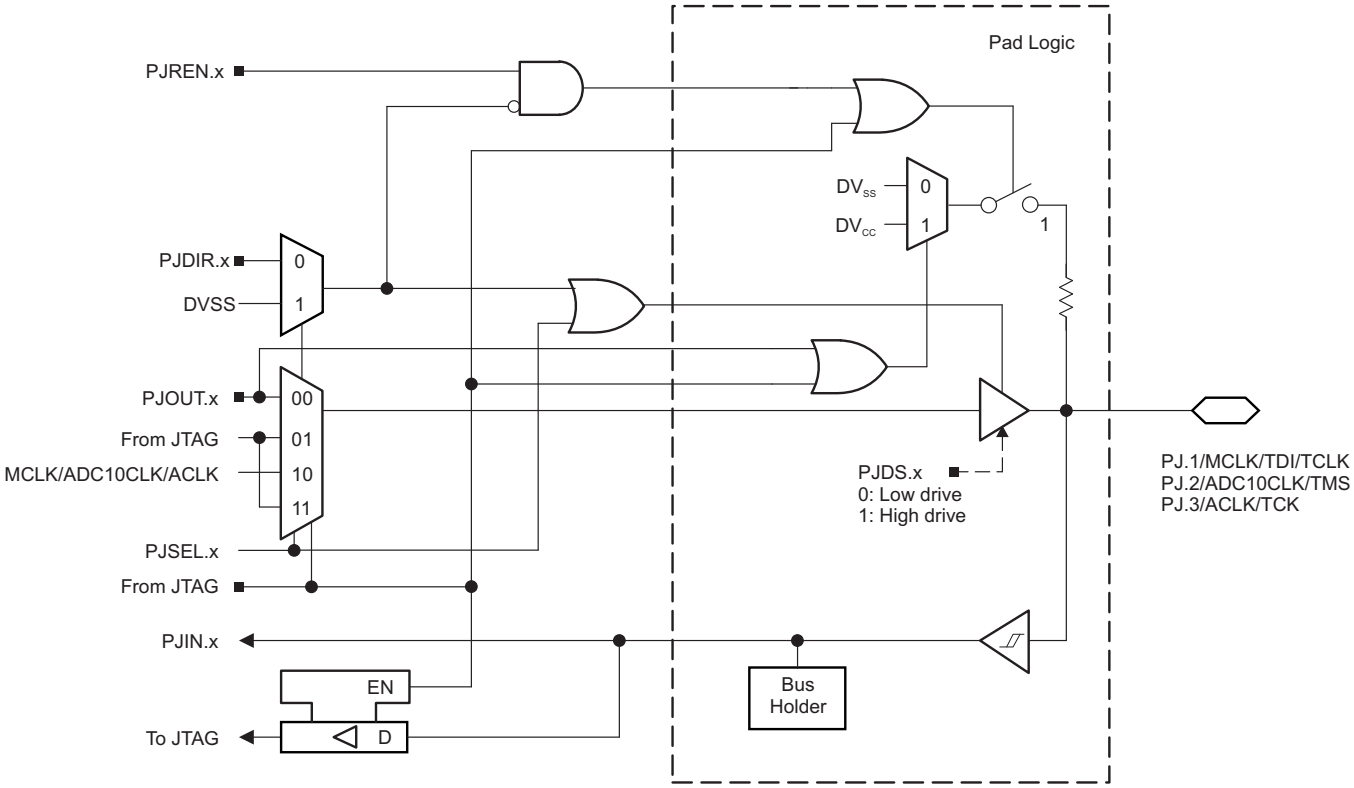


图 6-18. Port PJ (PJ.1 to PJ.3) Diagram

表 6-80. Port PJ (PJ.0 to PJ.3) Pin Functions

PIN NAME (PJ.x)	x	FUNCTION	CONTROL BITS OR SIGNALS(1)		
			PJDIR.x	PJSEL.x	JTAG Mode Signal
PJ.0/SMCLK/TDO	0	PJ.0 (I/O)(2)	I: 0; O: 1	0	0
		SMCLK	1	1	0
		TDO(3)	X	X	1
PJ.1/MCLK/TDI/TCLK	1	PJ.1 (I/O)(2)	I: 0; O: 1	0	0
		MCLK	1	1	0
		TDI/TCLK (3)(4)	X	X	1
PJ.2/ADC10CLK/TMS	2	PJ.2 (I/O)(2)	I: 0; O: 1	0	0
		ADC10CLK	1	1	0
		TMS (3)(4)	X	X	1
PJ.3/ACLK/TCK	3	PJ.3 (I/O)(2)	I: 0; O: 1	0	0
		ACLK	1	1	0
		TCK (3)(4)	X	X	1

(1) X = Don't care
(2) Default condition
(3) The pin direction is controlled by the JTAG module.
(4) In JTAG mode, pullups are activated automatically on TMS, TCK, and TDI/TCLK. PJREN.x are don't care.

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6.13 Device Descriptors (TLV)

表 6-81 and 表 6-82 list the contents of the device descriptor tag-length-value (TLV) structure for each device type.

表 6-81. MSP430F673x Device Descriptors

DESCRIPTION		ADDRESS	SIZE (bytes)	VALUE					
				F6736PZ F6736PN	F6735PZ F6735PN	F6734PZ F6734PN	F6733PZ F6733PN	F6731PZ F6731PN	F6730PZ F6730PN
Info Block	Info length	01A00h	1	06h	06h	06h	06h	06h	06h
	CRC length	01A01h	1	06h	06h	06h	06h	06h	06h
	CRC value	01A02h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Device ID	01A04h	1	6Ch	6Bh	6Ah	65h	63h	62h
	Device ID	01A05h	1	81h	81h	81h	80h	80h	80h
	Hardware revision	01A06h	1	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Firmware revision	01A07h	1	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
Die Record	Die record tag	01A08h	1	08h	08h	08h	08h	08h	08h
	Die record length	01A09h	1	0Ah	0Ah	0Ah	0Ah	0Ah	0Ah
	Lot/wafer ID	01A0Ah	4	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Die X position	01A0Eh	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Die Y position	01A10h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Test results	01A12h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
ADC10 Calibration	ADC10 calibration tag	01A14h	1	13h	13h	13h	13h	13h	13h
	ADC10 calibration length	01A15h	1	10h	10h	10h	10h	10h	10h
	ADC gain factor	01A16h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC offset	01A18h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 1.5-V reference Temperature sensor 30°C	01A1Ah	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 1.5-V reference Temperature sensor 85°C	01A1Ch	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.0-V reference Temperature sensor 30°C	01A1Eh	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.0-V reference Temperature sensor 85°C	01A20h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.5-V reference Temperature sensor 30°C	01A22h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.5-V reference Temperature sensor 85°C	01A24h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit

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表 6-82. MSP430F672x Device Descriptors

DESCRIPTION		ADDRESS	SIZE (bytes)	VALUE					
				F6726PZ F6726PN	F6725PZ F6725PN	F6724PZ F6724PN	F6723PZ F6723PN	F6721PZ F6721PN	F6720PZ F6720PN
Info Block	Info length	01A00h	1	06h	06h	06h	06h	06h	06h
	CRC length	01A01h	1	06h	06h	06h	06h	06h	06h
	CRC value	01A02h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Device ID	01A04h	1	6Fh	6Eh	6Dh	61h	59h	58h
	Device ID	01A05h	1	81h	81h	81h	80h	80h	80h
	Hardware revision	01A06h	1	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Firmware revision	01A07h	1	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
Die Record	Die record tag	01A08h	1	08h	08h	08h	08h	08h	08h
	Die record length	01A09h	1	0Ah	0Ah	0Ah	0Ah	0Ah	0Ah
	Lot/wafer ID	01A0Ah	4	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Die X position	01A0Eh	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Die Y position	01A10h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	Test results	01A12h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
ADC10 Calibration	ADC10 calibration tag	01A14h	1	13h	13h	13h	13h	13h	13h
	ADC10 calibration length	01A15h	1	10h	10h	10h	10h	10h	10h
	ADC gain factor	01A16h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC offset	01A18h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 1.5-V reference Temperature sensor 30°C	01A1Ah	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 1.5-V reference Temperature sensor 85°C	01A1Ch	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.0-V reference Temperature sensor 30°C	01A1Eh	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.0-V reference Temperature sensor 85°C	01A20h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.5-V reference Temperature sensor 30°C	01A22h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit
	ADC 2.5-V reference Temperature sensor 85°C	01A24h	2	Per unit	Per unit	Per unit	Per unit	Per unit	Per unit

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7 器件和文档支持

7.1 入门和后续步骤

有关 MSP430™系列器件以及开发协助工具和库的更多信息，请访问入门页面。

7.2 Device Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all MSP MCU devices. Each MSP MCU commercial family member has one of two prefixes: MSP or XMS. These prefixes represent evolutionary stages of product development from engineering prototypes (XMS) through fully qualified production devices (MSP).

XMS – Experimental device that is not necessarily representative of the final device's electrical specifications

MSP – Fully qualified production device

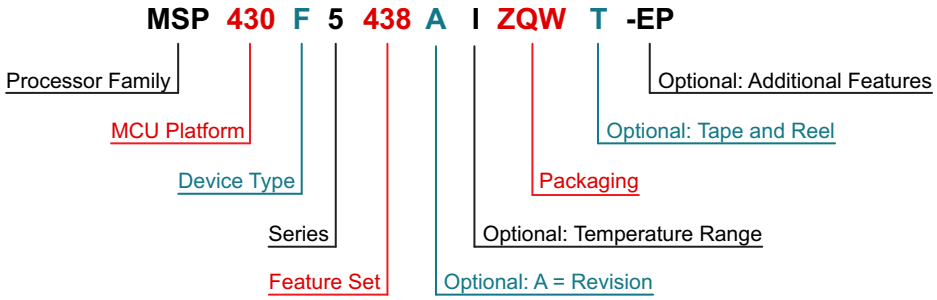
XMS devices are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

MSP devices have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (XMS) have a greater failure rate than the standard production devices. TI recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the temperature range, package type, and distribution format. 图 7-1 provides a legend for reading the complete device name.



Processor Family	CC = Embedded RF Radio MSP = Mixed-Signal Processor XMS = Experimental Silicon PMS = Prototype Device	
MCU Platform	430 = MSP430 low-power microcontroller platform	
Device Type	**Memory Type** C = ROM F = Flash FR = FRAM G = Flash or FRAM (Value Line) L = No Nonvolatile Memory	**Specialized Application** AFE = Analog Front End BQ = Contactless Power CG = ROM Medical FE = Flash Energy Meter FG = Flash Medical FW = Flash Electronic Flow Meter
Series	1 = Up to 8 MHz 2 = Up to 16 MHz 3 = Legacy 4 = Up to 16 MHz with LCD	5 = Up to 25 MHz 6 = Up to 25 MHz with LCD 0 = Low-Voltage Series
Feature Set	Various levels of integration within a series	
Optional: A = Revision	N/A	
Optional: Temperature Range	S = 0°C to 50°C C = 0°C to 70°C I = –40°C to 85°C T = –40°C to 105°C	
Packaging	http://www.ti.com/packaging	
Optional: Tape and Reel	T = Small reel R = Large reel No markings = Tube or tray	
Optional: Additional Features	-EP = Enhanced Product (–40°C to 105°C) -HT = Extreme Temperature Parts (–55°C to 150°C) -Q1 = Automotive Q100 Qualified	

图 7-1. Device Nomenclature

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7.3 工具与软件

所有 MSP 微控制器均受多种软件和硬件开发工具的支持。相关工具由 TI 以及多家第三方供应商提供。请参阅 MSP430 超低功耗 MCU – 工具与软件，了解所有工具。

表 7-1 列出了 MSP430F673x 和 MSP430F672x MCU 的 调试 功能。请参阅*《适用于 MSP430 的 Code Composer Studio 用户指南》*，以了解可用功能的 详细信息。

表 7-1. 硬件调试 特性

MSP430 架构	四线制 JTAG	两线制 JTAG	断点 (N)	范围断点	时钟控制	状态序列发生器	跟踪缓冲器	LPMX.5 调试支持
MSP430Xv2	有	有	3	有	是	否	否	否

设计套件与评估模块

MSP-TS430PZ100B - 适用于 MSP430F6x MCU 的 100 引脚目标开发板 MSP-TS430PZ100B 是一款独立的 100 引脚 ZIF 插座目标板，用于通过 JTAG 接口或 Spy-Bi-Wire（两线制 JTAG）协议在系统内对 MSP430 MCU 进行编程和调试。

适用于 MSP430F6x MCU 的 100 引脚目标开发板和 MSP-FET 编程器捆绑包 MSP-FET 是一款强大的闪存仿真工具，可在 MSP430 MCU 上快速开始应用开发。它包含 USB 调试接口，用于通过 JTAG 接口或节省引脚的 Spy-Bi-Wire（两线制 JTAG）协议在系统内对 MSP430 进行编程和调试。

EVM430-F6736 - 用于计量的 MSP430F6736 EVM EVM430-F6736 是一款基于 MSP430F6736 器件的单相电表评估板。该电表不仅可连接至主电力线，而且还具备电压和电流输入，以及可用于防篡改设置的第三连接系统。

软件

MSP430Ware™ 软件 MSP430Ware 软件集合了所有 MSP430 器件的代码示例、数据表以及其他设计资源，打包提供给用户。除了提供已有 MSP430 设计资源的完整集合外，MSP430Ware 软件还包含名为 MSP 驱动程序库的高级 API。借助该库可以轻松地对 MSP430 硬件进行编程。MSP430Ware 软件以 CCS 组件或独立软件包两种形式提供。

适用于 MSP430 MCU 的电能测量设计中心 电能测量设计中心是一款快速开发工具，它使用 TI MSP430i20xx 和 MSP430F67xx 基于闪存的微控制器 (MCU) 实现电能计量。它包含能够在各种电源监控和电能计量应用（包括智能电网和楼宇自动化）中简化开发和加快设计的图形用户界面 (GUI)、文档、 软件库和示例。使用设计中心，您无需编写任何代码即可配置、校准并查看结果。

MSP 驱动程序库 MSP 驱动程序库的抽象 API 提供易用的函数调用，无需直接操纵 MSP430 硬件的位与字节。完整的文档通过具有帮助意义的 API 指南交付，其中包括有关每个函数调用和经过验证的参数的详细信息。开发人员可使用驱动程序库函数以尽可能低的费用编写全部项目。

IEC60730 软件包 IEC60730 MSP430 软件包经过专门开发，用于协助客户达到 IEC 60730-1:2010（家用及类似用途的自动化电气控制 - 第 1 部分：一般要求）B 类产品的要求。其中涵盖家用电器、电弧检测器、电源转换器、电动工具、电动自行车及其他诸多产品。IEC60730 MSP430 软件包可以嵌入在 MSP430 MCU 中 运行的客户应用， 从而帮助客户简化其消费类器件在功能安全方面遵循 IEC 60730-1:2010 B 类规范的认证工作。

MSP430F673x、MSP430F672x 代码示例 根据不同应用需求配置各集成外设的每个 MSP 器件均具备相应的 C 代码示例。

电容式触摸软件库 可在 MSP430 MCU 启用电容触控功能的免费 C 代码库。MSP430 MCU 库版本 采用 多种电容触控实现方法，包括 RO 和 RC 方法。

MSP EnergyTrace™ 技术 适用于 MSP430 微控制器的 EnergyTrace 技术是基于电能的代码分析工具，适用于测量和显示应用的电能系统配置并帮助优化应用以实现超低功耗。

ULP（超低功耗）Advisor ULP Advisor™软件是一款辅助工具，旨在指导开发人员编写更为高效的代码，从而充分利用 MSP430 和 MSP432 微控制器 独特 功能。ULP Advisor 的目标人群是微控制器的资深开发者和开发新手，可以根据详尽的 ULP 检验表检查代码，以便最大限度地减少应用程序的能耗。在编译时，ULP Advisor 会提供通知和备注以突出显示代码中可以进一步优化的区域，进而实现更低功耗。

适用于 MSP 的定点数学库 MSP IQmath 和 Qmath 库是为 C 语言开发者提供的一套经过高度优化的高精度数学运算函数集合，能够将浮点算法无缝嵌入 MSP430 和 MSP432 器件的定点代码中。这些例程通常用于计算密集型实时 应用， 而优化的执行速度、高精度以及超低能耗通常是影响这些实时应用的关键因素。与使用浮点数学算法编写的同等代码相比，使用 IQmath 和 Qmath 库可以大幅提高执行速度并显著降低能耗。

适用于 MSP430 的浮点数学运算库 TI 在低功耗和低成本微控制器领域锐意创新，为您提供 MSPMATHLIB。此标量函数的浮点数学运算库，能够充分利用器件的智能外设，使速度最高 达到标准 MSP430 数学函数的 26 倍。Mathlib 能够轻松集成到您的设计中。该运算库免费使用并集成在 Code Composer Studio IDE 和 IAR Embedded Workbench IDE 中。

开发工具

适用于 MSP 微控制器的 Code Composer Studio™ 集成开发环境 Code Composer Studio (CCS) 集成开发环境 (IDE) 支持所有 MSP 微控制器器件。CCS 包含一整套用于开发和调试嵌入式 应用的工具。它包含了优化的 C/C++ 编译器、源代码编辑器、项目构建环境、调试器、描述器以及其他多种 功能。

命令行编程器 MSP Flasher 是一款基于 shell 的开源接口，可使用 JTAG 或 Spy-Bi-Wire (SBW) 通信通过 FET 编程器或 eZ430 对 MSP 微控制器进行编程。MSP Flasher 可用于将二进制文件（.txt 或 .hex 文件）直接下载到 MSP 微控制器，而无需使用 IDE。

MSP MCU 编程器和调试器 MSP-FET 是一款强大的仿真开发工具（通常称为调试探针），可帮助用户在 MSP 低功耗微控制器 (MCU) 中快速开发应用。创建 MCU 软件通常需要将生成的二进制程序下载到 MSP 器件中，从而进行验证和调试。

MSP-GANG 生产编程器 MSP Gang 编程器是一款 MSP430 或 MSP432 器件编程器，可同时对多达八个完全相同的 MSP430 或 MSP432 闪存或 FRAM 器件进行编程。MSP Gang 编程器可使用标准的 RS-232 或 USB 连接与主机 PC 相连并提供灵活的编程选项，允许用户完全自定义流程。

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7.4 文档支持

以下文档对 MSP430F673x 和 MSP430F672x MCU 进行了介绍。www.ti.com.cn 网站上提供了这些文档的副本。

接收文档更新通知

要接收文档更新通知（包括芯片勘误表），请转至 ti.com.cn 上您的器件对应的产品文件夹（关于产品文件夹的链接，请参见节 7.5）。请单击右上角的“通知我”按钮。点击注册后，即可收到产品信息更改每周摘要（如有）。有关更改的详细信息，请查阅已修订文档的修订历史记录。

勘误

《MSP430F6736 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6735 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6734 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6733 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6731 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6730 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6726 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6725 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6724 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6723 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6721 器件勘误表》 介绍功能规格的已知例外情况。

《MSP430F6720 器件勘误表》 介绍功能规格的已知例外情况。

用户指南

《MSP430x5xx 和 MSP430x6xx 系列用户指南》 详细介绍了该器件系列提供的模块和外设。

《MSP430 闪存器件引导加载程序 (BSL) 用户指南》 MSP430 引导加载程序（bootloader，简称 BSL，以前称为 bootstrap loader）允许用户在原型设计、最终生产和投用阶段与 MSP430 微控制器中的嵌入式存储器进行通信。可编程存储器（闪存）和数据存储器 (RAM) 能够按照要求进行变更。不要将此处的引导加载程序与某些数字信号处理器 (DSP) 中将外部存储器中的程序代码（和数据）自动加载到 DSP 内部存储器的引导装载程序混为一谈。

《通过 JTAG 接口对 MSP430 进行编程》 此文档介绍了使用 JTAG 通信端口擦除、编程和验证基于 MSP430 闪存和 FRAM 的微控制器系列的存储器模块所需的功能。此外，该文档还介绍了如何编程所有 MSP430 器件上均具备的 JTAG 访问安全保险丝。此文档介绍了使用标准四线制 JTAG 接口和两线制 JTAG 接口（也称为 Spy-Bi-Wire (SBW)）的器件访问。

《MSP430 硬件工具用户指南》 此手册介绍了 TI MSP-FET430 闪存仿真工具 (FET) 的硬件。FET 是针对 MSP430 超低功耗微控制器的程序开发工具。文中对提供的接口类型，即并行端口接口和 USB 接口进行了说明。

应用报告

《MSP430 32kHz 晶体振荡器》 对于稳定的晶体振荡器，选择合适的晶振、正确的负载电路和适当的电路板布局布线至关重要。该应用报告总结了晶体振荡器的功能，介绍了用于选择合适的晶体以实现 MSP430 超低功耗运行的参数。此外，还给出了正确电路板布局的提示和示例。此外，为了确保振荡器在大规模生产后能够稳定运行，还可能需要进行一些振荡器测试，该文档中提供了有关这些测试的详细信息。

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《**MSP430 系统级 ESD 注意事项**》　随着硅晶技术向更低电压方向发展以及设计具有成本效益的超低功耗组件的需求的出现，系统级 ESD 要求变得越来越苛刻。该应用报告介绍了三个不同的 ESD 主题，旨在帮助电路板设计人员和 OEM 理解并设计出稳健耐用的系统级设计。

《使用 **MSP430** 和段式 **LCD** 进行设计》　从智能电表，到电子货架标签 (ESL)，再到医疗设备，各式各样的应用 都需要使用段式液晶显示屏 (LCD) 为用户 提供相关信息。部分 MSP430 微控制器系列内置低功耗 LCD 驱动电路，MSP430 MCU 借此能够直接控制段式 LCD 玻璃。本应用手册可帮助您理解段式 LCD 的工作原理、MSP430 MCU 系列各种 LCD 模块的不同特性， 并提供了 LCD 硬件布线技巧、编写高效易用的 LCD 驱动软件的相关指导以及 具有不同 LCD 特性的 MSP430 器件的 产品组合概述， 旨在协助您进行器件选型。

7.5 相关链接

表 7-2 列出了快速访问链接。类别包括技术文档、支持与社区资源、工具和软件，以及申请样片或购买产品的快速链接。

表 7-2. 相关链接

器件	产品文件夹	立即订购	技术文档	工具与软件	支持和社区
MSP430F6736	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6735	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6734	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6733	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6731	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6730	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6726	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6725	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6724	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6723	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6721	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
MSP430F6720	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

7.6 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参见 TI 的 《使用条款》 。

TI E2E™ 社区

TI 的工程师交流 (E2E) 社区. 此社区的创建目的是为了促进工程师之间协作。在 e2e.ti.com 中，您可以提问、共享知识、拓展思路，在同领域工程师的帮助下解决问题。

TI 嵌入式处理器维基网页

德州仪器 (TI) 嵌入式处理器维基网页。此网站的建立是为了帮助开发人员熟悉德州仪器 (TI) 的嵌入式处理器，并且也为了促进与这些器件相关的硬件和软件的总体知识的创新和增长。

7.7 商标

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。 精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

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7.10 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

8 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F6720IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6720	Samples
MSP430F6720IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6720	Samples
MSP430F6720IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6720	Samples
MSP430F6720IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6720	Samples
MSP430F6721IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6721	Samples
MSP430F6721IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6721	Samples
MSP430F6721IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6721	Samples
MSP430F6721IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6721	Samples
MSP430F6723IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples
MSP430F6723IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples
MSP430F6723IPNR-S	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples
MSP430F6723IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples
MSP430F6723IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples
MSP430F6724IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6724	Samples
MSP430F6724IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6724	Samples
MSP430F6724IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6724	Samples
MSP430F6724IPZR	ACTIVE	LQFP	PZ	100		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6724	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F6725IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6725	Samples
MSP430F6725IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6725	Samples
MSP430F6725IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6725	Samples
MSP430F6725IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6725	Samples
MSP430F6726IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6726	Samples
MSP430F6726IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6726	Samples
MSP430F6726IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6726	Samples
MSP430F6726IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6726	Samples
MSP430F6730IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6730	Samples
MSP430F6730IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6730	Samples
MSP430F6730IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6730	Samples
MSP430F6731IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6731	Samples
MSP430F6731IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6731	Samples
MSP430F6731IPZ	LIFEBUY	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6731	
MSP430F6731IPZR	NRND	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6731	
MSP430F6733IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6733	Samples
MSP430F6733IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6733	Samples
MSP430F6733IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		F6733	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F6733IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		F6733	Samples
MSP430F6734IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6734	Samples
MSP430F6734IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6734	Samples
MSP430F6734IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6734	Samples
MSP430F6734IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6734	Samples
MSP430F6735IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6735	Samples
MSP430F6735IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6735	Samples
MSP430F6736IPN	ACTIVE	LQFP	PN	80	119	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6736	Samples
MSP430F6736IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6736	Samples
MSP430F6736IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6736	Samples
MSP430F6736IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6736	Samples
SN0806723IPNR	ACTIVE	LQFP	PN	80	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	F6723	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

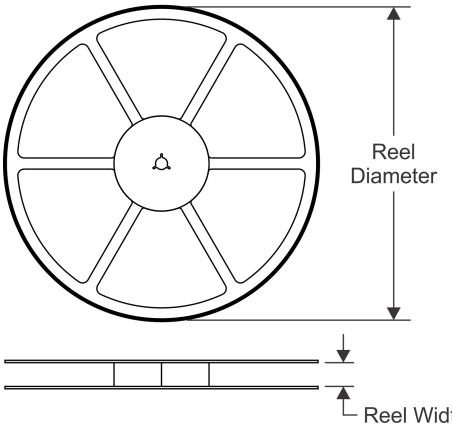
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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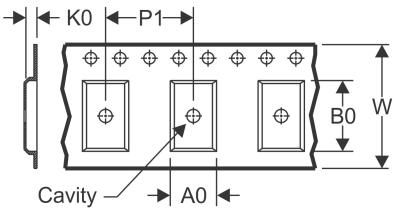
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

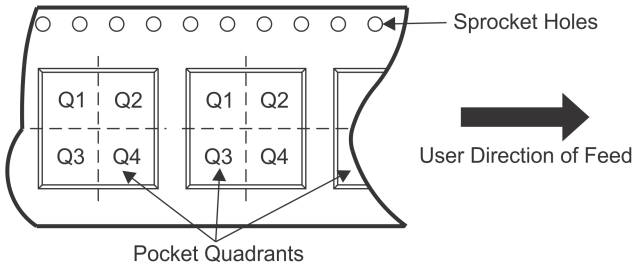


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

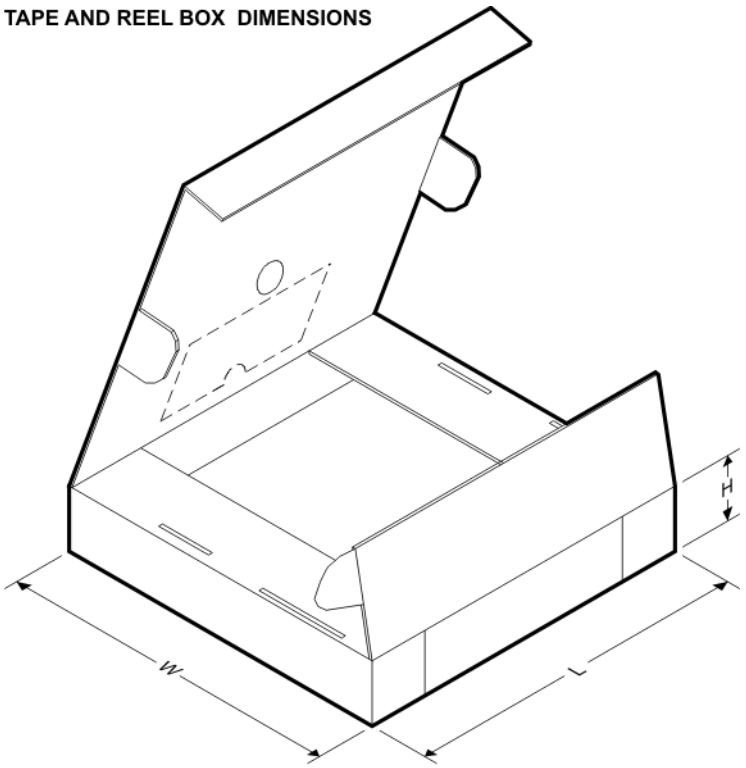


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430F6720IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6720IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6721IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6721IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6723IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6723IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6724IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6724IPZR	LQFP	PZ	100	0	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6725IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6725IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6726IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6726IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6730IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6731IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6731IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6733IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6733IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6734IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430F6734IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2
MSP430F6736IPNR	LQFP	PN	80	1000	330.0	24.4	15.0	15.0	2.1	20.0	24.0	Q2
MSP430F6736IPZR	LQFP	PZ	100	1000	330.0	24.4	17.0	17.0	2.1	20.0	24.0	Q2

TAPE AND REEL BOX DIMENSIONS



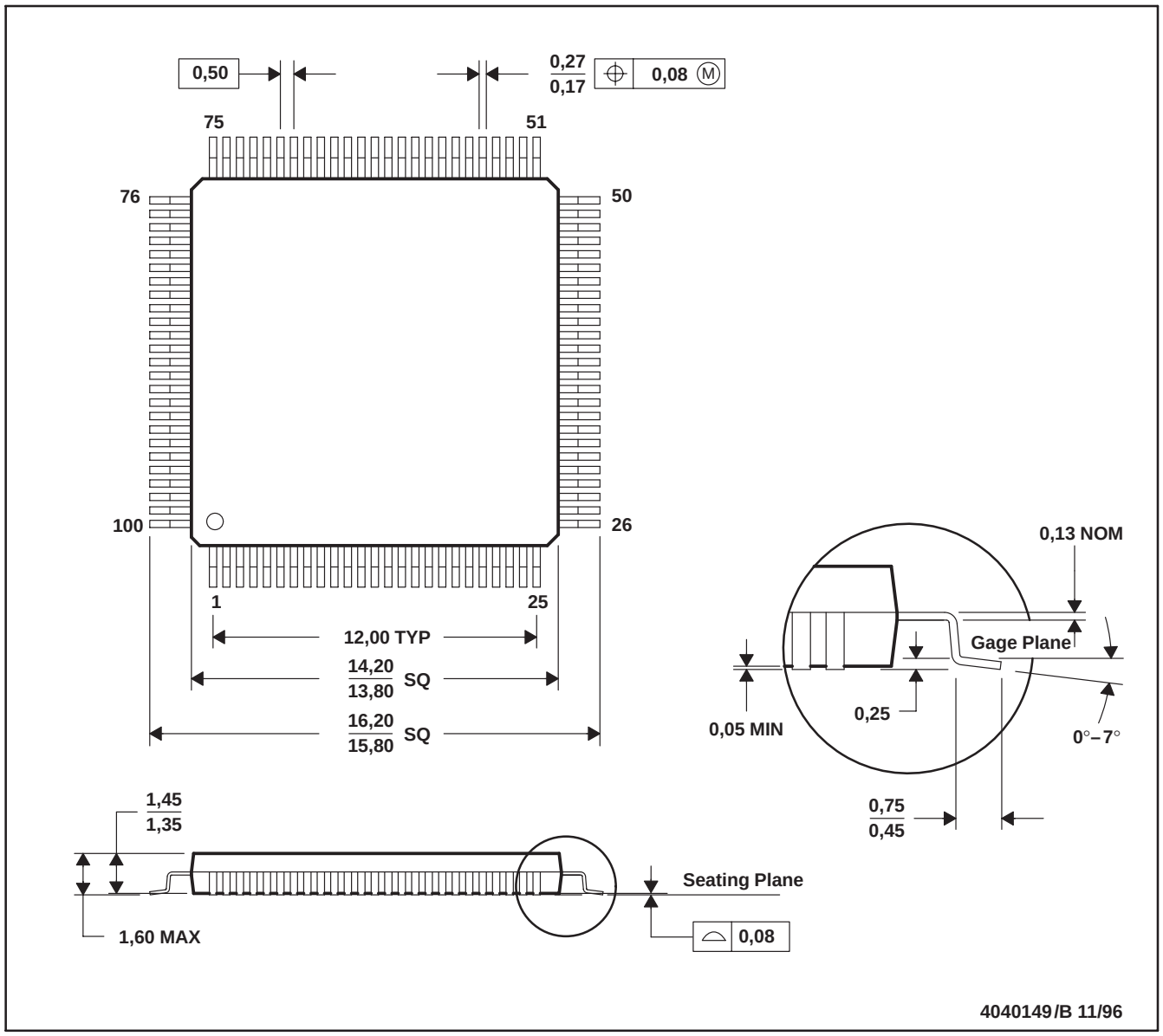
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430F6720IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6720IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6721IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6721IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6723IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6723IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6724IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6724IPZR	LQFP	PZ	100	0	350.0	350.0	43.0
MSP430F6725IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6725IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6726IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6726IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6730IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6731IPNR	LQFP	PN	80	1000	350.0	350.0	43.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430F6731IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6733IPNR	LQFP	PN	80	1000	367.0	367.0	45.0
MSP430F6733IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6734IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6734IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0
MSP430F6736IPNR	LQFP	PN	80	1000	350.0	350.0	43.0
MSP430F6736IPZR	LQFP	PZ	100	1000	350.0	350.0	43.0

MTQF013A – OCTOBER 1994 – REVISED DECEMBER 1996

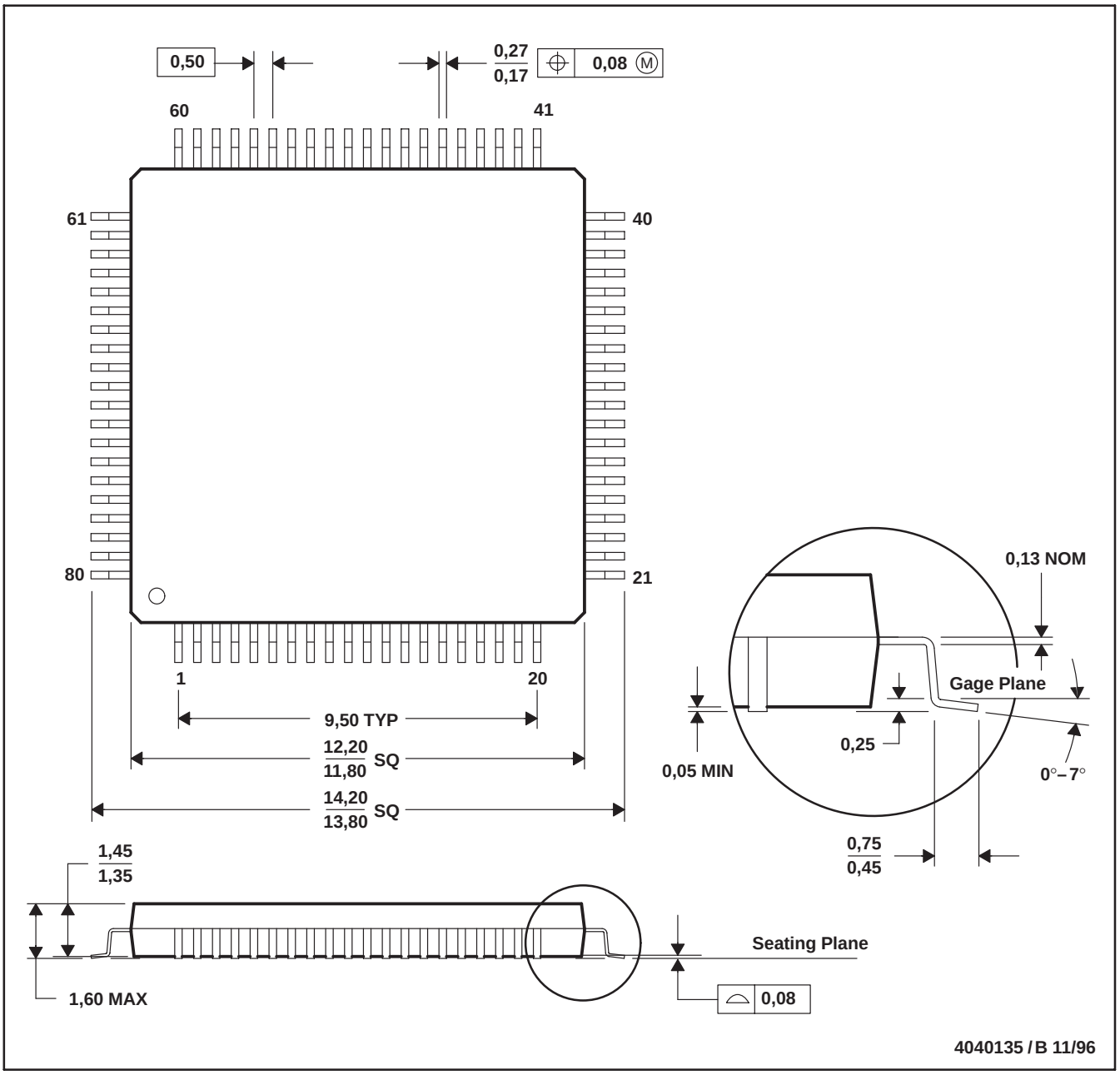
PZ (S-PQFP-G100) **PLASTIC QUAD FLATPACK**



NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-026

MTQF010A – JANUARY 1995 – REVISED DECEMBER 1996

PN (S-PQFP-G80) **PLASTIC QUAD FLATPACK**



NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-026

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